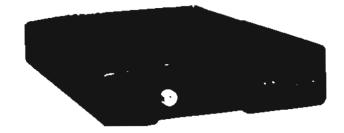


31621

GE Mobile Communications

RANGR^{*} 403-512 MHz



HICLUDES

SERVICE SECTION	LBI-317300
BOARD ASSEMBLIES	LBI-317310

TABLE OF CONTENTS

	Page
SYSTEM SPECIFICATIONS	Α3
DESCRIPTION	А6
OPERATION AND MAINTENANCE	A9

ILLUSTRATIONS

						:	rage
Figure	1	-	Typical	Module	Layout	(Top view)	А6
Figure	2	-	Typical	Module	Layout	(Bottom view)	Α7

FCC FILING NUMBER

PART #	FCC ID #	FREQUENCY SPLIT (MHz)	TX POWER OUT	OSCILLATOR STABILITY (ppm)
1	AXA9HHTR-142-82	450-470	35	2
2	AXA9HHTR-143-B2	450~470	100	2
3	AXA9HHTR-142-C2	470-488	30	2
4	AXA9HHTR-143-C2	470-488	80	2
5	AXA9HHTR-142-D2	482-500	30	2
6	AXA9HHTR-143-D2	482-500	80	2
7	AXA9HHTR-142-E2	494-512	30	2
8	AXA9HHTR-143-E2	494-512	80	2
9	AXA9HHTR-142-B	450-470	35	5
10	АХА9 ННТR-143-В	450-470	100	5

WARNING

Although the highest DC voltage in Mobile Two-Way Radio equipment is supplied by the vehicle battery, high currents may be drawn under short circuit conditions. These currents can possibly heat objects such as tools, rings, watchbands, etc., enough to cause burns. Be careful when working near energized circuits!

High-level RF energy in the transmitter Power Amplifier assembly can cause RF burns upon contact. Keep away from these circuits when the transmitter is energized!

Copyright © October 1986 General Electric Company

SYSTEM SPECIFICATIONS

OTOTOM SPECIFICATIONS						
FREQUENCY RANGE	403-423 MHz, 410-430 MHz, 420-440 MHz MHz 440-460 MHz, 450-470 MHz, 470-488 MHz MHz 482-500 MHz, and 494-512 MHz					
BATTERY DRAIN Receive Squelched Unsquelched	0.7 Amperes at 13.8 Volts 2.2 Amperes at 13.8 Volts					
Transmit 30W/35W Watts 80W/100W Watts	13 Amperes at 13.6 Volts 29.5 Amperes at 13.4 Volts					
FREQUENCY STABILITY	0.0005%/0.0002% depending on model.					
TEMPERATURE RANGE	-30°C (-22°F) to +60°C (140°F)					
DUTY CYCLE	100% Receive, 14% Transmit					
DIMENSIONS, LESS ACCESSORIES (H x W x D)	67 mm x 240 mm x 339 mm (2.6 x 9.5 x 13.3 inches)					
WEIGHT, LESS ACCESSORIES	4.3 kg (9.5 pounds)					
TRA	NSMITTER					
TRANSMIT OUTPUT POWER	30w/35w/80w/100w					
CONDUCTED SPURIOUS	-80 dB					
MODULATION	A / E 1-11-					
	<u>+</u> 4.5 kHz					
AUDIO SENSITIVITY	55 to 110 millivolts					
AUDIO SENSITIVITY AUDIO FREQUENCY CHARACTERISTICS	-					
	- 55 to 110 millivolts Within +1 dB to -4.5 dB of a 6 dB/octave pre-emphasis from 300 to 3000 Hz per EIA standards. Post-limiter					
AUDIO FREQUENCY CHARACTERISTICS	S5 to 110 millivolts Within +1 dB to -4.5 dB of a 6 dB/octave pre-emphasis from 300 to 3000 Hz per EIA standards. Post-limiter filter per FCC and EIA Less than 2% (1000 Hz)					
AUDIO FREQUENCY CHARACTERISTICS DISTORTION	Within +1 dB to -4.5 dB of a 6 dB/octave pre-emphasis from 300 to 3000 Hz per EIA standards. Post-limiter filter per FCC and EIA Less than 2% (1000 Hz) Less than 5% (300 to 3000 Hz)					
AUDIO FREQUENCY CHARACTERISTICS DISTORTION DEVIATION SYMMETRY	S5 to 110 millivolts Within +1 dB to -4.5 dB of a 6 dB/octave pre-emphasis from 300 to 3000 Hz per EIA standards. Post-limiter filter per FCC and EIA Less than 2% (1000 Hz) Less than 5% (300 to 3000 Hz) 0.3 kHz maximum 403-470 MHz 20 MHz					
AUDIO FREQUENCY CHARACTERISTICS DISTORTION DEVIATION SYMMETRY MAXIMUM FREQUENCY SEPARATION	Within +1 dB to -4.5 dB of a 6 dB/octave pre-emphasis from 300 to 3000 Hz per EIA standards. Post-limiter filter per FCC and EIA Less than 2% (1000 Hz) Less than 5% (300 to 3000 Hz) 0.3 kHz maximum 403-470 MHz 20 MHz 470-512 MHz 18 MHz					

AUDIO ATTACK TIME

20 milliseconds

CHANNEL GUARD TX TONE DISTORTION

5%

RECKIVER

AUDIO OUTPUT (to 4.0 ohm speaker)	10 Watts with less than 3% distortion
SENSITIVITY 12 dB SINAD (EIA Method)	0.35 µV
SELECTIVITY EIA Two-Signal Method (25 kHz channels)	-80 dB
SPURIOUS RESPONSE	-85 dB
INTERMODULATION 25 kHz	-80 dB
MODULATION ACCEPTANCE	<u>+</u> 7 kHz
MAXIMUM FREQUENCY SEPARATION	403-470 MHz 20 MHz 470-512 MHz 18 MHz
FREQUENCY RESPONSE	Within +2 and -8 dB of a standard 6 dB per octave de-emphasis curve from 300 to 3000 Hz (1000 Hz reference)
RF INPUT IMPEDANCE	50 ohms
HUM/NOISE RATIO UNSQUELCHED SQUELCHED	-45 dB -70 dB
RECEIVER RECOVERY TIME	200 milliseconds
RECEIVER ATTACK TIME	150 milliseconds
CHANNEL SPACING	25 kHz

^{*} These specifications are intended primarily for use of the serviceman. Refer to the appropriate Specifications Sheet for the complete specifications.

-50 dB

20 milliseconds

FM NOISE

CARRIER ATTACK TIME

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter" which is stamped on the label containing the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

Rev. A - UHF Radio 19C852450 P1-P36

A 10 pF capacitor (19A700219P26) was added from TR503-B to ground on Receiver Board to prevent receiver 1st IF (82.2 MHz) parasitic oscillation.

Rev. B - UHF Radio 19C852450 P1-P36

A 5 pF capacitor (819/5CAAD00800) and a 7 pF capacitor (819/5CAAD00977) was added in series from TR503-B to ground on Receiver Board to prevent receiver 1st IF (82.2 MHz) parasitic oscillation.

Rev. C - UHF Radio 19C852450 P1-P36

System Control Board CMC383

A 0.1 uF capacitor (B19/5CAAD01237) was added from \overline{SQ} DSBL (J701-1) to eliminate S550 scan noise in speaker with radio squelched.

DESCRIPTION

General Electric synthesized RANGR mobile radio combinations are completely solidstate utilizing microcomputer technology and integrated circuits to provide high-quality, high-reliability radios. Standard combinations may be equipped with:

- Microcomputer Controlled Frequency Synthesizer
- Up to 16 channels
- .0005% 1.0002% frequency stability
- Other structured options

The radio locks when the optional lock is installed but is not tamperproof. The cover can be removed in the locked or unlocked position.

The radio set is housed in a weather-resistant case only 6.7 centimeters high. The radio is secured to the vehicle by a bottom mounting plate. When unlocked, the radio may be pulled out of the mounting plate or the top cover removed for servicing.

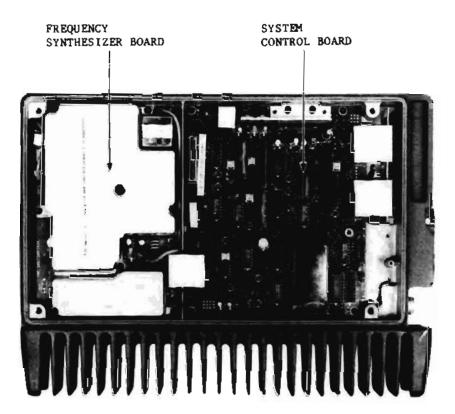
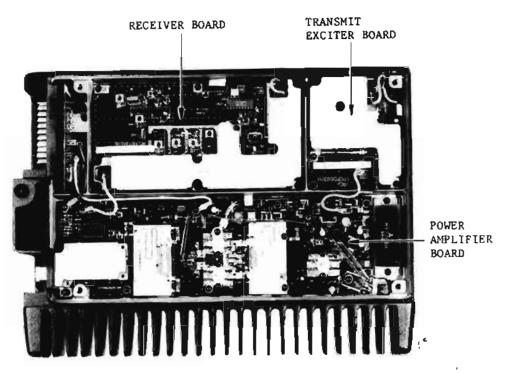
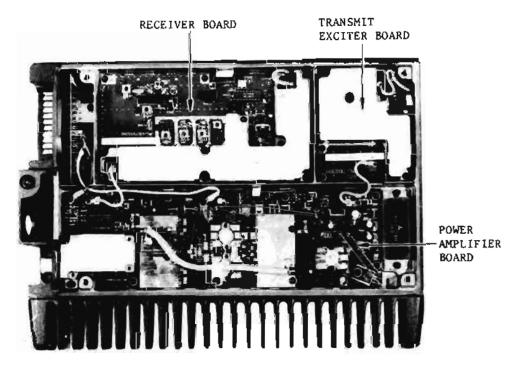


Figure 1 - Typical Module Layout (Top View)



- 80/100 W TYPE -



- 30/35 W TYPE -

Figure 2 - Typical Module Layout (Bottom View)

The basic radio consists of five printed wiring boards mounted in a cast aluminum frame. The five boards are the System Control board, the Frequency Synthesizer board, the Transmit Exciter board, the Power Amplifier board, and the Receiver board.

The radio is of double-layer construction with tuning adjustments easily accessible from the top of the radio.

The System Control board and the Frequency Synthesizer board are located on the top of the radio, while the Transmit Exciter board, the Power Amplifier board and the Receiver board are located on the bottom.

Interconnections are provided by ribbon cable between the boards. A power bus connects A+ and A- from the front connector to the PA assembly.

A centralized metering jack for the transmitter, receiver and system functions is provided for simplified alignment and troubleshooting.

SYNTHESIZER/INTERCONNECT

The synthesizer consists of a microcomputer, electrically - erasable PROM (EEPROM), a frequency synthesizer IC, transmit and receive VCO's and associated circuitry. The frequency synthesizer under control of the microcomputer generates all transmit and receive RF frequencies.

The EEPROM stores binary data for all RF frequencies, Channel Guard tones/digital codes, and the timing function of the carrier control timer(CCT). The microcomputer accesses the EEPROM and provides the correct WALSH bits to the Channel Guard circuitry to generate the correct Channel Guard tone or digital code on a per-channel basis.

PROGRAMMING

The EEPROM allows the radio to be programmed or reprogrammed as needed to adapt to changing system requirements. RF frequencies, Channel Guard tones and digital codes, and the CCT function can be reprogrammed.

The EEPROM can be reprogrammed through the radio front connector using the General Electric Universal PROM Programmer Model TQ2310. This programmer allows all information to be loaded simultaneously.

When programming, remember that all RF frequencies must be divisible by 12.5 kHz. Also insure that P706 is connected to J706-2 and 3 to enable programming.

NOTE -

Programming instructions are provided in the respective Programmer Maintenance Manuals.

TRANSMITTER

The transmitter consists of the exciter, frequency synthesizer, transmit VCO, and a power amplifier (PA) assembly. The PA assembly consists of a PA board mounted along the side of the radio next to the heat sink assembly. The PA board also contains an antenna relay and a low-pass filter.

Audio and Channel Guard circuitry for the transmitter is located in the System Control board.

RECEIVER

The receiver consists of the frequency synthesizer, RX VCO, injection amplifiers, front end, IF, and limiter detector. Audio, squelch and Channel Guard circuitry for the receiver is located on the System Control board.

MAINTENANCE

A microprocessor on the System Control board controls the frequency synthesizer, the TX on/off, the decoding of CTCSS tones, the generation of CTCSS tones, etc. The audio processor circuitry for the transmitter and the receiver are located on the System Control board. Squelch circuitry, a jack for central metering and the digital voice guard circuit are also located on the System Control board.

CONTROL UNITS

S-series control units are available and may be used directly with RANGR radio combinations.

Refer to the applicable Maintenance Manual for detail description of the Control Unit used with the RANGR radio combinations.

OPERATION

Complete operating instructions for the Two-Way Radio are provided in the Operator's Manual for the control unit used.

The use of microcomputer technology allows self-diagnostic maintenance routines to be incorporated in the microcomputer software. These routines are easy to run and provide a quick analysis of microcomputer and frequency synthesizer operation.

The service section of this manual contains the diagnostic routines and other maintenance information to service this radio. The service section includes:

- System interconnections
- Mechanical layout
- Disassembly procedures
- Replacement of IC's, chip capacitors and resistors
- Microcomputer self-diagnostics
- Alignment procedures for the transmitter and receiver
- Troubleshooting Procedure and waveforms



HAIRTERANCE HARRAL

403-512 MHz SYNTHESIZED RANGR

TWO WAY FM RADIO

SERVICE SECTION

TABLE OF CONTENTS

TABLE OF COULTRIS	
	Page
DESCRIPTION	B2
INITIAL ADJUSTMENT	В2
Transmitter Adjustment	B2
Receiver Adjustment	В2
MAINTENANCE	В2
Preventive Maintenance	82
Disassembly Procedure	в3
Removing IC's	87
Replacing Chip Components	B7
TEST AND TROUBLESHOOTING PROCEDURES	88
Microcomputer	В9
Microphonics	В9
Microcomputer Diagnostics	В9
Test Frequencies	B12
PA Troubleshooting Procedure	B13
Typical Performance Information	B15
TRANSMITTER ALIGNMENT	B16
RECEIVER ALIGNMENT	B23
MECHANICAL LAYOUT	B32-B40

GE Mobile Communications

DESCRIPTION

This section contains the information required to service the radio. included are disassembly procedures, procedures for replacing transistors, Integrated Circuits (IC's) and chip components. This section also includes alignment procedures and troubleshooting information (see Table of Contents).

INITIAL ADJUSTMENT

After the radio has been installed (as described in the Installation Manual), the following adjustments should be made by a certified electronics technician.

TRANSMITTER ADJUSTMENT

The adjustment for the transmitter includes measuring the forward and reflected power, and setting the transmitter to rated power output. Then, measure the frequency and modulation and record these measurements for future reference. For the complete transmitter adjustment, refer to the Alignment Procedure (see Table of Contents).

RECEIVER ADJUSTMENT

No adjustment for the input circuit is required. For complete receiver adjustment, refer to the Receiver Alignment Procedure (see Table of Contents).

HATETERANCE

PREVENTIVE MAINTENANCE

To facilitate troubleshooting of problems on the printed circuit board assemblies, the following service accessories are available:

DESCRIPTION	PART NUMBER
EXTENSION CABLE 22	B19/6JJFD00057
CONDUCTOR	
EXTENSION CABLE 10	B19/6JJFD00058
CONDUCTOR	
EXTENSION CABLE 10	B19/6JJFD00059
CONDUCTOR	n10// 110n00000
EXTENSION CABLE 4	B19/6JJFD00060
CONDUCTOR	B10/6118B00061
EXTENSION CABLE 6	B19/6JJFD00061
CONDUCTOR	710// *********
COAXIAL CABLE	B19/6JJFD00062
COAXIAL CABLE	B19/6JJFD00063
TUNING TOOL	B19/MPTC00448

To ensure high operating efficiency and to prevent mechanical and electrical failures from interrupting system operations, routine checks should be made of all mechanical and electrical parts at regular intervals. This preventive maintenance should include the checks as listed in Table 1-Maintenance Checks.

	INT	INTERVAL		
MAINTENANCE CHECKS	6 Months	As Required		
CONNECTIONS - Ground connections and connections to the voltage source should be periodically checked for tightness. Loose or poor connections to the power source will cause excessive voltage drops and faulty operation. When ground connections are not made directly to the battery, the connection from the battery to vehicle chassis must be checked for low impedance. A high impedance may cause excessive voltage drops and alternator noise problems.	х			
ELECTRICAL SYSTEM - Check the voltage regulator and alternator or generator periodically to keep the electrical system within safe and economical operating limits. Overvoltage is indicated when the battery loses water rapidly. Usage of 1 or 2 ounces of water per cell per week is acceptable for batteries in continuous operation. A weak battery will often cause excessive noise or faulty operation.		x		
MECHANICAL INSPECTION - Since mobile units are subject to constant shock and vibration, check for loose plugs, nuts, screws and parts to make sure that nothing is working loose. Be sure that all screws are properly torqued.	х			
ANTENNA - The antenna, antenna base and all contacts should be kept clean and free from dirt or corrosion. If the antenna or its base should become coated or poorly grounded, loss of radiation and a weak signal will result.	х			
ALIGNMENT - The transmitter and receiver meter readings should be checked periodically, and the alignment "touched up" when necessary. Refer to applicable Alignment Procedure and troubleshooting sheet for typical voltage readings.		x		
FREQUENCY CHECK - Check transmitter frequency and deviation, as required by FCC. Normally, these checks are made when the unit is first put into operation, after the first six months and once a year thereafter.		х		

TABLE 1 - MAINTENANCE CHECKS

DISASSEMBLY PROCEDURE

To remove the printed wire boards:

To gain access to the unit for servic- 1. Each of the boards may be removed ing:

- 1. Remove the lock screw on the front of the radio using No. 30 TORX ® driver.
 - frame. 2. The cables and the screws to be

after removing the radio cover, the

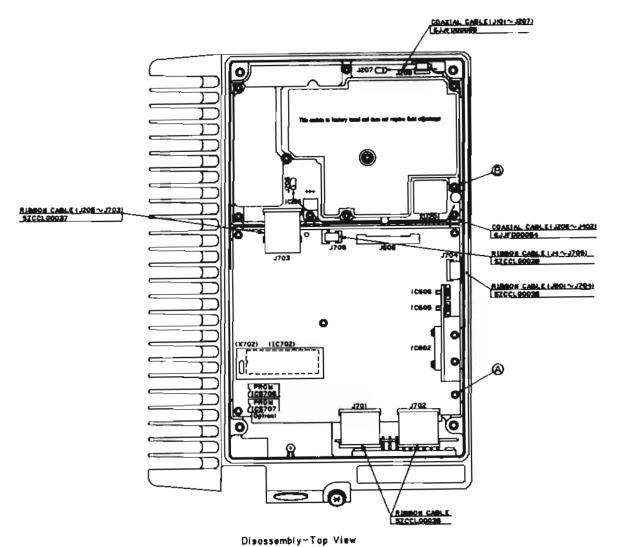
cables and the retaining screws

securing the board to the main

- 2. Pull the radio forward and remove from the mounting bracket.
- removed are listed in Table 2.

TORX ® Trademark of CAMCAR Division TEXTRON, Inc.

- B2 -



Pigure l

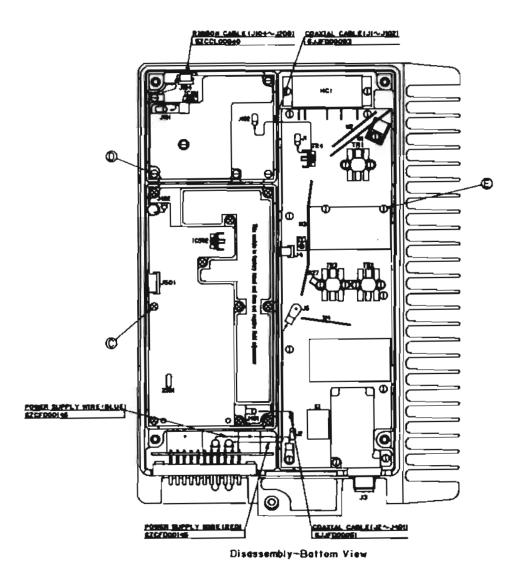


figure 2

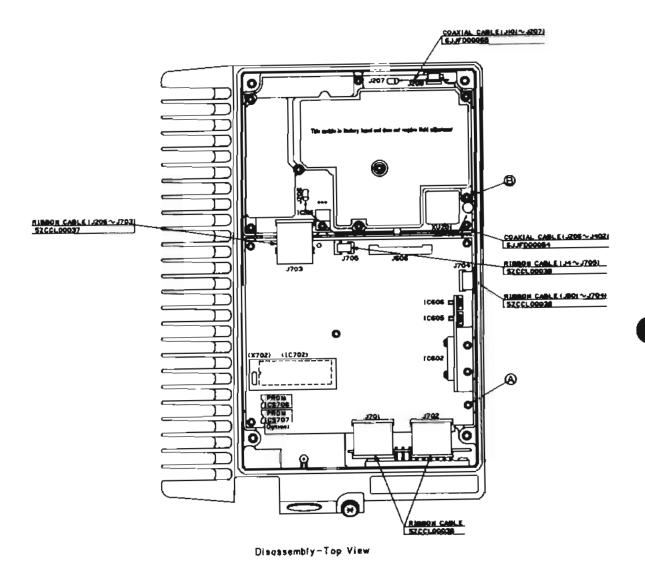


Figure 1

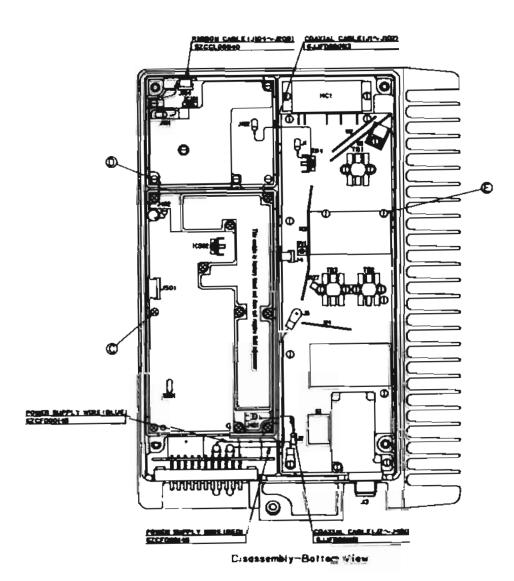


Figure 2

Board name	Cables to be removed	Screws to be removed
System control board	Five ribbon cables	Seven screws A (Figure 1)
Synthesizer board	Two coaxial cables and two ribbon cables	Ten screws B (Figure 1)
PA board	Two power supply wires (red and blue), two coaxial cables, one ribbon cable	20 screws E (Figure 2)
Tx Exciter board	Two coaxial cables, one ribbon cable	Six screws D (Figure 2)
Rx board	Two coaxial cables and one ribbon cable	Ten screws C (Figure 2)

TABLE 2 - DISASSEMBLY PROCEDURE

To replace the printed wire boards.

 Perform Preceding procedures in reverse order.

CAUTION

After securing the radio, it is important that the screws securing the covers be fully secured. This ensures that the RF shielding gaskets make good contact and that the radio performance specifications are not compromised.

PA TRANSISTOR REPLACEMENT

WARNING

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

To replace the PA RF transistors:

- Unsolder one lead at a time with a 50 watt soldering iron. Use a scribe or X-acto® knife to hold the lead away from the printed circuit board until the solder cools. Removed the mounting screws.
- 2. Lift out the transistor. Remove any old solder from the printed circuit board with a vacuum desoldering tool. Special care should be taken to prevent damage to the printed circuit board runs because part of the matching network is included in the base and collector runs.
- Trim the new transistor leads (if required) to the lead length of the removed transistor.
- 4. Apply a coat of silicon grease to the transistor mounting surface. Place the transistor in the mounting hole. Align the leads as shown on the Outline Diagram. Then replace the transistor mounting screws using moderate torque (9.4kg·cm).
- 5. Solder the leads to the printed circuit pattern. Start at the inner edge of mounting hole and solder the remaining length of transistor lead to the board. Take care not to use excessive heat that causes the printed wire board runs to separate from the board. Check for shorts and

solder bridges before applying power.

CAUTION

Failure to solder the transistor leads as directed may result in the generation of RF loops that could damage the transistor or may cause low power output.

REMOVING IC's

Removing IC's (and most other soldered-in components) can be easily accomplished by using a vacuum desoldering tool. To remove an IC, heat each lead separately on the solder side and remove the old solder with the desoldering tool,

CAUTION



The CHOS Integrated Circuit devices used in this equipment can be destroyed by static discharges. Before handling one of these devices, the servicemen should discharge

himself by touching the case of a bench test instrument that has a 3-prong power cord connected to an outlet with a known good earth ground. When soldering or desoldering a CMOS device, the soldering iron should also have a 3-prong power cord connected to an outlet with a known good earth ground. A battery-operated soldering iron may be used in place of the regular soldering iron.

REPLACING CRIP COMPONENTS

Replacement of chip components should always be done with a temperature - controlled soldering iron at 700°F (371°C). However, do not touch the black metal film of the resistors or the ceramic body of capacitors with the soldering iron.

REHOVING CHIP COMPONENTS

- Using two soldering irons heat both ends of the chip at the same time until solder flows, and then remove and discard the chip.
- Remove excess solder with a vacuum solder extractor.
- Carefully remove the epoxy adhesive and excess flux to prevent damage to the printed board.

REPLACING CHIP COMPONENTS

 Using as little solder as possible, "tin" one end of the component and one of the pads on the printed wiring board.

- Place the "tinned" end of the component on the "tinned" pad on the board and simultaneously touch the component and the pad with a well "tinned" soldering iron while pressing the component down on the board.
- 3. Place the "tinned" soldering iron on the other end of the component and the pad simultaneously. Apply solder to the top of the end of the component until the solder starts to flow. Use as little solder as possible while getting a good joint.
- After the component has cooled, remove all flux from the component and printed wiring board area with alcohol.

TEST AND TROUBLESHOOTING PROCEDURES

Maintenance of the radio is facilitated by using the Self Test and Diagnostics routines and servicing techniques unique to this radio. Typical voltage readings are provided on the Schematic Diagram for reference when troubleshooting.

CAUTION

Before bench testing the radio, be sure of the output voltage characteristics of your bench power supply.

To protect the transmitter power output transistors from possible instant destruction, the following input voltages must not be exceeded:

Transmitter unkeyed: 16.5 Volts
Transmitter keyed (50 ohms resistive load): 16.3 Volts
Transmitter keyed (no load or non-resistive load):14 Volts

These voltages are specified at the normal vehicle battery terminals of the radio and take the voltage drop of standard cables into account. The voltage limits shown for a non-optimum load is for "worst case" conditions. For antenna mismatches likely to be encountered in practice, the actual limit will approach the 16.3 Volt figure.

Routine transmitter tests should be performed at EIA Standard Test Voltages (13.6 VDC for loads of 6 to 16 amperes; 13.4 VDC for loads of 16 to 36 amperes). Input voltages must not exceed the limits shown, even for transient peaks of short duration.

Many commonly used bench power supplies cannot meet these requirements for load regulation and transient voltage suppression. Bench supplies which employ "brute force" regulation and filtering (such as Lapp Nodel 73) may be usable when operated in parallel with a 12 Voltautomotive storage battery.

MICROCOMPUTER

When servicing the microcomputer/ synthesizer circuitry it is sometimes desirable to force the microcomputer into specific operating modes. Following are tips that allow you to initiate these modes.

- Ground the lock-detect line at IC701-8 to force the microcomputer to continually try to reload the synthesizer. This mode will enable you to check the serial data, clock, channel change pulse and enable signals to the synthesizer.
- To stop the microcomputer from running, disable the watchdog timer by shorting the collector and emitter of TR701, and ground the single-step line at IC702-5.

MICROPHONICS

Synthesized radios tend to be sensitive to shock and vibration, creating microphonics. The construction of the RANGR radio with its die-cast aluminum frame, cast shield, and multiple board mounting screws, provides a high degree of immunity. When removing printed circuit boards or shields, note the location of all mounting hardware.

When servicing the radio be sure that no solder build-up has occurred on the chassis or shield.

To assure a high degree of resistance to microphonics be sure to replace exactly, all hardware removed. Be sure that all mounting screws are properly torqued and shields are in place. Refer to the Mechanical Layout Diagram.

NOT

Loose or rubbing parts, especially in the VCO area are particularly sensitive and can cause microphonics. Again, be certain all hardware is properly installed and torqued.

MICROCOMPUTER DIAGNOSTICS

The microcomputer, in addition to operational programming, contains soft-ware for self-diagnostic routines to aid in troubleshooting the radio. Since the radio can not function with a defective microcomputer, the self diagnostic routines include internal tests as well as input/output tests to verify proper operation.

The internal tests include a ROM test which verifies that the proper program is stored in the microcomputer and a RAM test which checks for proper data transfer to and from all memory locations.

The input/output tests include a test which grounds one pin at a time on Port 1 and the data bus, and a test which mirrors the inputs PTT, CG DISABLE, ADVANCE CHANGE, and FB4 - FB1 on to the data bus.

These tests assure proper operation of the ports and data bus, in addition to checking the input/output instructions of the microcomputer. When troubleshooting the radio, if problems are suspected on the system board, the diagnostic routines should be performed first before going on to the test procedures and alignment instructions.

TEST EQUIPMENT REQUIRED

- 13.8 VDC supply, 500 mA (unless being tested in radio)
- DC Voltmeter (Data Tech 30L or equivalent)
- Oscilloscope (Tektronix 404 or equivalent)

TEST PROCEDURE

- Connect oscilloscope to J801-18 (SPKR 1) and ground.
- Enter the #elf-diagnostic mode as follows:

CAUTION

When using the radio with the S550, S950 or S990 control head, the ADVANCE CHANGE line should be disconnected form the control head by removing connector P3. Instead of keying the microphone, ground J606-10.

Key the radio with the microphone on-hook. (Ground J801-11. Make sure that MONITOR Switch is OFF.)

- Apply A+ at J702-9 through a 10K resistor to J702-10.
- · Turn radio on.

ROM AND RAH TESTS

Once power is supplied to the board, the microcomputer will jump to the self-diagnostic test and immediately begin execution of the ROM and RAM tests. Upon completion of the ROM and RAM test (less than a second) the display, data bus, or alert tone will indicate when the tests have been successfully completed. Test status is indicated as follows:

	D3	D2	DI	00	ALERT
ROM TEST	0	0	0	0	MOME
ROM TEST PASSED RAM TEST FAILED	0	0	0	1	HOME
ROM TEST PASSED RAM TEST PASSED	0	0	1	0	l kHz

If the data bus is inaccessible then the alert tone can be used to indicate whether the radio passed the tests. If the tests are successfully completed there will be a 1 kHz tone on SPKR 1 and it will be heard on the speaker if the board is in radio. If no alert tone is present, then either the ROM or RAM test has failed.

If the radio fails these tests, the microcomputer function is defective. Before replacing the microcomputer, exhaust all other possibilities. Check associated circuits for shorted or open printed wire runs and components.

IMPUT/OUTPUT TESTS

If the ROM and RAM tests are completed satisfactorily, release the PTT switch and remove A+ from J702-10, Hote that the data bus will still indicate 02 (Mex), however, the 1 kHz tone should no longer be displayed on the scope or heard on the speaker. The I/O test grounds one pin at a time on Port I and the data bus and is stepped through the test sequence by operating the PTT switch (momentarily grounding JEO1-II). Port I and the data bus can be monitored using a voltmeter. Port I consists of pins 27-34 on microcomputer IC702. The data bus includes pins 12-I9 on IC702. Refer to schematic diagram for data bus and port identification for IC702. For example:

PI7 = port 1 bit 7.

- Homentarily press and release the PTT switch (J801-II) Fort 1 and data bus lines all will go high.
- Momentarily press and release the PTT switch (J801-II). IC702-34 and IC702-19 will go low. All other outputs should be high.
- Homentarily press and release the PTI switch (JB01-ii). IC702-33 and IC702-18 will go low. All other outputs should be high.
- 4. Homestarily press and release the PIT switch (J801-11), IC702-17 will go low. All other outputs should be high. Note that IC702-32 will remain high. This is because this output switches the radio into the transmit mode when grounded. Thus the output is bypassed so that the radio will never go into the transmit mode during self test.
- Homentarily press and release the PHT switch (JMO1-11). 16702-31 and 16702-16 will go low. All other outputs should be high.
- Howentarily press and release the PIT switch (J801-11). 1C702-30 and IC702-15 will go low. All other outputs should be high.
- Momentarily press and relater the PTT switch (J801-11). IC702-29 and IC702-14 will go low. All other outputs should be high.

- Homentarily press and release the PTT switch (J801-11). IC702-28 and IC702-13 will go low. All other outputs should be high.
- Homentarily press and release the PTT switch (JS01-11), IC702-22 and IC702-12 wall go low. All other outputs should be high.
- Homentarily press and release the PTT switch (J801-11). Purt I outputs will all be set high.

LIE

At this point the program advances to mirror the outputs PTT, CG DISBL, ADVANCE CHANGE, and FB4-FB1 into the data bus IC702-12 throught IC702-19, respectively.

II. Momentarily apply ground to the fullowing points while observing status of the associated data but as indicated below. When ground is applied, the data bus should go low and them go high when ground in featured.

Momentarily Ground	Data Bus	Homestarily Ground	Data Bus	
J801- 30	IC702-18	J801-13	10702-14	
J801-10	IC702-17	.58912	IC702-13	
J801-32	10702-16	J801-1	IC702-12	
J801-4	10702-15	J801-11	IC702-19	

 Exit the diagnostic routines by momentarily removing power from the radio.

TEST FREQUENCIES

If the EEPROM is not custom programmed to the customer specified personality, then a standard test program is provided. The EEPROM is programmed on several channels including tone and digital Channel Guard and carrier control timer. The test program is given in Table 3.

UHF TEST PROGRAM FREQUENCY

BAND	C H	TX (MHz)	RX (MHz)	CG (Hz)	сст
(MHz)	-	(1012)	(1412)	(112)	
403.00	1	412.975	412.950	71.9	
to	21	403.500	403.025	023	
423.00	3	422.975	422,950	71.9	0.30
423.00	4	412.975	412.950	,,,,	0.30
	4	412.973	412.930		
410.00	1	419.975	419.950	71.9	
to		410.500	410.025	023	
74.	2		429,950	71.9	0.30
430.00	3	429.975		/1.9	0.50
	4	419.975	419.950		
420.00	,	429.975	429.950	71.9	
420.00		420.500	420.025	023	
-	2			71.9	0.30
440.00	- 1	439.975	439.950	/1.9	0.30
	4	429.975	429.950		
430.00	1	439.975	439.950	71.9	
430.00 to	2	430.500	430.025	023	
			449.950	71.9	0.30
450.00	3	449.975		/1.9	0.30
	4	439.975	439.950		
450.00	1	459.975	459.950	71.9	
to	2	450.500	450.025	023	
470.00	- 1	469.975	469.950	71.9	0.30
4/0.00	4	459.975	459.950	,,,,	0.50
	4	439.973	439.930		
470.00	1	478.975	478,950	71.9	
to	2	470.500	470.025	023	1
488.00	7.5	487.975	487.950	71.9	0.30
400.00	4	478.975	478.950		
	-	4/0.3/3	470.750		-
482.00	1	490.975	490.950	71.9	
to	2	482.500	482.025	023	
500.00	_	499.975	499.950	71.9	0.30
300.00	4	490.975	490.950		36.13168
	L	.,,,,,,			-
494.00	1	502.975	502.950	71.9	1
to	2	494,500	494.025	023	
512.00	1 -	511.975	511.950	71.9	0.30
312.00	4	502,975	502.950	1	
	1	302.773			

BAND: frequency band

CH : channel number

TX : transmit frequency

RX : receive frequency

CG : channel guard

CCT : carrier control timer

TABLE 3 - TEST PROGRAM

PA TROUBLESHOOTING PROCEDURE

DC VOLTAGE CHECK

First, Check the meter readings for power supply voltage and various stabilized DC voltages, at J606.

The typical readings for the test positions and test points are given in the chart below. The meter readings are typical using General Electric Test Set 4EX3All with Test Set Adapter 19C851532Gl.

TEST POSITION	METERING POINT	FUNCTION MEASURED	SCALE	TYPICAL READING
В	J606- 3	9V-RX	0-15V	9 V
С	J606-4	5 v	0-15V	5₹
H	J606-8	EX9V	0-15V	9V
Ĭ	1606-9	+8V	0-15V	87
Ţ	J606-11	9V	0-15V	90
К	J606-12	A+	0-15 v	13.6V

TABLE 4 - READINGS AT J606

EXCITER QUICK CHECK

When troubleshooting the transmitter check for typical readings for the DC voltages across Exciter resistor R116, the Synthesizer output (J207), and the Exciter output (J102) as listed in Table 5.

SYMPTOM	PROCEDURE	ANALYSIS
Little or No RF Output	Unkey transmitter and check IC101-3 for +9.0 VDC Key transmitter and Check DC voltages on TR101-TR106. (No RF Present)	resistors for each stage. Check R106, R112, R123, R126, and R132. Check TR101-TR105. Replace
	Key transmitter and check DC voltages on TRIOI-TRIO5. (RF Present)	Voltage should decrease when the transmitter is keyed. If not, check C101, C103, C107, C108, C112, C113, C116, C125, C140 and L109-L111.
	Disconnect the coaxial cable 2C601 from PA and measure RF input power from exciter. Should be 0.25 Watts or more.	If exciter output is low, check TR105 and associated circuitry. Check FL101-FL103. If output power is correct, be sure ZC601 is soldered securely and that it mates proper: with the contact on the power amplifier.

TABLE 5 - EXCITER QUICK CHECK

TYPICAL PERFORMANCE INFORMATION

SIGNAL LEVELS

SIGNAL	INDICATION	VOLTAGE	FEAET
CAS	High Level	9.0	VDC
	Low Level	0.15	VDC
RUS	High Level (Rx Un-sq)	9.0	VDC
	Low Level (Rx Squelched)	0.15	VDC
	Low Level (Rx Mute/PTT pulled		
	low, Rx unsquelched)	0.6	VDC
SQ DSBL, Input		0	VDC
	Logic High(Sq)	2.4	VDC
	Rx Un-Sq	0.14	
CCT PA ENBL	Logic Low	0.35	
	Logic High	5.5	
Tx ENBL	Logic Low	2.0	VDC
	Logic High	9.0	
PTT, Input	Logic Low	0	VDC
•	Logic High	13	VDC

TABLE 6 - SIGNAL LEVELS

Front Connector	J801
System Metering	J606
RX RF	J401
LNI XX	J206
TX INJ	3207
EX Output	J102

TABLE 7 - RADIO COMMECTOR IMPENTIFICATION

TRANSMITTER ALIGNOST

TEST PROCEDURES

These Test Procedures are designed to assist you in servicing a transmitter that is operating, but not properly. Once a defect is pinpointed, refer to the Transmitter Troubleshooting Procedure. Before starting, be sure that transmitter is tuned and aligned properly.

CAUTION

Before bench testing the radio, be sure of the output voltage characteristics of your bench power supply.

To protect the transmitter power output transistors from possible instant destruction, the following input voltages must not be exceeded:

Transmitter unkeyed:

Transmitter keyed (50 ohms resistive load):

16.5 Volts

Transmitter keyed (50 ohms resistive load):

16.3 Volts

Transmitter keyed (no load or non-resistive load):14.0 Volts

These voltages are specified at the normal vehicle battery terminals of the radio and take the voltage drop of standard cables into account. The voltage limits shown for a non-optimum load is for "worst case" conditions. For antenna mismatches likely to be encountered in practice, the actual limit will approach the 16.3 Volt figure.

Routine transmitter tests should be performed at EIA Standard Test Voltages (13.6 VDC for loads of 6 to 16 amperes; 13.4 VDC for loads of 16 to 36 amperes). Input voltages must not exceed the limits shown, even for transient peaks of short duration.

Many commonly used bench power supplies cannot meet these requirements for load regulation and transient voltage suppression. Bench supplies which employ "brute force" regulation and filtering (such as Lapp Model 73) may be usable when operated in parallel with a 12 Voltautomotive storage battery.

MODULATION LEVEL ADJUSTMENT

The MOD ADJUST controls are adjusted to the proper setting before shipment and normally do not required readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing over-modulation while preserving intelligibility.

TEST EQUIPMENT

- 1. An audio oscillator (GE Model 4EX6A10)
- 2. Deviation Monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Model 4EX3All with Test Set Adapter Cable 19C851532G1

PROCEDURE OF SYNTHESIZER TRANSMIT DEVIATION

NOTE -

The transmit deviation has been properly set by the factory and should require no readjustment. Should it become necessary to adjust the deviation please refer to the Maintenance Manual LBI-31731 and the section TX AUDIO PROCESSOR in SYSTEM CONTROL BOARD and MODULATION LEVEL CONTROL in FREQUENCY SYNTHESIZER BOARD. These will familiarize you with the modulation deviation and make the Alignment Procedure more understandable.

- 1. Select a center frequency channel. Remove Pt05.
- 2. Rotate RV201 and RV603 fully counterclockwise.
- 3. Apply a 1 kHz tone at 1 Vrass through a $100\mu\text{F}$ capacitor to MIC HI at J701-16 (+ lead of capacitor).

Connect the deviation monitor to the antenna connector J2 via a 30-dB coupler, whose output is terminated in a 50-ohm load. Key the radio.

Set VCO DEVIATION ADJUST, RV202 for ±3.75 kHz deviation.

- 4. Set RV603 fully clockwise. Apply a 400 Hz tone to J605-2 and with the radio keyed, vary its amplitude until the Deviation Monitor reads 2 kHz. Note the level.
- 5. Change the signal generator frequency to 10 Hz at the same level and set REF MOD ADJUST, RV201 for a deviation of 2 kHz. Unkey the radio.
- 6. Disconnect the signal generator and replace P605 in position 1-2.
- Select a frequency with Channel Guard (preferably close to the center frequency).

Key the radio and set CG DEVIATION ADJUST, 8V603 for a deviation reading of +0.75 kHz.

MOTE: If Channel Guard or Voice Guard is not used on any frequency, the VCD DEVIATION ADJUST RV202 may be set for a deviation of ± 4.5 kHz instead of ± 3.75 kHz.

AUDIO CHECKS

TEST EQUIPMENT REQUIRED

Audio Oscillator

Oscilloscope

· AC Voltmeter

Deviation Monitor

AUDIO AC VOLTAGE

 Connect audio oscillator output across J701-16 (or J801-9) and J701-3 (or J801-5).

		1C607-1	IC607-7
SCOPE SETTING	HORIZONTAL	200 µSEC/DIV	200 µSEC/DIV
	VERTICAL	2 VOLTS/DIV	2 VOLTS/DIV
SET AUDIO OS at 1000 Hz W OF 1.0 VRMS. ADJUSTED FOR	ITH OUTPUT MODULATION		
		•	

AUDIO SENSITIVITY

- Connect audio oscillator output across J701-16 (or J801-9) and J701-3 (or J801-5). Adjust output for 1000 Hz at 1.0 VRMS.
- Reduce generator output until deviation falls to 3.0 kHz for radios without Channel Guard or to 2.25 kHz for radios with Channel Guard. Voltage should be less than 120 millivolts.

SYNTHESIZER AND TRANSMITTER ALIGNMENT

TEST EQUIPMENT REQUIRED

- 1. Wattmeter, 50 ohm (capable of measuring 150 Watts & 1 Watt)
- 2. DC Voltmeter, 20,000 ohms per volt
- 3. Digital Voltmeter
- 4. Power supply, 13.8 VDC regulated
- 5. GE Test Set 4EX3All with Test Set Adapter Cable 19C851532Gl

PRELIMINARY CHECKS AND ADJUSTMENTS

- NOTE -

Refer to Figure 3 for location of tuning and adjustment controls.

- 1. Apply DC power to radio.
- Connect plug of GE Test Set to Metering jack J606. Set polarity to "+" and voltage range to the ! volt position (Test !).

— note —

Before alignment or making any adjustments to the transmitter, be sure that power supply voltage (A+) and various stabilized DC voltages are proper. Refer to Table 4.

ALIGNMENT PROCEDURE

- SYNTHESIZER -

STEP	METERING POINT	TUNING CONTROL	METER READING	PROCEDURE
				The synthesizer is factory aligned and should not require further adjustment. Should it become necessary to adjust the synthesizer, please refer to the Maintenance Manual LBI-31731 and "Frequency Synthesizer" section. These will familiarize you with the operation of the VCO's and make the Alignment Procedure more understandable.
				The label on the cover of the Synthesizer must be removed, or holes made in it to gain access to the existing holes in the shield. These hole locations are shown in Figure 3.
				Should it become necessary to adjust the synthesizer, program a PROM to the highest frequency of the split (400 MHz for A board, 470 MHz for B board or 512 MHz for C board) for proper alignment.
1.	TP201 (Control Voltage Monitor)	CV202	7.0 VDC	Select highest frequency transmit channel in the split (440 MHz-A, 470 MHz-B, 512 MHz-C). With a 50 ohm load on the antenna connector J3, key the radio. Adjust CV202 until the lock detector indicator CD710 goes out. Monitor TP201 with a digital voltmeter and adjust CV202 for a reading of 7.0 ±0.1 VDC. Check that CD710 remains out. Unkey the radio.

STEP	METERING POINT	TUNING CONTROL	METER READING	PROCEDURE
2.	TP201 (Control Voltage Monitor)	CV201	7.0 VDC	Select highest receive channel in the split as in Step 1 (release PTT switch). Adjust CV201 until lock detector indicator CD710 goes out. Monitor TP201 with a digital voltmeter and adjust CV201 for a reading of 7.5+0.1VDC. Check that CD710 remains out.
3.	TP201 (Control Voltage Monitor)		3.5 to 7.5 VDC	Select each receive and transmit channel. Voltage at TP201 should be between 3.5 and 7.5 VDC.
4.	J207 J206		-3 to +6	Monitor TX injection at J207 and Rx injection at J206 Tx injection -3 to +6 dBm Rx injection -3 to +6 dBm

- REFERENCE OSCILLATOR FREQUENCY -

STEP	METERING POINT	TUNING	METER READING	PROCEDURE
5.	J207	FREQ TRIM Control on VC-TCXO	Channel Operating Frequency	

STEP	METERING POINT	TUNING CONTROL	METER READING	PROCEDURE
				NOTE
				The Exciter requires no adjustment. If it becomes necessary to check the Exciter, proceed as follows.
6.				NOTE
				The Exciter can be isolated from the rest of the radio for checking purposes, if desired. To isolate and set up for alignment, remove coaxial cables 2C608 and ZC610. Connect a (0-1 watt) wattmeter to J102. Apply a 0 dBm on-frequency signal to J101.
	J102		250 mH	Check output power on the wattmeter. It should be greater than 250 milliwatts.
7.				Disconnect wattmeter from J102. Reinstall 2608 and 2610 if removed. Connect a (0-150 watts) wattmeter set to antenna jack J3.
	J3	RV1	Rated Output Power	80/100 WATT POWER AMPLIFIER Monitor the transmitter output power on each channel. Select the channel with the lowest output power and set RVI for 80/100 watts output.
				30/35 WATT POWER AMPLIFIER Monitor the transmitter output power on each channel. Select the channel with the lowest output power and set RV1 for 30/35 watts output.

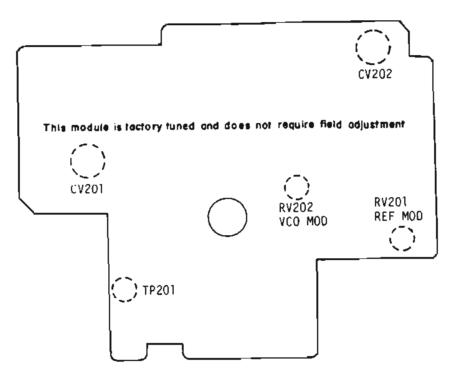


Figure 3 - Hole locations for synthesizer tuning and transmitter deviation adjustment

RECKIVER ALIGNMENT

Alignments for Front-End and Local Injection circuits are not required because a band-pass filter is employed in the RANGR wide band synthesized radio receiver.

TEST EQUIPMENT REQUIRED

- GE TEST Set 4EX3A11, 4EX8K12, or 20,000 ohms-per-volt multimeter.
- AC Voltmeter
- RF Signal Generator
- Frequency Counter (403 to 512 MHz)
- 4-ohm 15 watt resistor.
- Audio Isolation Transformer (1:1) 19Al16736P1 or equivalent

- NOTE

Before aligning the receiver or making any adjustments to the radio be sure that the output of 9 Volt Regulator is 9.0 ±0.2;

ADJUSTMENT PROCEDURES

RECEIVER FREQUENCY ADJUSTMENT

No receiver frequency adjustment is required.

2nd RECEIVER OSCILLATOR

Using a frequency counter monitor 2nd Local Terminal. Set L509 for a frequency of 82.655 MHz +200 Hz.

IF/FM DETECTOR ALIGNMENT

Apply a 1000 microvolt, on-frequency test signal modulated by 1,000 Hz with ± 3.0 kHz deviation to antenna jack J3.

Connect a 4-ohm, 15-watt resistor in place of the speaker. Connect the isolation transformer input across the resistor. Connect the isolation transformer output to the Distortion Analyzer (See Figure 5).

Adjust the VOLUME control for 5 watts output (4.47 VRMS) using the Distortion Analyzer as a voltmeter.

Set the output signal level of the RF signal generator so as to obtain 12 dB SINAD at audio output.

Adjust coils L504 to L508 to obtain minimum 12 dB SINAD.

Set the output signal level of the RF signal generator to 1000 microvolt.

Adjust L511 for maximum audio output.

Adjust RV602 for audio output level at TP1 of 300 mVrms.

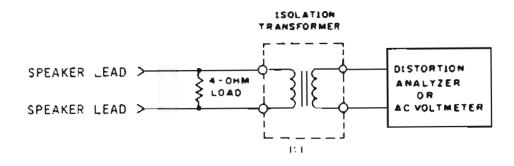


Figure 5 - Audio Isolation Transformer

RV605 ADJUSTMENT PROCEDURE

RV605 is used to set squelch amplifier gain to correct for noise variations between various bands of RANGR. This control does not require adjustment unless the squelch hybrid HC601 is changed or the systems board is exchanged between radios of different frequency bands.

- 1) Connect a signal generator to the antenna connector.
- Set the squelch control on the Control Head fully clockwise.
- 3) Ser RV605 on the System Control board fully clockwise.
- 4) Set the signal generator to the level to produce 20dB quieting.
- 5) Raise the generator level by 4dB.
- b) Set the squelch control on the Control Head fully counterclockwise.
- 7) Adjust RV605 until the squelch just closes.
- 8) Set the modulation frequency to lkHz with 3kHz deviation.
- Check the signal generator level required to just open the squelch. It should be greater than the 20dB level and less than luv.

RECEIVER AUDIO AND SQUELCH CHECKS

SQUELCH CIRCUIT TEST WITH SEHE SIGNAL PRELIMINARY STEPS

- Set the squelch volume on the control head to close at \$ 48 SIMAD level.
- Quiet receiver with 1000 uV modulated signal applied to antenna jack J3.
- 3. Set andulation frequency to 6 kHz.
- 4. Set deviation to 3 kHz.
- 5. Use 10 megohm probe.

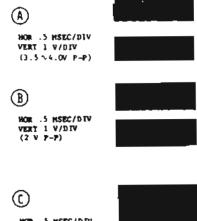






SQUELCH CIRCUIT CHECKS WITH NOISE

- Set the equalch on the control head to close at 8 dB SINAD level.
- 2. Remove input signal.
-). Use 10 megohm probe.



AUDIO CIRCUIT

PREL DILBARY STEPS

- Apply 1000 uV on frequency signal with 1000 kg modulation and 3 kHz deviation to antenna jack 33.
- Output set to 10 Watts (6.3 VEMS) into 4-ohm load.
- 3. Use 1 megolm probe.

D HOR .5 MSEC/DIV VERT 50 mV/DIV (160 mV P-P)



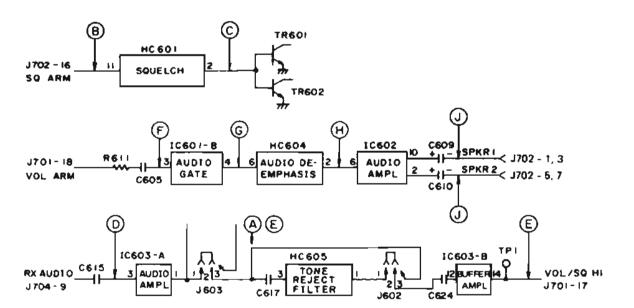


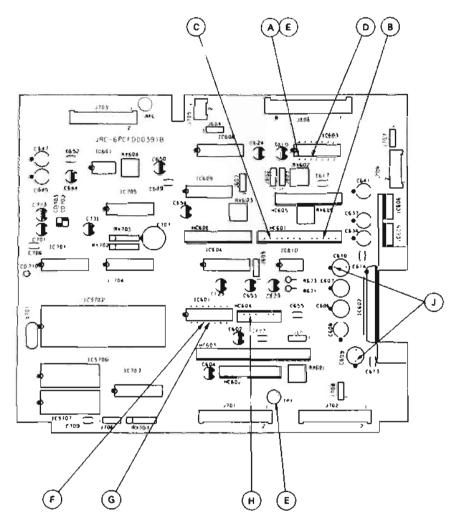












TEST PROCEDURE

These Test Procedures are designed to help you to service a receiver that is operating, but not properly. The problems encountered could be low power, poor sensitivity, distortion, limiter not operating properly, and low gain. By following the sequence of test steps starting with Step 1, the defect can be quickly localized. Once the defective stage is pinpointed, refer to the "Service Check" listed to correct the problem. Additional corrective measures are included in the Troubleshooting Procedure. Before starting with the receiver Test Procedures, be sure the receiver is tuned and aligned to the proper operating frequency.

TEST EQUIPMENT REQUIRED

- · Distortion Analyzer
- Signal Generator
- · 6 dB attenuation pad
- Audio Isolation Transformer

4-ohm resistor (15-watt minimum)

PRELIMINARY ADJUSTMENT

- NOTE

These procedures are written around the Heathkit Distortion Analyzer. If a Distortion Analyzer other than the Heath IM-12 is used, measure the sensitivity and modulation acceptance bandwidth in accordance with manufacturer's instructions.

1. Unsquelch the receiver.

STEP 1 AUDIO POWER OUTPUT AND DISTORTION

TEST PROCEDURE

Measure Audio Power Output as follows:

A. Apply a 1000 microvolt, on-frequency test signal modulated by 1,000 Hz with 3.0 kHz deviation to antenna iack J3.

B. With 10 Watt Speaker

Disconnect the speaker. Connect a 4-ohm, 15- Watt load resistor in its place.

Connect the isolation transformer input across the resistor. Connect the isolation transformer output to the Distortion Analyzer (See Figure 5).

- C. Adjust the VOLUME control for 10watt output (6.32 VRMS) using the Distortion Analyzer as a voltmenter.
- D. Make distortion measurements according to manufacturer's instructions. Reading should be less than 3%. If the receiver sensitivity is to be measured, leave all controls and equipment as they are.

SERVICE CHECK

If the distortion is more than 3%, or maximum audio output is less than 10-watt, make the following checks:

- E. Battery and regulator voltage---low voltage will cause distortion. (Refer to Receiver Schematic Diagram for voltages.)
- F. FM Detector alignment (Refer to Receiver Alignment).

STEP 2 USABLE SENSITIVITY (12 DB SINAD)

TEST PROCEDURE

[f STEP 1 checks out properly, measure the receiver sensitivity as follows:

- A. Apply a 1000 microvolt, on-frequency signal modulated by 1000 Hz with 3.0 kHz deviation to J3.
- B. Place the RANGE switch on the Distortion Analyzer in the 200 to 2000 Hz distortion range position (1000 Hz filter in the circuit). Tune the filter for minimum reading or null on the lowest possible scale (1002, 30%, etc.)
- C. Place the RANGE switch to the SET LEVEL position (filter out of the circuit) and adjust the input LEVEL control for a +2 dB reading on a mid range (30%).
- D. Set signal generator output to 0.3 µV. Switch the RANGE control from SET LEVEL to the distortion range. Readjust Distortion Analyzer SET LEVEL as required until a 12 dB difference (+2 dB to -10 dB) is obtained between the SET LEVEL and distortion range positions (filter out and filter in).
- E. The 12 dB difference (Signal plus Noise and Distortion to noise plus distortion ratio) is the "usable" sensitivity level. The sensitivity should be less than rated 12 dB SINAD specifications with an audio output of at lesst 5 Watts (4.47 Volts RMS across the 4.0 ohm receiver load using the Distortion Analyzer as a Voltmeter).
- F. Leave all controls as they are and all equipment connected if the Modulation Acceptance Bandwidth test is to be performed.

SERVICE CHECK

If the sensitivity level is more than rated 12 dB SINAD, check the alignment of the IF stages as directed in the Alignment Procedure.

STEP 3 MODULATION ACCEPTANCE BANDWIDTH (IF BANDWIDTH)

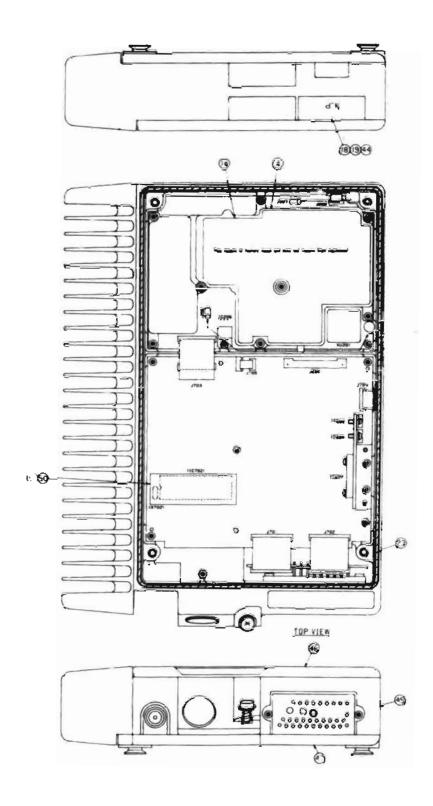
TEST PROCEDURE

If STEPS 1 and 2 check out properly, measure the bandwidth as follows:

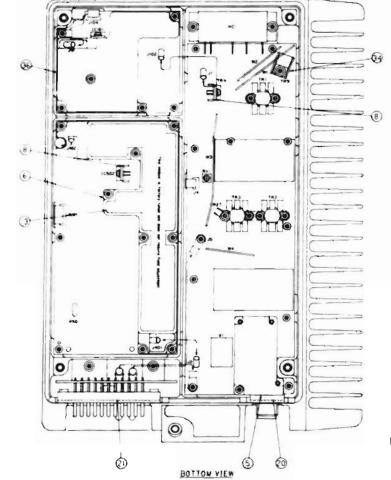
- Reduce audio output level to 10% of rated output.
- B. Set the Signal Generator output for twice the microvolt reading obtained in the 12 dB SINAD measurement.
- C. Set the RANGE control on the Distortion Analyzer to the SET LEVEL position (1000 Hz filter out of the circuit), and adjust the input LEVEL control for a +2 dB reading on the 30% range.
- D. While increasing the deviation of the Signal Generator, switch the RANGE control from SET LEVEL to distortion range until a 12 dB difference is obtained between the SET LEVEL and distortion range readings (from +2 dB to -10 dB).
- E. The deviation control reading for the 12 dB difference is the Modulation Acceptance Bandwidth of the receiver. It should be more than +7.0 kHz.

SERVICE CHECK

If the Modulation Acceptance Bandwidth test does not indicate the proper width, check the synthesizer frequency and then refer to the alignment of IF stages.

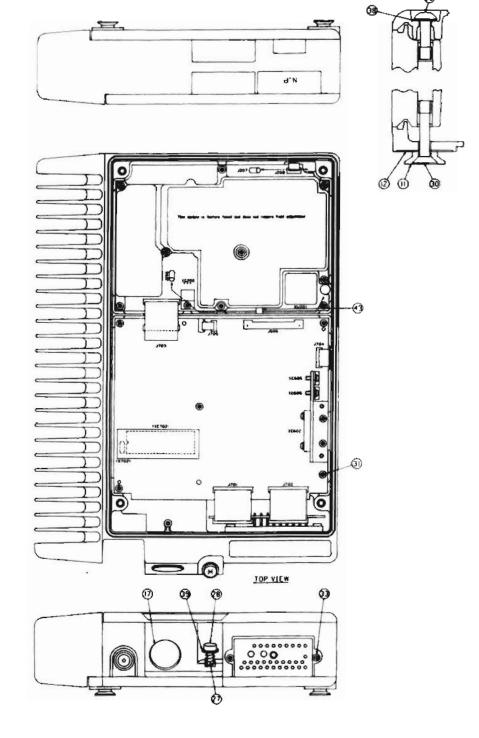


MECHANICAL LAYOUT DIAGRAM 1/2



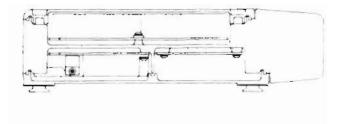
NO.	NOWENCL ATOR	CODE
4	CASE, SHIELD	B19/WTC0024258
5	CASE, SHIELD	B19/WTC0024268
6	CASE, SHIELD	BI9/WTC0024284
8	PLATE, NEAT SINK	BI9/WTBI47952A
13	SEAL	B19/WTT021171A
14	SEAL	819/MTT0211728
18	PLATE SERIAL NO.	B19/MPNNIB115
19	OVERLAY	B19/MPHH19349
20	GASKET ARTENNA CONNECTOR	B19/WPPK01254A
21	GASKET, INTERFASE CONNECTOR	B19/WPP(01255A
22	GASKET, SHIELD	819/MPPK01286
23	GASKET, SHIELD	B19/WPPK01286
74	GASKET, SHIELD	BIS/MPPEDIIS!
25	GASKET, SHIELD	B19/MPPK01162
76	GASKET, SHIELD	B19/WPP(0163
34	PLATE HEAT SINK	B/9/WTB/50008
36	CASE, SHIELD	B/9/WTC002430A
44	ADHESIVE TAPE	B19/W120028
45	FRAME ASM ICOMPLETE ASMI	B19/MPBC07182
46	TOP COVER ASM ICOMPLETE ASMI	B19/WP8C07110
47	BOTTOW COVER ASM ICOMPLETE ASM:	B19/MP8C07112
48	MOUNTING BRACKET	B19/MPBX14964
49	MOUNTING HARDWARE	B19/MPXP01744A
50	CASE, SHIELD	B19/418/53924
51	COVER, SHIELD	BI9/WTBI53975A

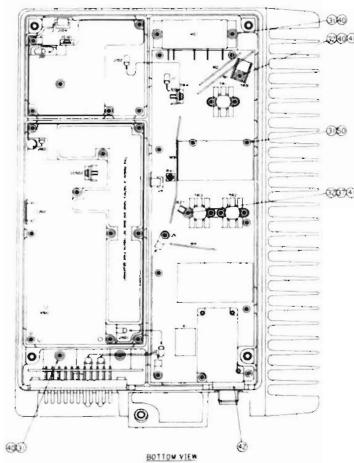
MECHANICAL LAYOUT DIAGRAM



HARDWARE (SCREW) KIT KIT CODE: B19/MPXP01954 1/2

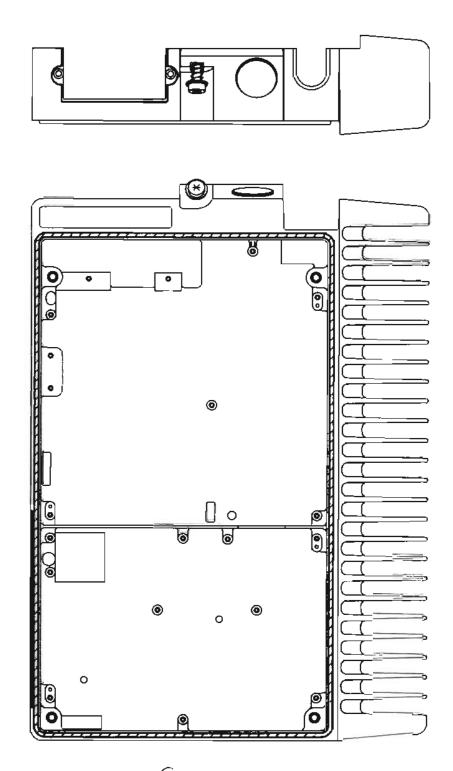
MECHANICAL LAYOUT DIAGRAM 2/2



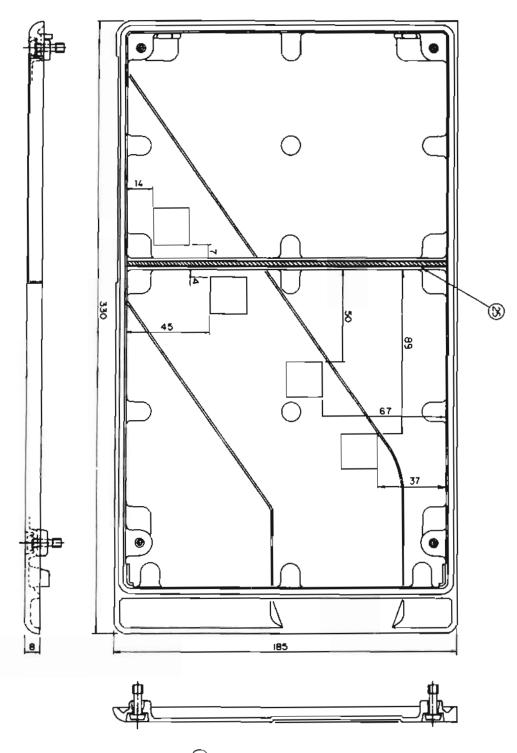


NO.	NOMENCLATOR	CODE	Sad bin vie
н	F001	Bi9/WTL032906B	4
12	SPACER	B19/WTT021134A	4
17	COVER	B19/MTV002836	
27	SPR146	B19/MP5R02159A	
78	SCREW	B19/MP7G02014A	
29	CCREM	B19/MP1602015	
30	SCREM	B19/MPTG02016	
31	SCREW, PAR HEAD WILE	B/9/981G03830	62
32	SCREW, PAN HEAD W3172	B19/887603291	7
33	SCREW, FLAT HEAD W3110	B19/BR1603297	
37	SPACES	819/W1L035255	1
30	WASHER, THRUST	B19/BF 1501781	4
39	MAGNEP .	B19/BRTG0330	
40	MASHER .	B19/85F W030005	4.
41	LOCK MASHER	BI9/BRTG03497	3
42	SPACER	8/9/W18/5007/	1
43	CLAMP, CABLE	BI9/W11021147	.1.
50	MASHER	B19/BSL W030005	2

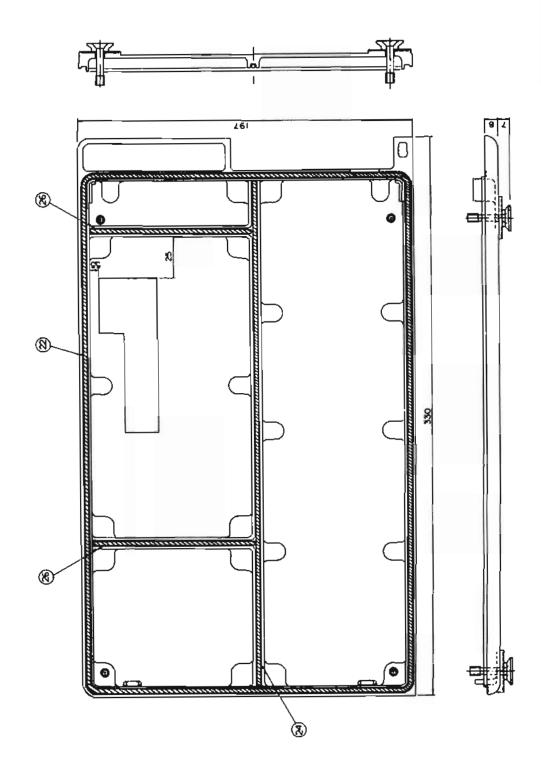
HARDWARE (SCREW) KIT KIT CODE: 819/MPXP01954 2/2



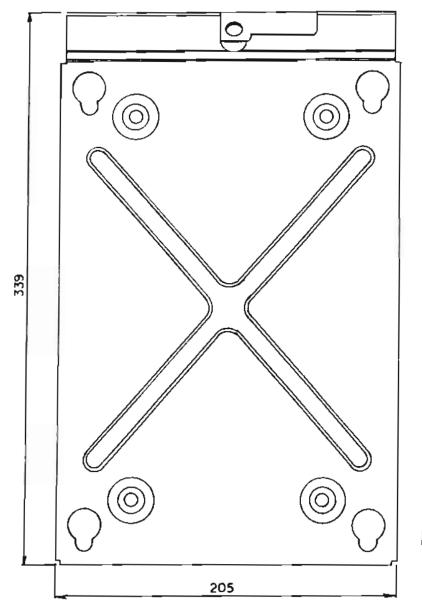
(45) FRAME ASSEMBLY ASM CODE: B19/MPBC07182

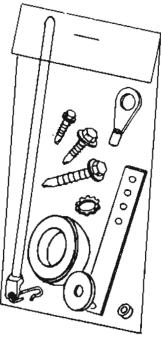


(46) TOP COVER ASSEMBLY ASM CODE: B19/MPBC07110



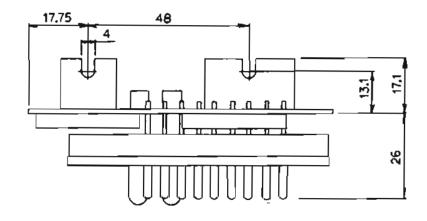
67)
BOTTOM COVER ASSEMBLY
ASM CODE: B19/MPBC07112

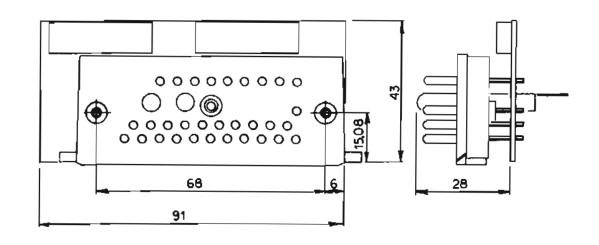




MOUNTING BRACKET
CODE:B19/MPBX14964

MOUNTING HARDWARE KIT
KIT CODE: B19/MPXP01744A





INTERFACE BOARD ASSEMBLY
ASM CODE:B19/CFQ-2223



HAIRTKHANCE MARUAL

403-512 MHz BOARD ASSEMBLIES

_	TABLE OF CONTENTS	
		Page
	DESCRIPTION	C2
	CIRCUIT ANALYSIS	C2
	SYSTEM CONTROL BOARD	C2
	FREQUENCY SYNTHESIZER BOARD	C14
	EXCITER BOARD	C19
	PA BOARD	C19
	RECEIVER BOARD	C20
'	DRAWINGS & PARTS LISTS	D1 - D53

DESCRIPTION

The System Control board for RANGR provides all functions necessary for two-way communications. This board is controlled by the control unit.

The System Control board interconnects with the power/control cable from the control unit.

The System Control board contains the audio circuitry, microcomputer, EEPROM and voltage regulators. The micro-computer controls all system functions, supplies frequency data to the frequency synthesizer, and tone/code data for the Channel Guard.

In addition to the normal radio functions, the microcomputer contains self-diagnostic maintenance routines to aid in troubleshooting the radio. Included are an internal test of the microcomputer and input/output tests to assure proper operation of the dats port and data bus. Details and procedures are included in the Service Section of this manual.

Centralized metering jacks for servicing are accessible from the top of the radio.

The system control and interface circuits consist of the microcomputer, electrically eraseable PROM, interface circuits for voltage shifting and protection, and a watchdog timer. The EEPROM gives the user the capability to program the radio's personality as desired. The EEPROM contains the receive and transmit frequency data, Channel Guard tone frequencies/digital codes and the CCT delay on a perchannel basis.

The EEPROM may be programmed serially through the front connector using the General Electric Universal Radio Programmer Model TQ2310.

NOTE -

CIRCUIT AMALTSIS

SYSTEM CONTROL BOARD

MICROCOMPUTER AND CONTROL

The microcomputer interfaces with the control unit through J701/J702 and responds to all user commands and control functions originating from the control unit. It provides the transmit and receive data to the frequency synthesizer, switching information for tone and digital Channel Guard, and provides the carrier control timer (CCT) function when the radio is in the transmit mode.

When the microphone is keyed, the PTT line from the control unit goes low. This low is applied to the microcomputer through buffer TR702 and inverter TR703. TR702 is controlled by ignition switch A+. The ignition switch must be on and A+ applied to the base of TR702. TR702 must be turned on to permit keying of the transmitter. When Channel Guard is present, the release of the PTT signal is delayed by the microcomputer for approximately 160 milliseconds to eliminate any squelch tail.

The microcomputer immediately closes the antenna relay switch by applying a low level to DPTT at IC702-28. The microcomputer then delays 15 milliseconds before transmit 9V is switched on by applying a low level to TX ENB at IC702-32. This is done to guarantee that the ante-na relay contacts are closed be the transmitter is energized. Once DPTT is low, the receive audio is muted. Buffers TR705 and TR704 provide DPTT to the audio control circuits, and antenna relay. IC704-B provides the DPTT signal to the Tx/Rx VCO's and the audio processor.

The TX ENB line is controlled by microcomputer port 1, bit 5 (IC702-32) through inverter TR710 and buffer TR712. A low level on IC702-32 turns TR710 off, allowing the base of TR712 to rise. TR712 turns on, and applies A- to the TX ENB line. Inverter TR711 is also turned on during this time to inhibit the alert tone.

CHANNEL SELECTION

The microcomputer and EEPROM provide the radio with up to 16 independent transmit and receive frequencies. Each time the PTT switch is operated the microcomputer transfers channel data from the EEPROM and converts it to frequency data assigned to the selected channel. The frequency data is then loaded serially into the frequency synthesizer.

The microcomputer continually monitors the status of tri-state buffers IC703A-D. These buffers are periodically turned off by a positive 5 volt, one-millisecond pulse from IC702-36. At the same time PROM power switch TR708 is turned on and applies +5 VDC to the EEPROM. When the buffers are turned on, channel select data is loaded into input/output ports of the microcomputer through ports P20-P23. Power is then applied to the EEPROM and the tri-state buffers are turned off. The microcomputer converts the channel select data into address information, accesses the EEPROM, and receives the frequency data stored in the addressed location.

This data then passes through the I/O ports of the EEPROM and P20-P23 of the microcomputer. The conversion process is repeated eight times in rapid succession (eight locations are required for each channel) and the data loaded serially into the frequency synthesizer over the clock and data lines. This data also includes Channel Guard information, if present, and carrier control timer information on a per-channel basis. A 4-millisecond channel change pulse from port P16 of the microcomputer is also sent to the

frequency synthesizer to speed up channel acquisition.

WATCHDOG TIMER

The watchdog timer, consisting of a digital counter IC701-A and TR701, monitors the operation of the micro-computer. IC701-A generates a reset pulse in the unlikely condition that the microcomputer goes awry and does not execute the software properly.

A 6 MHz crystal X701 steps the microcomputer through the software. As programmed in software a random pulse appears at IC702-35 and is applied to the base of inverter TR701 momentarily turning it on and inhibiting any reset pulse from timer IC701-A. A discharging circuit consisting of R710 and C705 forces the microcomputer to toggle IC701-A. If the timer does not receive any inputs for a specified period of time. TR701 turns off and IC701-A times Out and applies a reset pulse to pin 4 of the microcomputer. The watchdog reset will normally restore the microcomputer to normal operation so that only one pulse will occur. In the event the microcomputer is not restored to normal operation, a 6 Hz square wave will appear on the reset line and the indicator CD710 (normally unlit) will turn on. Refer to the self-diagnostic routine to determine the problem.

ADVANCE CHANGE PULSE

The advance change pulse is received from connector J702 and applied to the microcomputer interrupt port IC702-6 through inverter TR707. The advance change pulse is important in radios equipped with PSLM. When a call is received on a priority channel the advance change pulse interrupts the microcomputer, forcing it to service immediately the I/O circuits. The tri-state buffers are turned on and new channel select information read in.

CARRIER CONTROL TIMER

The carrier control timer function is executed by the microcomputer under software control on a per-channel basis. When the programmed time has elapsed an alert tone is generated from P13 (IC702-30) on the microcomputer, applied to the audio PA and heard on the speaker. The CCT may be programmed for 1 or 2 minutes or disabled (programmed for no CCT).

VOLTAGE TRANSLATION

Inverter buffers IC7048-F, TR713, and TR710 translate the 5 VDC levels required by the microcomputer to the +9 VDC level used by the frequency synthesizer. Inverter TR709 restores the proper polarity to the clock.

FREQUENCY SEGMENT CONTROL

To schieve rapid wideband VCO tuning extending over the 403-440 MHz range, the 440-470 MHz range, or 470-512 MHz range, each bandsplit is divided into four frequency segments.

By selecting one segment the operating frequency apread of the VCO is limited and frequency lock time reduced. Each segment is identified by two bits on a per-channel basis and programmed into the EEPROM. Capacitors are switched in and out of the VCO tank circuit to set the VCO tuning range to cover the correct frequency segment.

The frequency segment control circuit consists of a dual "D"-type flipflop operating under control of the microcomputer. The four frequency segment identification bits appear on the channel-change and data lines and fed to dual "D" FF IC705. At the appropriate time the microcomputer applies the enable signal to clock the new segment data change through the FF. The output of the FF's is a binary expression identifying the frequency segment selected. Table 1 identifies the binary expression and the selected frequency segment.

The output of the frequency segment control circuit is applied to the modulation level control and the frequency segment selector circuits.

		FREQUENCY SPLIT (MH2)	FF QUTPUT				
	SEGMENT		IC705-1 (IMPUT TR216)	IC705-2 (INPUT TR 217)	IC705-13 (INPUT TR 218)	IC705-12 (INPUT TR 219)	GROUNDED MODULATION RESISTOR
	1	403-412	0	1	0	1	NONE
100 / 100	2	412-421	0	1	1	0	R275
403-440MHz	3	421-430	1	0	0	1	R276, R296
	4	430-440	1	0	1	0	R275, R276 R296
	1	440-447	0	1	0	1	NONE
//	2	447-455	0	1	1	0	R275
440-470MHz	3	455-462	1	0	0	1	R276, R296
	4	462-470	1	0	1	0	R275, R276 R296
	1	470-480	0	1	0	1	NONE
470 traver	2	480-490.5	0	1	1	0	R275
470-512MHz	3	490.5-501	1	0	0	1	R276, R296
	4	501-512	1	0	1	0	R275, R276 R296

TABL: 1 - Frequency Segment Selection

TX AUDIO PROCESSOR

The audio processor provides audio pre-emphasis with amplitude limiting and post-limiter filtering and a total gain of approximately 24 dB. Approximately 27 dB gain is provided by IC607A, 4 dB by IC607B and -7 dB by R653, R654.

The 9 Volt regulator IC606 powers the audio processor and applies regulated 9 volts to a voltage divider consisting of R651, R655 and symmetry control, RV604. The +4.5 V output from the voltage divider establishes the operating reference point for operational amplifiers IC607A and IC607B. C647 provides an AC ground at the summing input of both operational amplifiers.

When the input signal to IC607A-2 is of a magnitude such that the amplifier output at IC607A-1 does not exceed 5 volts P-P, the amplifier provides a nominal 27 dB gain. When the audio signal level at IC607A-1 exceeds 5 volts P-P, the amplifier gain is reduced to 1. This limits the audio amplitude at IC607A-1 to 6 volts P-P.

Resistors R650, R652 and C646 comprise the audio pre-emphasis network that enhances the signal-to-noise ratio. R652 and C646 control the pre-emphasis curve below limiting. R650 and C646 control the cut-off point for high-frequency pre-emphasis. As high frequencies are attenuated, the gain of IC607 is increased.

Audio from the microphone is coupled to the audio processor through R650 and C646.

The amplified output of IC607A is coupled through R653, C650, R656, R657, R658 and bilateral switch IC608C to a second operational amplifier IC607B. The bilateral switch is controlled by the DPTT line so that Tx audio is transmitted only when the PTT switch is pressed. IC607B provides a signal gain of approximately 4 dB.

The Channel Guard tone input is applied to bilateral switch IC608C, and IC609 controlled by the DPTT line. The CG tone then modulates the reference oscillator and VCO on the synthesizer board.

A post-limiter filter consisting of IC607B, R656-R659, C651 and C652 provides 12 dB per octave roll-off. R653 and C649 provide an additional 6 dB per octave roll-off for a total of 18 dB. The output of the post-limiter filter is coupled through the VG (Voice Guard) unit or directly to the synthesizer Tx MOD.

TX enable switch IC608-D shorts out operational amplifier IC607-B when the radio is in the receive mode. The TX ENABL signal is generated by the microcomputer when the PTT switch is operated and is less than 2.7 VDC in the receive mode.

RX AUDIO

Received audio from the FM detector is applied to the input of audio preamplifier IC603-A. The audio output level of the audio preamplifier is adjusted by Volume/Squelch HI level control RV602 for 300 millivolts RMS. The audio of 300 millivolts RMS is applied to the audio preamplifier (IC603-B) through the Tone Reject filter (HC605). When VG (VOICE GUARD) is optionally added, this audio is applied to the VG circuit (BC602. HC603). Audio output from the VG circuit is applied to Tone Reject filter (HC605) through pins J603-2 & 3. The audio is then applied to the volume and squelch controls in the control unit through connector J701-17.

Audio is returned on the VOL ARM through J701-18 and applied to audio gate (bilateral switch) IC601-B. The audio gate is controlled by DPTT (delayted Push-To-Talk) and PA KEY/CCT PA ENB and is turned on when the control input (pin 5) exceeds 7 VDC. The gate is turned off when the control input is less than 2 volts. Receipt of

an on-frequency signal (if present) with sufficient signal-to-noise level and the correct Channel Guard frequency will cause the audio control circuit to apply +9 volts to IC601-B turning the audio gate on.

Audio from the audio gate is applied to the de-emphasis network consisting of a low-pass filter and a high-pass filter.

The low-pass filter provides a 6 dB per octave roll-off between 300 and 3000 Hz. The high-pass filter actenuates frequencies below 300 Hz.

The audio output from the de-emphasis network is applied to the non-inverting input of the audio power amplifier. The audio power amplifier consists of ICoO2, and associated circuitry, and provides 10-watts (6.3 VRMS across a 4 ohm load) of audio output power at terminals J7O2-1 and 5. The gain of ICoO2 is determined by the value of R615.

SQUELCH CIRCUITS

The squelch circuit (HC601) monitors noise on the SQ ARM output line and allows the receiver to be unmuted when an on-frequency signal reduces the noise level below the squelch threshold setting.

The 300 millivolt output of the audio preamplifier is applied to the squelch circuit through the variable squelch control in the control unit. The squelch control sets the noise threshold level required to operate the squelch circuit. When the noise falls below the threshold level, the receiver is unmuted.

The squelch circuit (HC601) consists of a high-pass filter, an averaging detector, DC amplifier, and a Schmitt trigger shown in Figure 1. The high pass filter consisting of HC601-A, removes all voice signals from the SQ ARM output and couples noise to HC601-B.

Noise in the 6-8 kHz range is applied to the averaging detector consisting of HC601-B. The noise is rectified and filtered to provide an average DC output level proportional to the noise input. The DC output level is adjusted by RV605.

The average DC level is amplified by HC601-C to a level ranging from 0 to 6.0 VDC, and applied to the non-inverting input of the Schmitt trigger, HC601-D. The inverting input of HC601-D is referenced to 4.5 VDC. IC603-C provides the stable 4.5 VDC reference voltage.

When the DC level exceeds 4.5 VDC, Schmitt trigger HC601-D switches and provides a positive voltage to the CAS (Carrier Activity Sensor) and RUS (Receiver Unsquelched Sensor) control transistors in the audio control circuits. The Schmitt trigger will remain on until the threshold level falls below approximately 4.3 VDC. This difference in voltage between the firing point and turn-off point provides sufficient hysterisis to eliminate "bubbling" -- i.e., noise popping in the speaker. The "bubbling" would normally be caused by transitional changes in the DC level around the reference point which allows the receiver to be unmuted.

When an on-frequency signal is received, there will be little or no noise present at the squelch input. This results in an absence of voltage at the output of the squelch circuit Schmitt trigger, allowing the receiver to be unmuted.

AUDIO CONTROL

- C7 -

The audio control circuits shown by Figure 2 control the operation of the audio gate (IC601-B) and the final audio PA and consist of TR601-605, inverter IC601-A and associated circuitry. The audio control circuit inputs consist of DPTT (Delayed Push-To-Talk), RX MUTE (Receiver Mute), PA KEY/CCT PA ENB (Public Address Key/Carrier Control Timer Public

Address Enable), and the output of the squelch circuit.

When an on-frequency signal with the correct Channel Guard Tone is received, CAS control transistor TR601 and RUS control transistor TR602 are turned off by the absence of a positive voltage at their bases. The CAS line from the collector of TR601 rises to +9 VDC and is supplied to J702-21.

The collector of RUS Transistor TR602 also rises to +9 VDC and turns on inverter IC601-A. A- is then applied to the base of inverter TR603, turning in off and allowing its collector to go high. The positive voltage on the collector is applied to audio gate IC601-B, turning it on. TR604 is biased on but has no effect on audio switch TR605. The base of the transistor is connected to the output of audio control switch IC601A-2 which is at A-, Therefore TR605 turns off, allowing input audio to the PA which feeds audio power to the speaker.

When the microphone is keyed, the DPTT input is low. This low is applied to audio gate IC601-B through CD604B, turning IC601-B off. It is also applied to audio control switch IC601-A (through CD604A) turning it off. TR603 is also off and TR604, TR605 are on. TR605 shorts out the audio input to the audio PA IC 602.

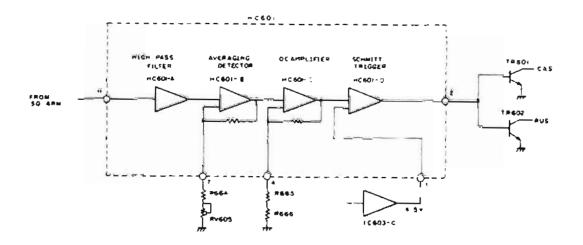


Figure 1 - Squelch circuits (HC601)

- C8 -

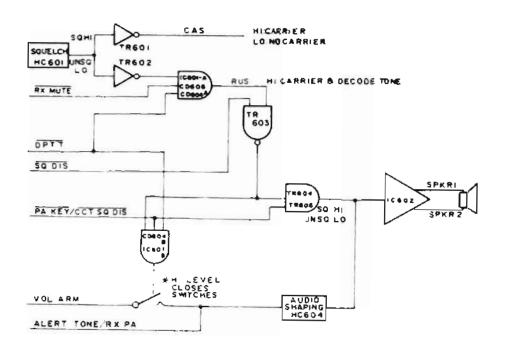


Figure 2 - Audio Control Circuit

POWER DISTRIBUTION

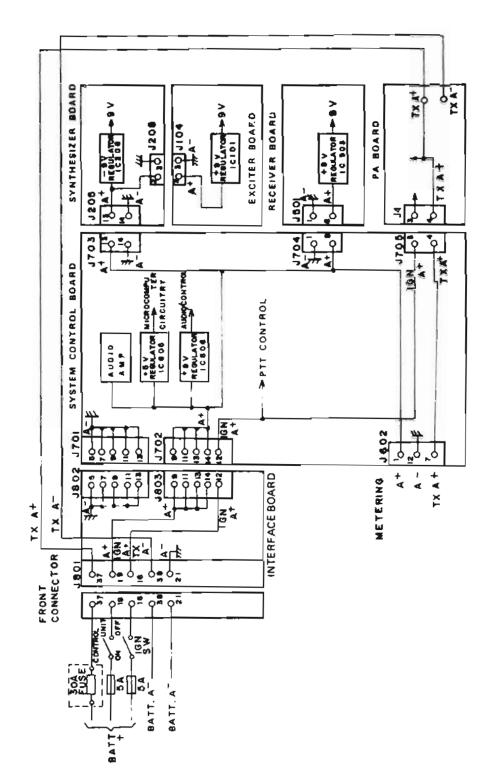
Battery supply A+ enters the radio through the front connector at J750-19. A- enters through J801. Figure 3 is a block diagram of the power distribution system. Two heavy connections are provided for transmit A+ and transmit A- and connect to two busses. The busses are connected to the PA through a special feedthrough arrangement. A second set of wires is routed through the control unit and supplies power to the audio amplifier and all other radio circuitry.





The CMOS Integrated Circuit devices used in this equipment can be destroyed by static discharges. Before handling one of

these devices, the serviceman should discharge himself by touching the case of a bench test instrument that has a 3-prong power cord connected to an outlet with a known good earth ground. When soldering or desoldering a CMOS device, the soldering iron should also have a 3-prong power cord connected to an outlet with a known good earth ground. A battery-operated soldering iron may be used in place of the regular soldering iron.



igure 3 - Power Distribution

CHANNEL GUARD

Channel Guard provides a means of restricting calls to specific radios through the use of a continuous-tone or digitally-coded squelch system (CTCSS or CDCSS). Tone frequencies range from 67 Hz to 210.7 Hz. 33 standard tones and 83 unique digital codes are available. These tones/codes are identified in Tables 2 and 3.

	STANDARD	TONE	FREQUENCIE	S Hz
67.0	88.5	107.	2 131.8	167.9
71.9	91.5	110.	9 136.5	173.8
74.4	94.8	114.	8 141.3	179.9
77.C	97.4	118.	8 146.2	186.2
79.7	100.0	123.	0 151.4	192.8
82.5	103.5	127.	3 156.7	203.5
85.4			162.2	210.7

TABLE 2 - Channel Guard Tone Frequencies

PR IMARY CODE	EQUIVALENT CODE	PR IMARY CODE	EQUIVALENT CODE	PR IMARY CODE	CODE
023	340, 766	205	135, 610	464	237,642, 772
025		223	350, 475, 750	465	056, 656
026	566	226	104, 557	466	144, 666
031	374, 643	243	267, 342	503	157, 312
032		244	176, 417	506	224, 313, 574
043	355	245	370, 554	516	067, 720
047	375, 707	251	236, 704, 742	532	161, 345
051	520, 771	261	227, 567	546	317, 614, 751
054	405, 675	263	213, 136	565	307, 362
065	301	265	171, 426	606	153, 630
071	603, 717, 746	271	427, 510, 762	612	254, 314, 706
072	470, 701	306	147, 303, 761	624	075, 501
073	640	311	330, 456, 561	627	037, 560
074	360, 721	315	321, 673	631 745	231, 504, 636
114	327, 615	331	372, 507	632	123, 657
115	534, 674	343	324, 570	654	163, 460, 607
116	060, 737	346	616, 635, 724	662 444	363, 436, 443,
125	172	351	353, 435	664	344, 471, 715
131	572, 702	364	130, 641	703	150, 256
132	605, 634, 714	365	107	712	136, 502
134	273	371	217, 453, 530	723	235, 611, 671
143	333	411	117, 756	731	447, 473, 474
152	366, 415	412	127, 411, 711		744
155	233, 660	413	133, 620	732	164, 207
156	517, 741	423 713	234, 563, 621	734	066
162	416, 553	431	262, 316, 730	743	312, 515, 663
165	354	432	276, 326	754	076, 203
172	057	445	222, 457, 575		
174	142, 270				

TABLE 3 - Primary and Equivalent Digital Codes (Octal)

The Channel Guard encode and decode functions are implemented in the microcomputer under software control. The microcomputer provides digital and/or tone Channel Guard with Squelch Tail Elimination (STE).

If the radio is in the receive mode, the Chennel Guard tone/code is hard limited and fed into the microcomputer through IC702-29 (LIM CG Tone Decode). If the correct tone code is present, the receiver is opened by the RX MUTE line. If the radio is in the transmit mode, the microcomputer generates the Channel Guard cone using WALSH BIT I and WALSH BIT 2. Those outputs are summed together and filtered on the System Control board to generate a smooth sinewave for tone Channel Guard or a degital waveform for digital Channel Guard.

The Channel Guard contains a summing amplifier IC604-A, 8-pole active voice reject filter HC60b, limiter IC604-C and tone/code reject filter HC605. A Channel Guard disable circuit TR606 allows the Channel Guard encode to be disabled. The Channel Guard decoder can be disabled at the microcomputer.

The microcomputer selects the assigned Channel Guard encode code/tone information from the EEPROM memory for each channel, transmit and receive, and generates the Channel Guard signal.

The output of audio preamplifier IC603-A is applied to the summing amplifier through bilateral switches IC601-C and D. In the encode mode DPTT is high applying A- from IC601-D to the control input of IC601-C turning it off and preventing the output of audio preamplifier IC603-A from interfering with the encoding signal.

The output of summing amplifier 1C604-A is applied to buffer/amplifier 1C604-B through a two-pole active voice reject filter HC606. The active filter shunts all frequencies above 300 Hz to

ground, thereby preventing those frequencies from interfering with the encoded signal. The output of IC604-B is the assigned CG tone or digital signal. This signal is applied to the TX HOD line throug. CG deviation control RV603, IC608C and TC607E. Chambal Guard deviation is set for 0.75 kHz.

In the decode mode DPTT is low, turning bilateral switch ICEOL-D off, allowing the 9 V filtered supply to turn IC601-C on. The output of audio preamplifier IC603-A is then applied to the summing amplifier IC604-A through bilateral switch IC601-C. This signal is amplified and filtered by IC604A,B and HC606, so that only the CG signal (if present) is applied to hard limiter IC604-C. The CG signal is squared up for comparison by the microcomputer to determine if the CG signal is correct. If the microcomputer determines the CG signal to be correct, RX Mute transistor TR713, is turned off, applying +9 VDC to the RX MUTE line to open the receiver.

The Channel Guard Disable(CG DSBL) line has a double function. It can disable the encode or the decode CG function. The encode function is disabled by applying +19 V or more to J701-15. This will turn on TR606 and shunt the Channel Guard tone/code to ground while the decode function is disabled within the microcomputer software. To disable the decoder. ground the CG DSBL line at J701-15. The microcomputer will detect that the line is low, turn off TR713 and force the RX MUTE line high. The decode filter/limiter circuit is not affected, it continues to operate. The detection software also does not stop working. This allows the off-hook STE to function. When the CG DSBL line is pulled high (9.0 VDC) the microcomputer does not sense any changes. It is buffered by protection diode CD709. Channel Guard disable transistor TR606 will turn on when the CG DSBL line goes above 17 V and shorts the output of the filter to ground. This will prevent any signal from going out on CC HI and will also disable the decoder since no limited CG tone will

go to the microgrammeter. The receiver will be noted since no CG is decoded. Disabling the decoder this way will never allow the audio to open up, while taking the radio off hook (pulling CG DSBL low) will always make the radio open up. Turning CG Disable transistor TR606 on causes the PC bias to change. It will take 2 or 3 seconds for the bias to restore itself after the encoder is disabled.

The Squelch Tail Elimination (STE) eliminates squelch tails when the radio is on-hook or off-book. When Changel Guard is disabled (off-hook), the decoder is still looking at the received signal. The RX MUTE line is high, as would normally be expected. The Channel Guard decoder is looking for the STE burst (phase reversal in tone Channel Guard, STE tone in Digital Channel Guard). If an STE burst is detected, the RX MUTE line will go low for about 200 ms. This will prevent the squelch tail from being heard. After 200 ms, the RX MUTE line will go high again; by now the transmission has ended and the squeich will hold the audio closed. The off-hook STE does not affect the operation of the Channel Guard while on-hook. Another way of looking at it: the radio will go quiet for 200 ms any time STE is detected. If it was on-hook it will stay quiet after the 200 ms, if it was off-hook it will revert to noise squelch operation.

In some instances it is necessary to invert the polarity of the digital Channel Guard signal to enhance system compatability. Inverted polarity normally results in a wrong code or one that cannot be used. When this occurs, move P604 connected between J604-1,2 to J604-2,3. The encode DCG codes may be inverted by reprogramming the EEPROM.

PREGUENCY SYNTHESIZER BOARD

The frequency synthesizer receives clock, data, and control information from the microcomputer and from this generates the Tx/Rx RF frequencies. It also provides frequency-lock status to the microcomputer. It consists of synthesizer chip IC201, low- and highcurrent buffers, loop filter, Tx & Rx voltage-controlled oscillators (VCO's), feedback amplifiers, the dual-modulus prescaler, and the reference oscillator. The VCO's are locked to the reference oscillator by a single direct-divide synthesis loop consisting of the feedback buffer, prescaler, and synthesizer. The TX VCO operates over a frequency range of 134.3 MHz to 170.6 MRz. The RX VCO operates over the range of 106.93 to 143.26 MHz.

REFERENCE OSCILLATOR

The reference oscillator consists of a 5 PPM VC-TCXO (Voltage Controlled-Temperature - Compensated Crystal Oscillator). The standard reference oscillator frequency is 13.2 MHz.

The 5 PPM* VC-TCXO receives transmit CG tone from REF MOD CONTROL RV201. RV201 provides the required tone level and phase to modulate the VC-TCXO. The VC-TCXO is enclosed in an RF shielded can. Access to the oscillator trimmer is made through a hole in the top of the can. The VC-TCXO is compensated by an internal temperature-compensator circuit for both low and high temperatures. With no additional compensation the oscillators will provide 5 PPM stability from -30°C to +60°C.

* 2 ppm on some models.

CAUTION

VC-TCXO are individually compensated at the factory and cannot be repaired in the field. Any attempt to repair or change the frequency of a VC-TCXO will void the warranty.

SYNTHESIZER

Synthesizer IC201 contains a programmable reference oscillator divider (:R), phase detector, and programmable VCO dividers (:N, A). The reference frequency, 13.2 MHz from the reference oscillator is divided by a fixed integer number to obtain a 4.16 kHz channel reference for the synthesizer. This divide value can be changed by PROM programming. The internal phase detector compares the output of the reference divider with the output of the internal :N, A counter. The :N, A counter receives as its input the VCO frequency divided by the dual-modulus prescaler and programmed by the microcomputer. This comparison results in a + error voltage when the phases differ and a constant output voltage when the phase-detector inputs compare in frequency and phase.

If a phase error is detected an error voltage is developed and applied to the VCO DC offset and high current buffers and loop-filter to reset the VCO frequency. The count of the :N, A counters is controlled by the frequency data received on the clock and data lines from the microcomputer. Thus, when a different channel is selected or when changing to the transmit or receive mode an error voltage is generated and appears at the phase-detector output, ADP OBT causing the phase-locked loop to acquire the new frequency.

The enable pulse from the microcomputer enables the synthesizer and allows frequency data to be internally stored.

DC OFFSET AND HICH CURRENT BUFFERS

DC-offset buffer TR201 and diode CD201 receive the error voltage from the synthesizer and increase this level by 1.8 VDC to extend the operating range of the high-current buffers. When the PLL is off-frequency due to a channel change or frequency drift, the error voltage from the synthesizer(APD) rises or falls, turning either TR202 or TR203 on. These two transitions control high-current buffers TR204 and TR205. TR204 and TR205 complete a high-current rapid-charge or -discharge path for C207-C209.

If the error voltage decreases, TR203 is turned off and TR205 is turned on, completing a discharge path for C207-C209 through bilateral switches IC204. At the same time TR202 is turned on and TR204 is turned off, blocking the charge path. The opposite conditions exist when the error voltage goes positive. IC204 is turned on for 4 milliseconds when a channel is changed in the receive mode. The time is 20 milliseconds when in transmit mode and when changing form transmit to receive mode.

LOOP FILTER

The loop-filter consists of R209-R211, and C207-209. This filter controls the bandwidth and stability of the synthesizer loop. Bilateral switch IC204 is controlled by the 4 millisecond, 9 volt channel-change pulse. When the channel-change pulse is present, the bilateral switch shorts out the low-pass filter, greatly increasing the loop bandwidth to achieve the 4 millisecond channel-acquisition time required for dual-priority scan. The low-pass filter removes noise and other extraneous signals internal to the synthesizer chip.

The output of the filter is applied to the varicaps in the transmit and receive VCO's to adjust and maintain the VCO frequency.

The use of two VCO's allows rapid independent selection of transmit and receive frequencies across the frequency split.

RECEIVER VOLTAGE CONTROLLED OSCILLATOR

The receiver VOO consists of a low-noise JPET oscillator, TR213, followed by high-gain buffer TR211. TR211 prevents external loading and provides power gain. The VOO is a Colpitts oscillator with the various varactors, capacitors and coil forming the tank circuit.

The VCO is switched on and off under control of the DPTT line. When the DPTT line is low the Receiver VCO is turned on (TR213 is off, TR212 is on). Oscillator output is typically .10 dBm. The output is applied to the feedback buffers for VCO frequency control and as the Rx injection frequency to the receiver lst mixer through L.O. buffers Th404. Th405 on the RX board. The Rx VCO also uses a high-Q resonator coil to achieve superior noise performance. The VCC operates over a frequency range of 106.93-143.26MHz. The VCO voltage need only be set once at the highest frequency of the band split, after which it will operate over the entire split with no more tuning.

TRABSMITTER VOLTAGE CONTROLLED OSCILLATOR

The transmit VCO is basically the same as the receiver VCO. The wideband VCO allows frequency separation of 12 MHz, 10 MHz or 14 MHz as determined by the bandsplit the radio is operating on, 403-440 MHz, 440-470 MHz or 470-512 MHz. The varactors in condjunction with the frequency segment selector circuitry (TR216-TR219, TR227, TR228, TR230 and pin diodes CD217, CD218 and CD221) provide a voltage-controlled adjustment range that extends across the entire frequency split. Buffer TR221 provides a typical output of +10 dBm to the feedback buffers for VCO frequency control and as the Tx Injection frequency to the exciter.

VCO control switch TR222 turns the Transmit VCO on when DPTT is high.

PEEDBACK BUFFERS

The Rx injection and Tx injection voltage output from the Rx VCO and Tx VCO are supplied to the receiver mixer and the exciter, respectively, and to the feedback buffers. Buffering is provided by TR207 and TR206 and the output applied to dual-modulus prescaler IC202.

DUAL-MODULUS PRESCALER

dust-modulus prescaler completes the PLL feedback path from the synthesizer to loop-filter, to the VCO's and feedback buffers and then back to the synthesizer through the prescaler. The prescaler divides the VCO frequency by 64 or 65 under control of M CONT from the synthesizer. The output of the prescaler is applied to the synthesizer where it is divided down to 6.16 kHz by an internal : N. A counter and compared in frequency and phase with the divided-down frequency from the reference oscillator. The result of this comparison is the error voltage used to maintain frequency lock. The N. A counter is controlled by data received from microcomputer. Depending on the operating frequency, the DC voltage at TP201 should be within the range 3.5 to 7.5 VDC When the PLL is locked.

LOCK DETECT

The lock-detect circuit consists of comparator IC203, diodes CD203 and CD204, and reference oscillator mute switch TR208, and TR209. It is used to quickly synchronize the phase relation of the divided-down VCO frequency and the reference oscillator if the loop loses lock. It also provides a fast lock-detect signal to the microcomputer to turn on the out-of-lock indicator. If a large change in frequency is required, the ramp capacitor output

(C_R) of the synthesizer may increase to near 7.5 VDC and cause the comparator output to decrease. This decrease in voltage turns TR209 off and allows TR208 to be turned on by the positive LD line from the synthesizer. Thus TR208 disables the reference oscillator and allows the PLL loop to be brought back to synchronization rapidly.

If a large frequency error exists, the LD positive lead from the synthesizer will carry negative spikes to the microcomputer through CD204 to activate the lock indicator circuit. Pulse shaper IC701 is a one-shot multivibrator which increases the pulse width to span 1 computer cycle. TR209 is turned on, keeping TR208 off thereby preventing TR208 from muting the reference oscillator.

MODULATION LEVEL CONTROL

The modulation level control circuit automatically sets the Tx audio level applied to the transmit VCO modulator CD212 through VCO deviation edjust control RV202. modulation level control circuit consists of IC205, R274-R276, R278, varactor CD212, C245 and bypass capacitors C247 and C248. The modulation level is controlled by turning bilateral switches IC205 on or off (under control of IC705) to include attenuators R275 and R276 in the circuit. R274, R275 and R276 form an adjustable voltage divider to change the modulation level as required. Table I also identifies the resistor (if applicable) used for each frequency segment.

FREQUENCY-SEGMENT SELECTOR

The frequency-segment selector switches capacitance in and out of the Tx and Rx VCO tank circuits to select the frequency segment containing the selected channel. The frequency-segment selector consists of TR216-TR219, TR227, TR228, TR230, CD209, CD210, CD217, CD218, CD220 and

CD221 and operates under control of the microcomputer through FF's IC705A & B. Capacitors (C224, C227, C252, C255, C291 and C294) are selected or deselected for operation in a given segment. Table 4 identifies the circuit conditions existing for selection of each segment and the capacitors used.

Reverse bias to turn off the pin-diodes is provided by the +8V filtered supply through R232, R234 and R28b. Forward bias for the diodes and current for the switching transistors are provided by the +8V supply through R231, R233 and R285. When segment 3 is selected TR216, TR219 and TR277 are turned on. In the Tx VCO diodes CD217 and CD221 are reverse biased and CD218 is turned on. Capacitors C251 and C293 are effectively isolated from AC ground by L218 and L225 respectively and C254 is connected to ground via CD218 and Tx219.

Similarly in the Rx VCO C223 and C290 are isolated from ground, and C226 is grounded via CD210 and TR219.

Operation of the radio over the frequency ranges 403-440 MHz, 440-470 MHz or 470-512 MHz is determined by the group number of the synthesizer board. Each frequency split is divided into four operating segments varying from 7 MHz to 11 MHz wide.

SECHENT TR216 TR217 TR218 TR219 TR227 TR228 TR230 CD209 CD210 CD217 CD218 CD220 CD221 CAPACITORS			23	54 54	
		ALL.	C223 C251	C226 C254	NONE
	CD 221	NO	OPF	440	OFF
	CD 220	NO	OPP	ON OPP	OFF
LOES	CD218	NO	990 990	NO	088
PIN DIOES	CD217	NO	NO	OFF	OPP
	CD210	NO	ON OPP	NO	OPP
	cp209	NO	NO	OFF	OPP
	TR 230	1	0	0	0
١	TR 228	τ	0	0	0
TRANSISTOR SWITCH*	TR 227	0	1	1	1
STOR	TR219	٦	0	٦	1 0 1
TRANS	TR218	0	۲	0	1
	TR 217	1	1	0	0
	TR216	0	0	٦	т
	SECMENT	1	2	m	7

' 1' indicates translator is turned on.

EXCITER BOARD

The Exciter consists of four wide-band amplifier stages and a tripler stage, and operates over a frequency range of 403-512 MHz without any tuning. An attenuator pad (R101-R103) at the input of the Exciter provides a constant load for the VCO and attenuates the signal from the VCO to approximately 1 millimatt.

The Exciter amplifies the 1 milliwatt signal from the VCO to provide 250 milliwatts drive to the power amplifier.

In addition to tripling the input signal and providing approximately 24 :B gain, the exciter contains the filter circuits that determine the bandwidth and spurious response characteristics of the translitter.

The 134-171 MHz TX injection input from the TX VOO is applied to the base of amplifier TR101 through attenuator pad and C101. Collector voltage is supplied through L101 and R106. C103 matches the output of AMPL1 to TRIPLER.

The 8 to 10 milliwart output of TR101 is coupled to the base of tripler TR102. C105 and L102 bypass the tripler signal at the input of TR102, and C106 and L104 bypass the input signal at the output of TR102. This improves the efficiency of tripler. The 8 to 10 milliwart output from this stage is coupled through band-pass filter FL101 to AMPL2 input.

AMPL2 consists of class-A amplifier TR103. The 30 to 50 milliwatt output of this stage is coupled through Cl12 to the band-pass filter FL102.

Following the band-pass filter FL102 are class-A and class-B amplifiers. TR104 and TR105 respectively. The 300 milliwatt output of TR105 is coupled through impedance matching network C123 and L109 to the band-pass filter FL103 which provide the final selectivity in the exciter.

The output of band-pass filter FL103 is applied through coaxial connector J102 to the power amplifier board.

A+, supplied from the frequency Synthesizer board is stabilized to 9V by IC101 (3-terminal regulator), and +9V is applied to TR101-TR105 via TR106.

In the transmit mode, TX EMB is low, providing a path to ground for base current through TR106, which turns on. 9V from the regulator IC101 is then applied to the exciter.

- Service Note

The output RF level can be measured by connecting a 50 ohm dummy load to J102 and feeding a 0 dBm signal to J101 (134-171 MBz) and grounding the TX ENB line.

The Exciter is energized by pressing the PTT switch.

Regulated 9 volts is present on all exciter stages when the transmitter is turned on.

PA BOARD 80/100 WATT POWER AMPLIFIER

The 250mW RF output from the exciter is applied to the PA input connector J1. It then passes through an attenuator consisting of resistors R1-R3, to the power module HC1. This unit consists of 3 class-C amplifiers to provide an output of 10 W. The first stage of the power module derives its collector voltage from the power control circuit.

The 10 W output of the power module drives amplifier TR1 via impedance-matching components C1, C6, C7 and stripline Z1. The low output impedance of TR1 is transformed to 50 ohms at the output end of C18 by C10-C14, C16, C18 and stripline Z2. L1 and L2 are the DC return and stabilizing network in the base of TR1.

The output of TRI is coupled to a Wilkinson power splitter consisting of microstrip 213.

The power amplifier stages consist of two identical paralleled class C power amplifiers (TR2, TR3). L3 and R34 are the DC return and stabilizing network in the base of TR2, while L5 and R35 make up the network in the base of TR3. Supply voltage (A+) for TR2 and TR3 coupled through collector feed network L17, L18, L19 and L20.

The output of TR2 and TR3 is applied to a Wilkinson power combiner (214).

The output of the combiner passes through the directional coupler. The rectified signals produced by CD1 and CD2 provide a measure of the forward and reflected power levels respectively.

After passing through the directional coupler the output is coupled to the low-pass filter consisting of L8-L10 and C62-C68 through antenna relay K1. In the RX mode, signals from the antenna are coupled via K1 the low-pass filter consisting of L11, L12 and C70-C73. CD3-CD6 provide receiver input protection against strong signals at the autenna connector in the receive mode.

30/35 W POWER AMPLIFIER

The circuit of the 30/35 W PA is the same as 80/100 W unit, except that the 50 ohm output of TR1 is fed directly to the directional coupler, and TR2 and TR3 are not used.

POWER CONTROL CIRCUIT

The power control circuit provides power leveling as well as thermal protection for the PA.

When the transmitter is keyed, RF is rectified by CD1. The resulting DC turns on RF switch TR4-TR7. Turning on TR5 applies collector voltage to the

lst RF driver transistor in the PA module.

If the power output should start to increase above the level set b. RVI. TR5 will start to conduct. This causes TR7 to conduct less, reducing the collector voltage of TR5 to the lst RF driver transistor in the PA module.

Thermal protection is provided by temperature compensating resistor R27.

When the heat sink temperature rises above 90 °C, the resistance of R27 increases and the power output is reduced to 60 W-

CAUTION

Do not operate the transmitter at levels higher than rated output. Operating at higher than rated output will shorten the life of the RF power transsistor.

RECEIVER BOARD

The FM dual-conversion, superhetrerodyne receiver is designed for operation in the 403-512 MHz frequency ranges. A regulated 9.0 volts is provided to all receiver stages except the audio PA IC, which operates from the switched A+ supply.

The receiver has intermediate frequencies of 82.2 MHz and 455 kHz. Adjacent channel selectivity is obtained by using two band-pass filters: a 82.2 MHz crystal filter and a 455 kHz ceramic filter.

All of the receiver circuitry except the synthesizer, audio preamp, audio PA, and squelch circuit is mounted on the Rx board. The receiver consists of:

- Front and Mixer
- 82.2 MHz 1st IF, 455 kHz 2nd IF and FM Detctor
- Audio PA
- Squelch

RECEIVER FRONT END

An RF signal from the antenna is coupled through the low pass filter, antenna relay, and band-pass filter (FL401) to the input of RF amplifier TR401. The output of TR401 is coupled through band-pass filter (FL402) and band-pass filter (FL403) to the input of 1st mixer BC401. Front-end selectivity is provided by these band-pass filter.

RECEIVER INJECTION

Receiver RF injection (320.8-429.8 MHz) from the synthesizer VCO is applied to amplifier TR402 through J402. The input level at J402 will be between 1.0 and 2.0 milliwatts, 1.0 milliwatts minimum. The output of amplifier TR402 is coupled to the input of amplifier TR403 is filtered by a bandpass filter (FL404). This filter is tuned to pass frequencies in the 320.8-429.8 MHz passband.

Lst MIXER

The first mixer is a double-balanced diode mixer (HC401) that converts a signal in 403-512 MHz range to the 82.2 MHz first IF frequency.

In the mixer stage, RF from the front-end RF filter is applied to one input of the mixer. Injection voltage from the amplifier stages is applied to the other input of the mixer. The 82.2 MHz 1st IF output signal is coupled from the output of HC401 through C501 to the source input of IF AMPL TR501/504. TR501/504 are a JFET amplifier/buffer stage. The output of the JFET buffer is coupled through C504 to a 4-pole XTAL band-pass filter (FL501).

1st IF

The highly-selective crystal filters FL501-1 and FL501-2 provide the first portion of the receiver IF selectivity. The output of the filters is coupled through impedance matching network L506, C507 and C508 to the lst IF amplifier TR503.

The crystal filter output of FL501 is applied to the base of the 1st IF amplifier TR503, and the amplified signal is taken from the collector. The amplifier provides approximately 20 dB of IF gain. The output is coupled through an impedance matching network, L507, C510 and R507 that matches the amplifier output to the input of FL502. The output of the filter is coupled through impedance-matching network L508, C511 and R508 to the 2nd mixer HC501.

2nd MIXER

HC501 and associated circuitry comprise the 2nd oscillator and 2nd mixer.

The 82.2 MHz IF input is applied to pin 7 and mixed with an 82.655 MHz frequency supplied by crystal oscillator X501. L509 sets the frequency of X501.

2nd IF AND DETECTOR

The output of the 2nd mixer is coupled to the 4-pole ceramic filter, which provides the 455 kHz selectivity. The output of the ceramic filter is coupled to the base of TR504. The transistor provides limiting for the 455 kHz IF signal (1.4Vp-p) to prevent high level overloading of ICS01.

IC501 and associated circuitry function as the IF amplifier and FM detector.

The 455 kHz IF input is applied to $pin\ 18$.

The IF signal is amplified and applied to a 4-pole ceramic filter PL504 which provides the 455 kHz selectivity. The output of the 455 kHz filter is applied to IC501-5. The 2nd IF signal is amplified and limited. L511 shifts the IF signal by 90° and applies it to the internal FM detector. The FM detector compares the shifted IF signal to the internal IF signal to recover the audio modulation. The audio output of IC501 is applied to the system control unit via the level control, EV501.

GE Mobile Communications

TABLE OF CONTENTS

BLOCK DIAGRAM	D2-D6
DRAWINGS	D7-D19
PRINTED CIRCUIT BOARD LAYOUT	D21-D32
HYBRID CIRCUIT	D33-D34
PARTS LIST	D35-D53

DRAWING SHEET No.

A603 : FREQUENCY SYNTHESIZER BOARD

A604 : RECEIVER BOARD
A605 : EXCITER BOARD

A606 : POWER AMPLIFIER BOARD

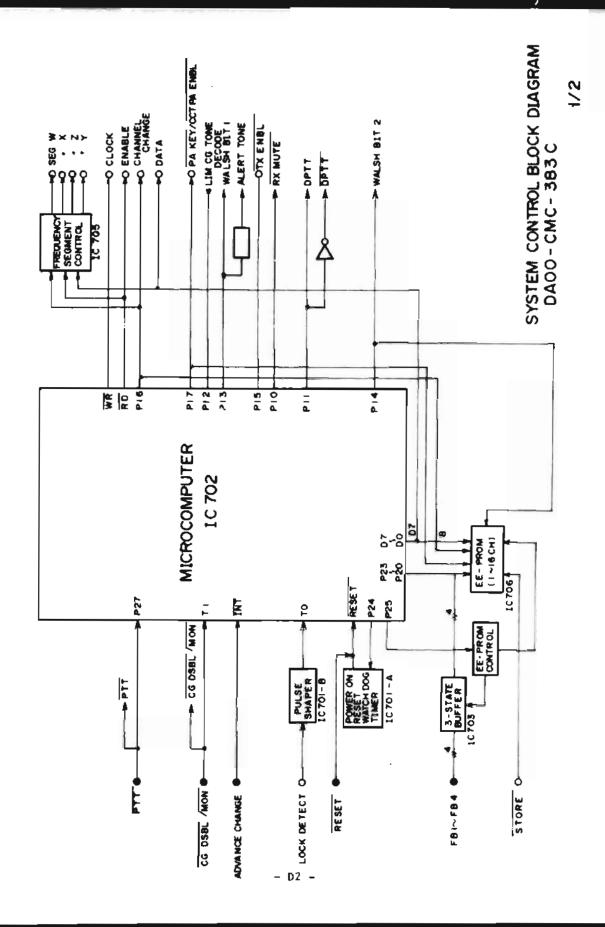
 A601 (INTERFACE: CFQ-2223) and A602 (SYSTEM CONTROL: CMC-383C) do not change in the table below.

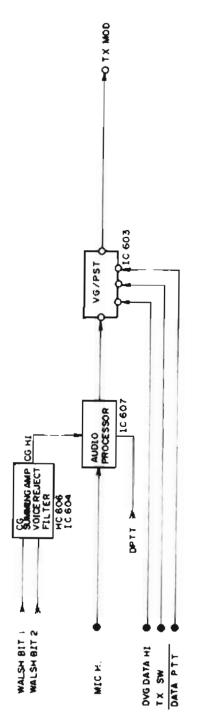
DRAWING SHEET No.

TYPE PC BOARD	35 A (403-423MK2 35W)	FOOA	35B (410-430MHZ, 35W)		35 C (420-440MrZ 35W)	100C 1420-440MZ.100W		
A603		CMG-132A						
M604	CMA-239A		CMA	-239B	CMA	-239C		
4605	605 CAF-256A							
M606	CAH-256L	CAH-256H	CAH-256L	CAH-266H	CAN-256L	CAH-256H		

TYPE PC BOARD	3 5 D (440-460MZ, 35W)	1000 (440-460M/Z (00W)	35 E (450-470M2, 35W)	100 E (450-470MZ, 100W
4003		CMG-13	28	
4604	CMA-	-2390	CMA	-239E
A400		CAF-25	6 B	100
4606	CAH-256L	CAH-256H	CAH-256L	CAH-256H

TYPE PC BOARD	3 O F (470 -488M/Z.30W)	8 OF (470-46660Z, 60W)			30H 1486-512MZ 30WI	80 H (488 - 512MeZ , 8097)
A603		84/00VC	CMG-13	20		
M604	CMA	-239F		-239 G	CMA	-239H
A906			CAF-25	6C		
A806	CAH-256L	CAH-256H	CAH-256L	CAH-256H	CAH-256L	CAH-256H





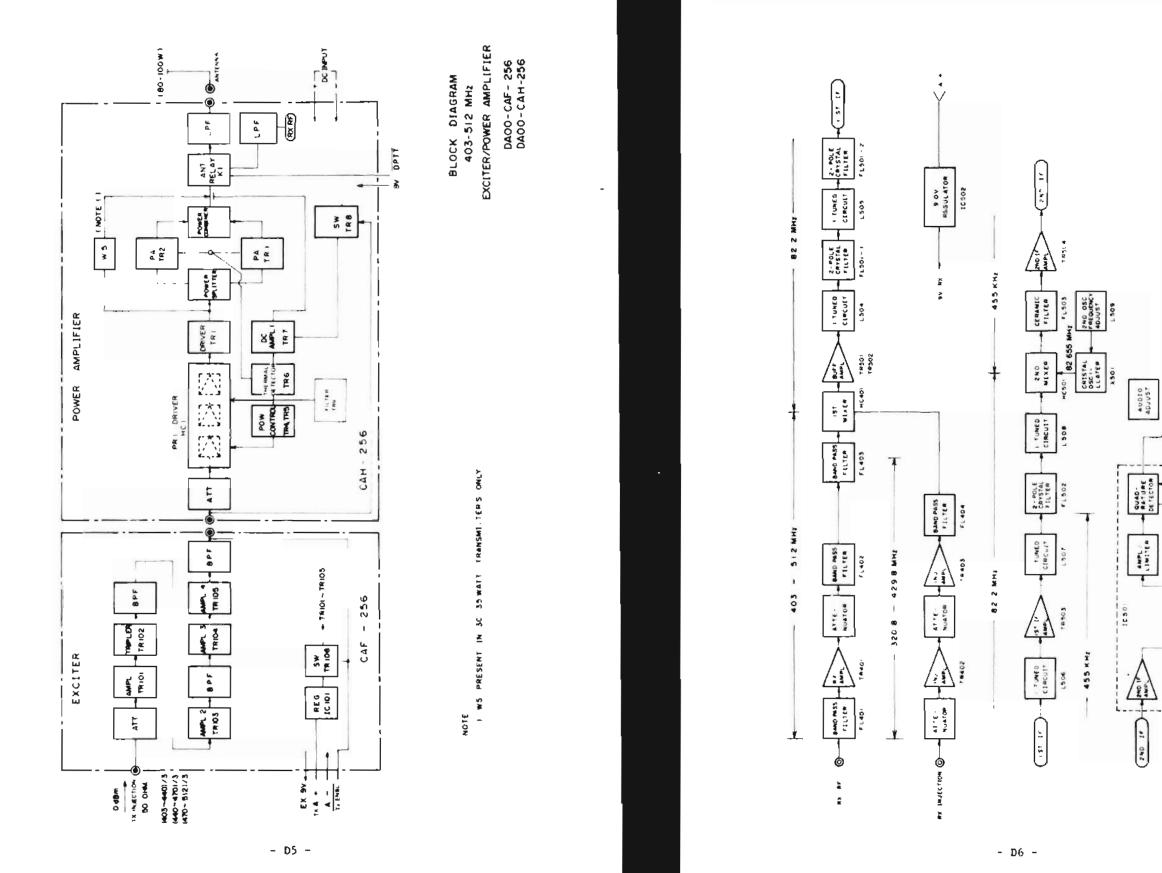
SYSTEM CONTROL BLOCK DIAGRAM DA00-CMC-383C

2/2

BLOCK DIAGRAM 403-440 MHz 440-470 MHz 470-512 MHz FREQUENCY SYNTHESIZER DAOO-CMG-132 Rx INJECTION (FRL) THAN SC BIT TO 301 THAN SC BET BE BIT THAN SECONT - SE BEST 8 146 8 156 6 MHz 2 146 6 156 6 MHz C 156 6 - 106 MHz #1, VCO, #1, VCO, TR 210 Ta/A; Switch TAP12,7823 COSTI TREM. THE ACTOR TREES, THE ACTOR TO CORREST, THE ACTOR TO CORREST, THE ACTOR TO CORREST, CORR 503-640 401-537 0-63 3164 DUAL MODULU PRESCALER CONTROL CONTROL 10202 VOLTAGE COMMENTOR IC POS LOCK 0 f T De T 4,8 TNTMESE ZEP MEF OSC MUYE FRZOS, TREOS CHARL! LOOK MITTER #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #05150 #0 CHAMBEL

- D4 -

- D3 -

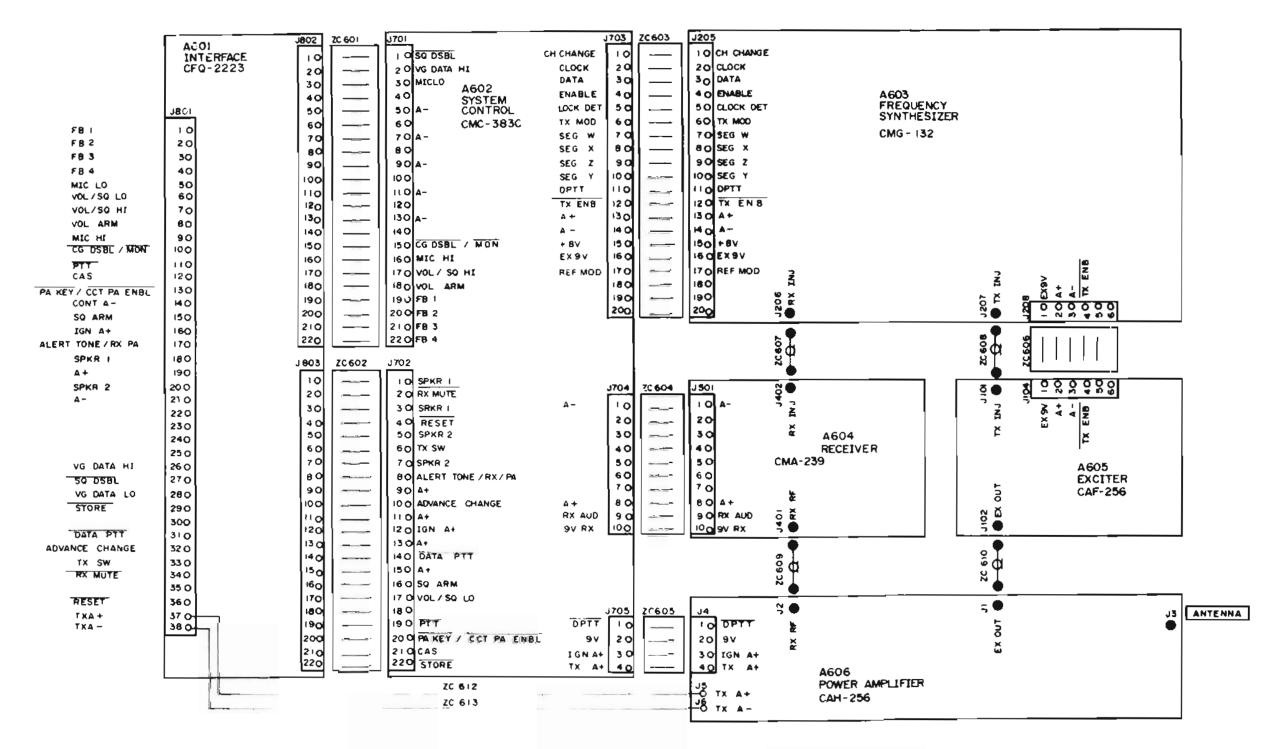


403-512 MHz RECEIVER DA00-CMA-239

BLOCK DIAGRAM

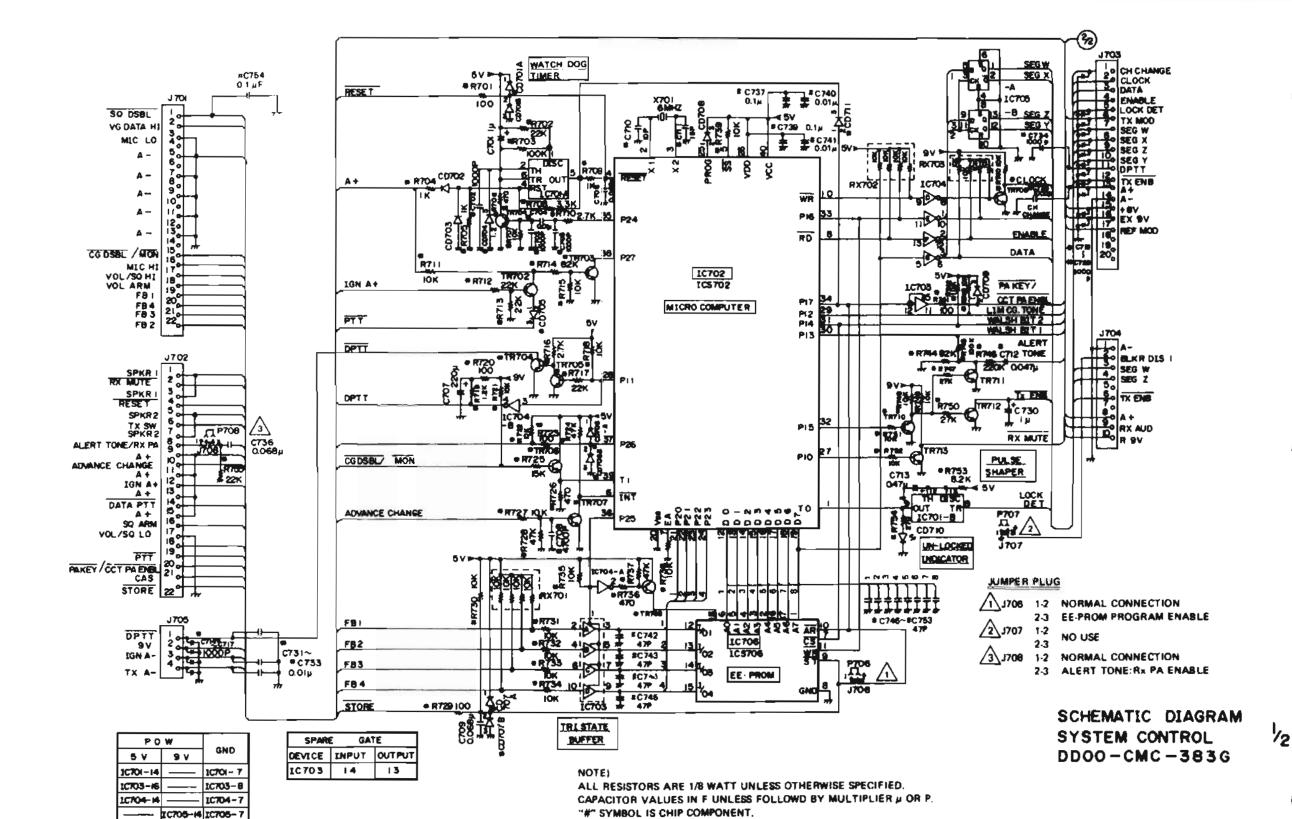
SHIFT SHIFT NETWORK

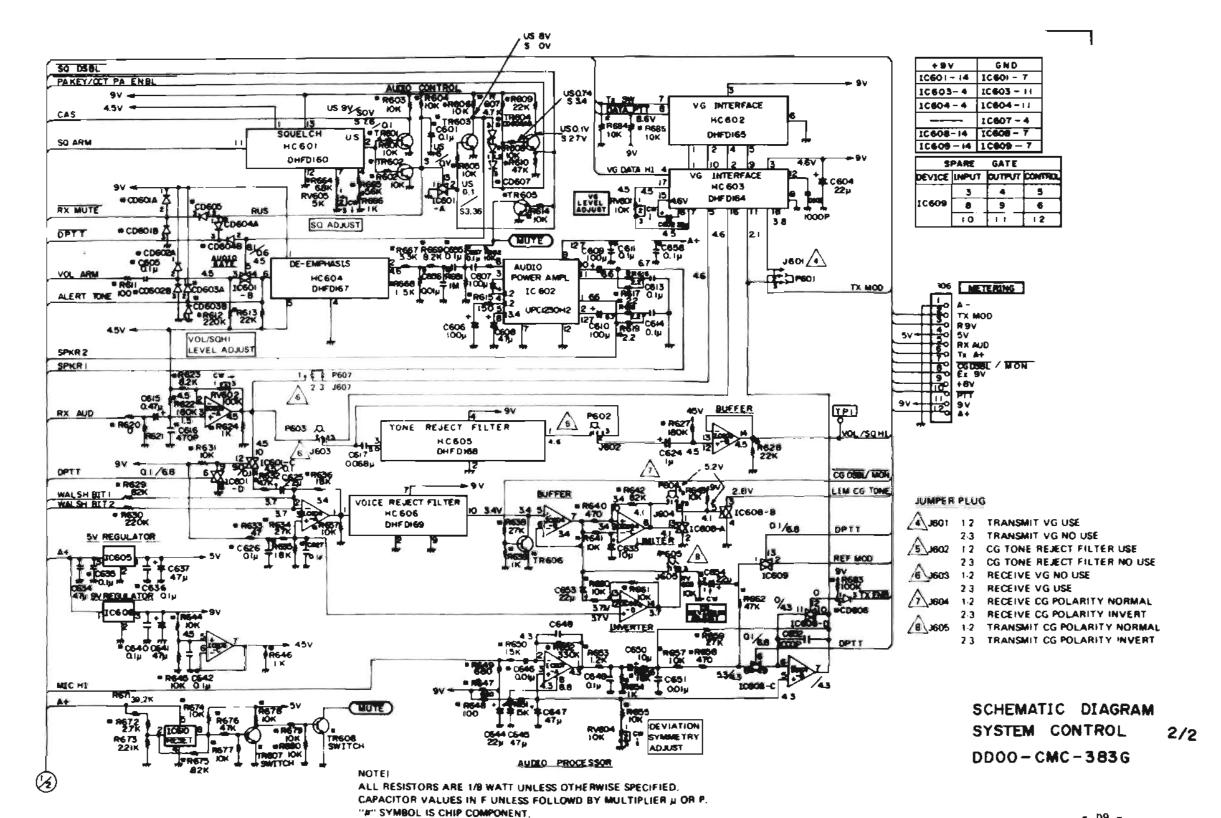
CENSMIT CENTER

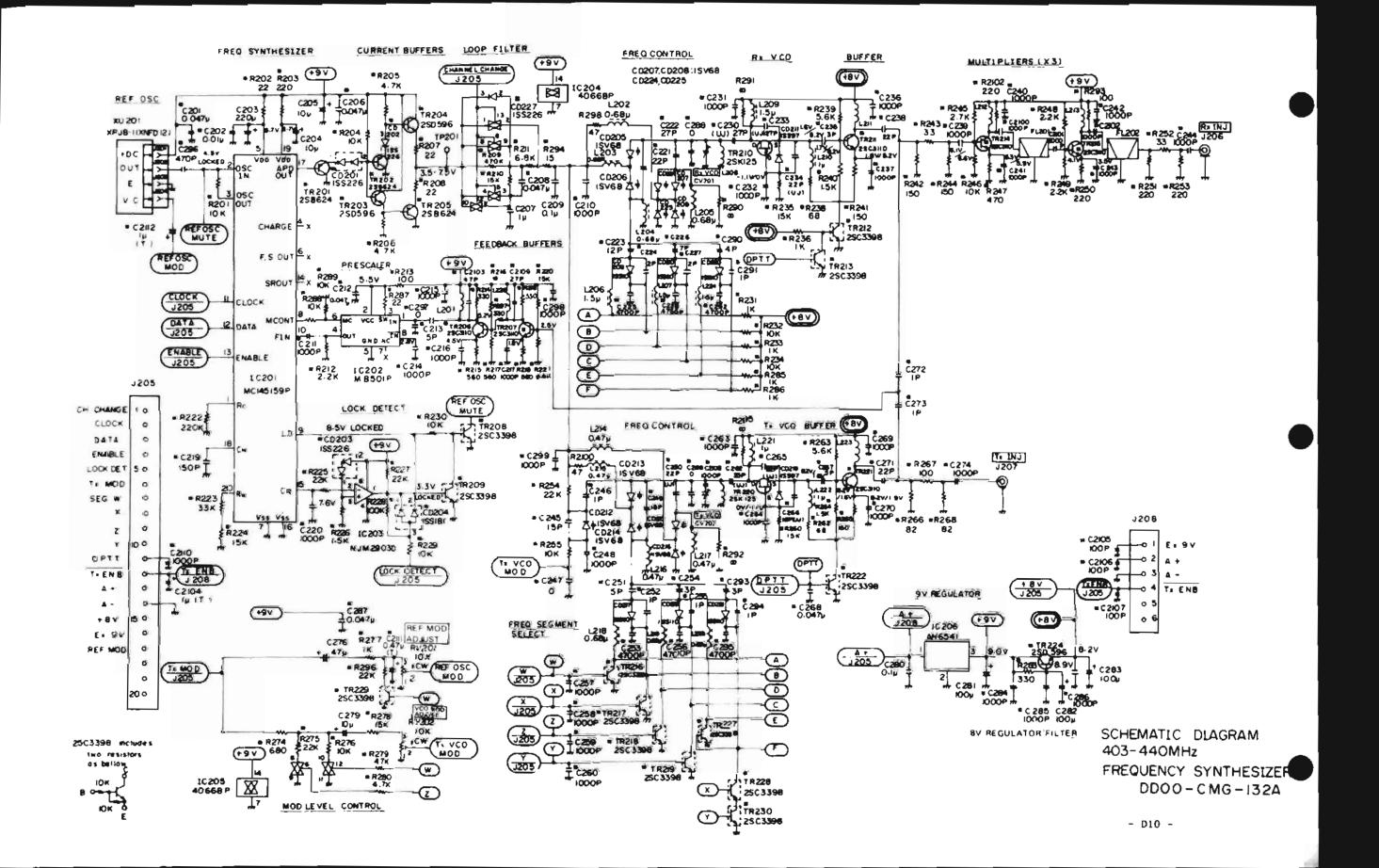


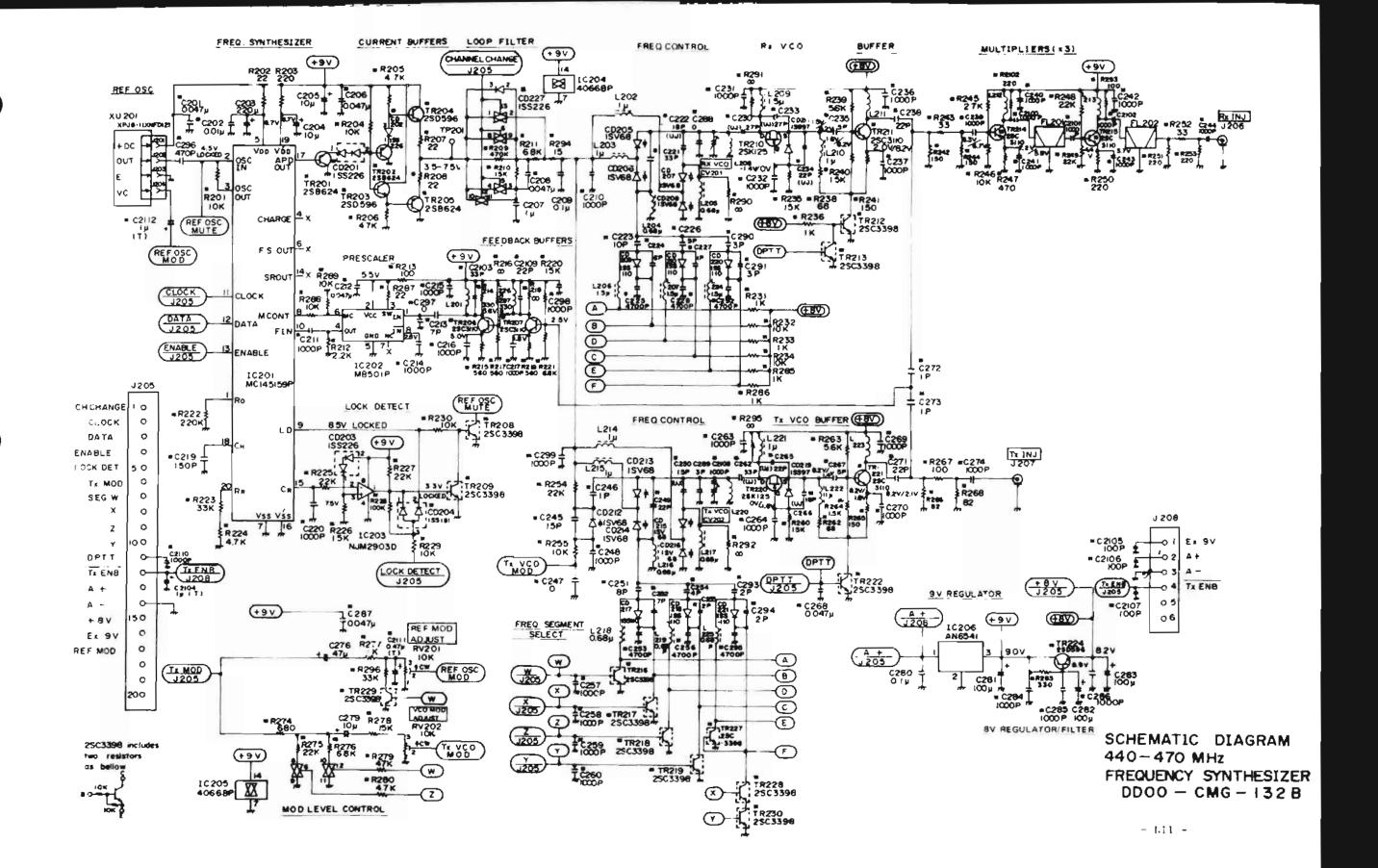
TYPE JHM 45:15	35A	1004	358	1008	35C	100C	354	WOOD:	35E	100E	30F	80F	30G	80G	304	80H
FREQUENCY (MHZ)	403-42	23	410⊸	130	470-	440	440 -	460	450	470	670	-488	482	-500	488	612
A603 SYNTHESIZER	•		CMG 1	32A				CMG	_137B				CMG	-132C		
4606 POWER AMPLIFIER	CAH 256AL C	AH-256AH	CAH 256AL	CAH-256AH	CAH-256AL	CAH 256AH	CAH 2568L	САН-256ВН	CAH 256BL	CAH 2568H	CAH 256CL	CAH-256CH	CAH-256CL	CAH 256CH	CAH-256CL	CAH 266CH
A604 RECEIVER	CMA-23	9A	CMA 2	398	CMA	2.39C	CMA-Z	390	CMA	239E	CMA	239F	CMA	2396	CMA	2394
A605 EXCITER			CAF-2	56A				CAF	266B	-	T.		CAF	-256C		

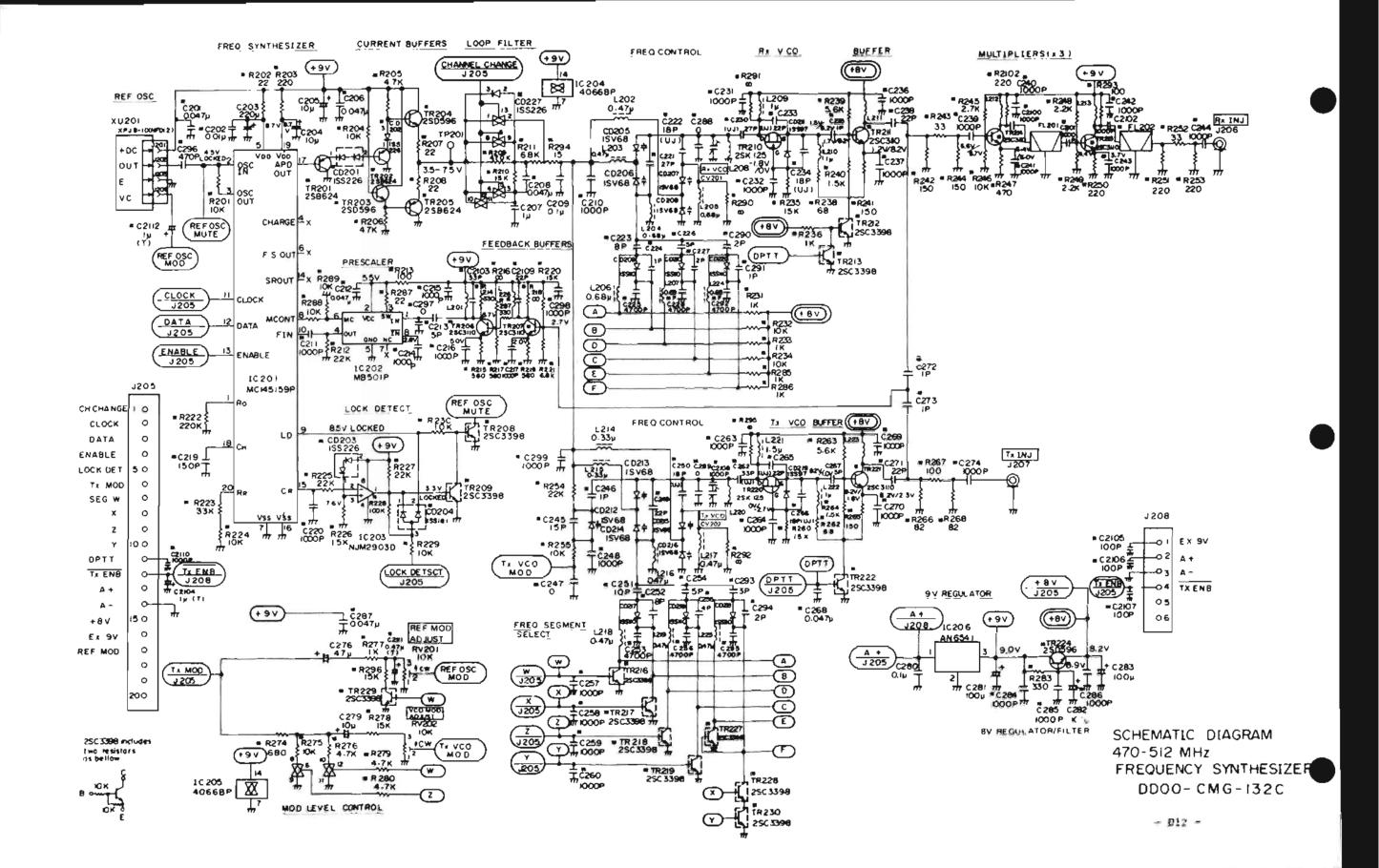
SCHEMATIC DIAGRAM INTERCONNECTION DDOO-JHM-451S

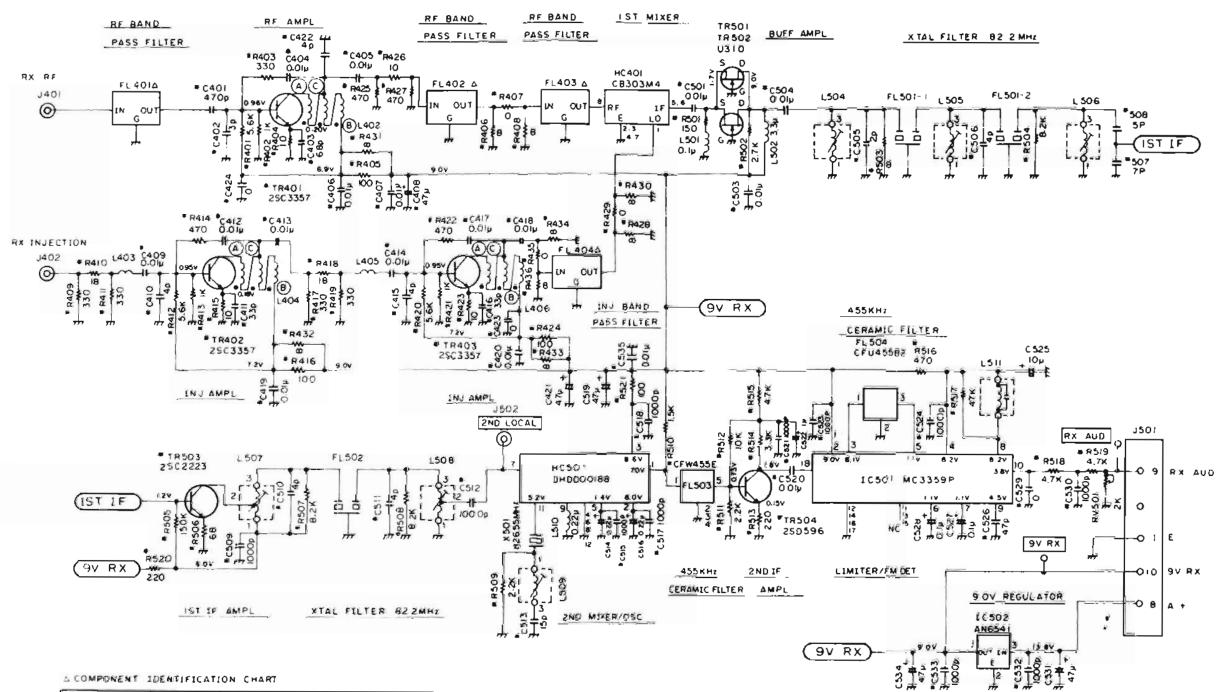












PWS	8	AND	FL401-403	FL402	F L404
CMA - 2394	4	Band	BP403-423A2	8P403-423AI	BP320-358A2
CMA - 2398	8	Band	BP410-430A2	8P410-430AI	BP320-358A2
CMA - 2390	C	Band	BP420-44042	8P420-44041	89 320-358 #2
CMA - 2590	D	Band	BP44:0 -46062	BP440-460A1	SP357-386A2
CMA- 2398	E	Band	8P450 - 470AZ	82450-470AI	8P357-388A2
CMA - 239F	F	Bang	8P470 - 488A2	8P470-488A1	8P384-43042
CMA - 239G	G	Bonsi	8P482-500A2	8P482-500AI	BP394-430A2
CMA- 239H	н	Bond	BP488 5/2A2	gr-488-512A1	8F394-45042

90166

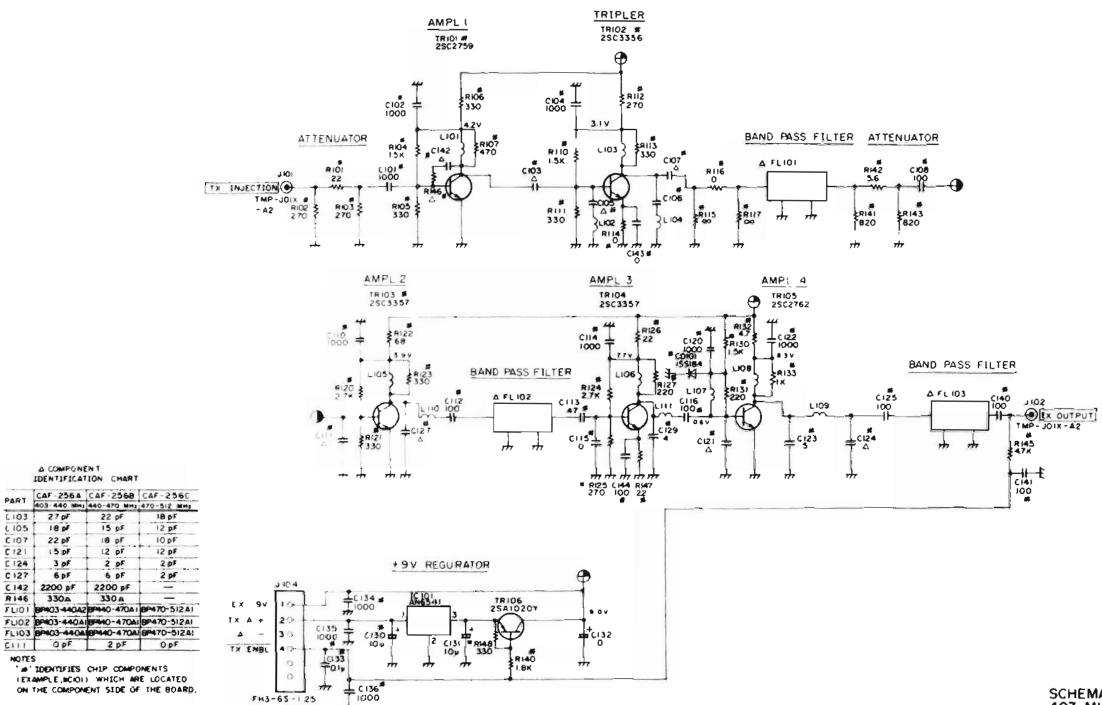
WILLIAM THE LOCATED ON SOLDER SIDE OF PWE.

ALL MESISTORS ARE 1/8 WATT UNLESS OTHERWISE SPECIFIED

MESISTOR VALUES IN D. UNLESS FOLLOWED BY MULTIPLIER K OR M
CAPACITOR VALUES IN P. UNLESS FOLLOWED BY MULTIPLIER K. A OR N

INDUCTANCE INCUES IN P. SWILESS FIRELOWED BY MULTIPLIER M. OR N

SCHEMATIC DIAGRAM 403-512MHz RECEIVER DD00-CMA-239



ALL RESISTORS ARE 1/8 WATT UNLESS OTHERWISE SPECIFIED. RESISTOR VALUES IN A UNLESS FOLLOWED BY MULTIPLIER K OR M. CAPACITOR VALUES IN PETUNLESS FOLLOWED BY MULTIPLIER H. M. INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER IN OR ..

-DSA - 161

A COMPONENT

27 pF

18 pF

22 pF

15 pF

3 pr

6 pF

2200 pF

330A

OpF

PART C 103

C 105

C107

C 121

C 124

C127

C142

R146

11113

IDENTIFICATION CHART

15 pF

18 pF

12 pr

2 pF

6 pF

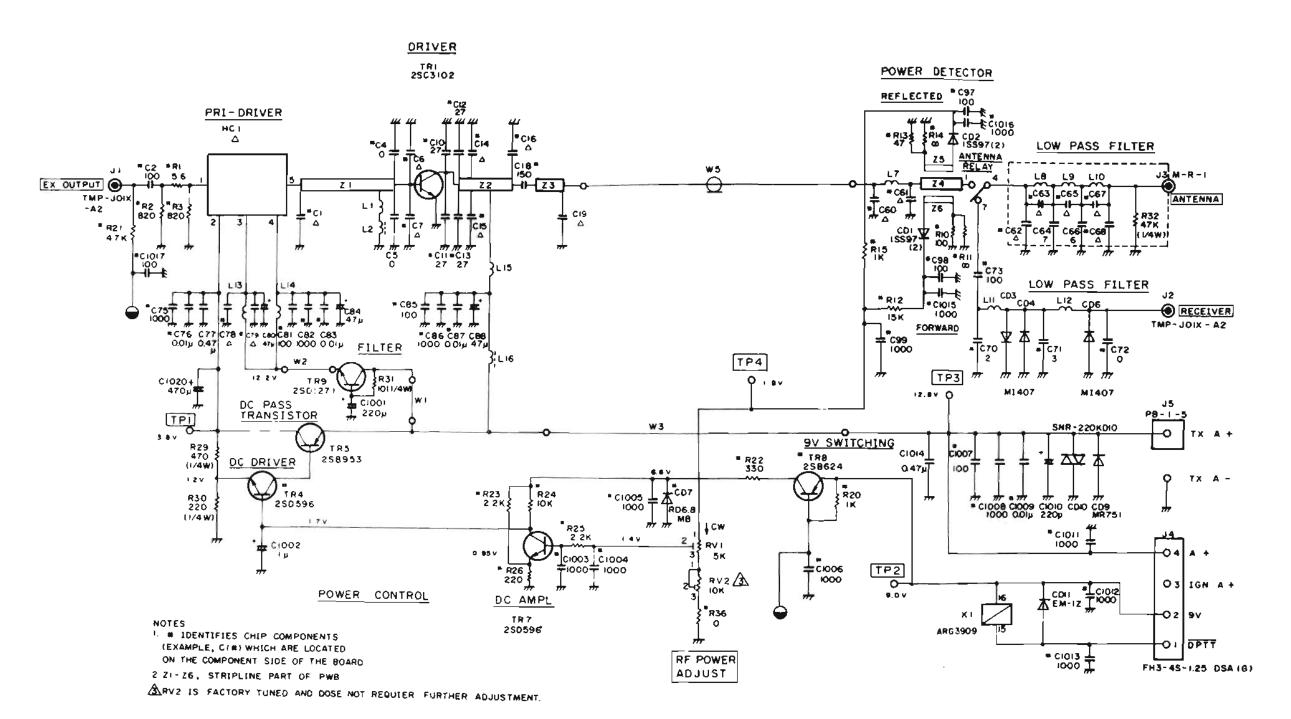
2200 pF

330 a

2 pF

" " TOENTIFIES CHIP COMPONENTS

SCHEMATIC DIAGRAM 403 MHz - 512 MHz **EXCITER** DD00-CAF-256

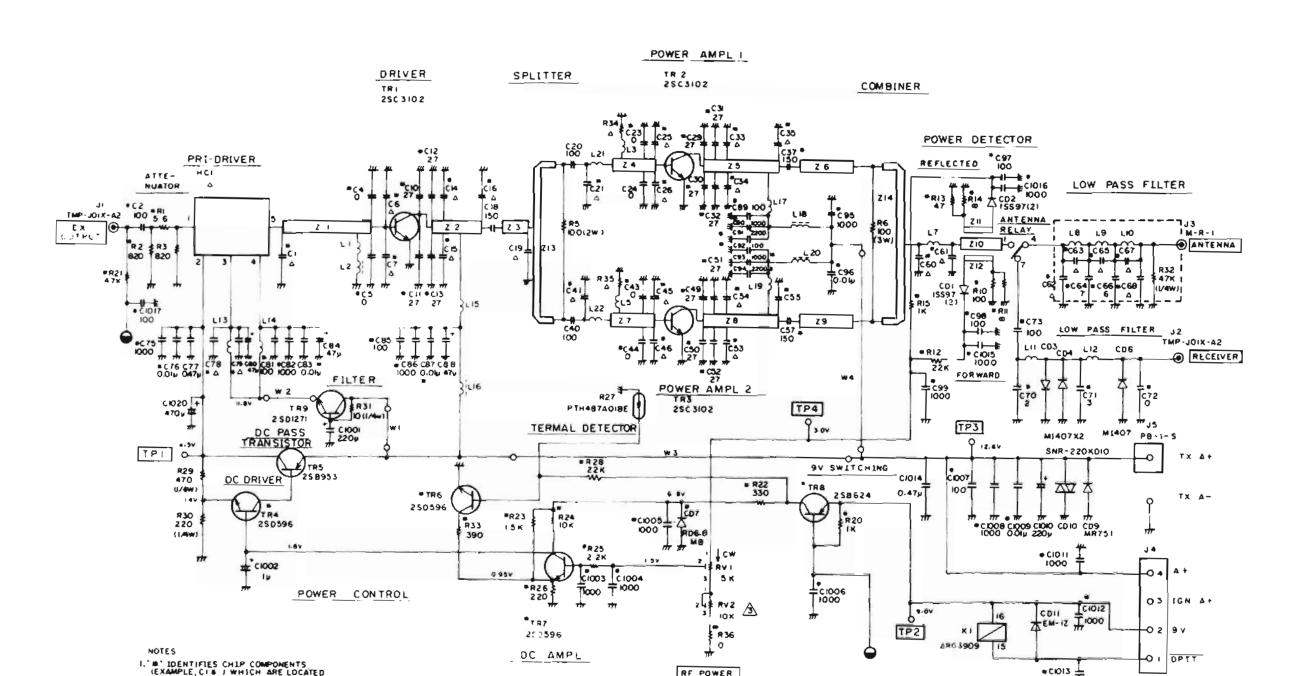


ALL RESISTORS ARE I/B WATT UNLESS OTHERWISE SPECIFIED.
RESISTOR VALUES IN 1 UNLESS FOLLOWED BY MULTIPLIER K OR M.
CAPACITOR VALUES IN PF UNLESS FOLLOWED BY MULTIPLIER M, N.
INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER M, OR M.

SCHEMATIC DIAGRAM 403 MHz - 512 MHz POWER AMPLIFIRE DD00 - CAH - 256L

... COMPONENT IDENTIFICATION CHART

	CAH-256AL	CAH-256BL	CAH-256CL	
PART	403 ~ 440MHz (35W)	440 ∿470MHz (35W)	470 ∿ 512MHz (30W)	
# C1	10P	10P	8P	
# C6	47P	39P	30P	
# C7	47P	39P	30P	
# C14	15P	15P	10P	
# C15	15P		-	
# C16	12P	14P	10P	
C19	3P	3P	-	
# C60	3P	2P	2Г	
# C61	3P	1P	2P	
# C62	6P	4P	2P	
# C63	2P	_	0.5P	
# 665	2P	1P	1P	
# C67	3P	2.5P	2.5P	
# C68	3P	1P	2P	
# C78	1000P	1000P	-	
# C79	0.01μ	0.01μ		
HC1	M57704M-37	M57704H-37	M57704SH-37	



RF POWER

ADJUST

ALL RESISTORS ARE I/B WATT UNLESS OTHERWISE SPECIFIED. RESISTOR VALUES IN A UNLESS FOLLOWED BY MULTIPLIER K OR M. CAPACITOR VALUES IN PF UNLESS FOLLOWED BY MULTIPLIER W.A. INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER IN OR P.

A RYZ IS FACTORY TUNED AND DOSE NOT REQUIER FURTHER ADJUSTMENT.

ON THE COMPONENT SIDE OF THE BOARD,

2 ZI - ZIZ STRIPLINE PART OF PWE.

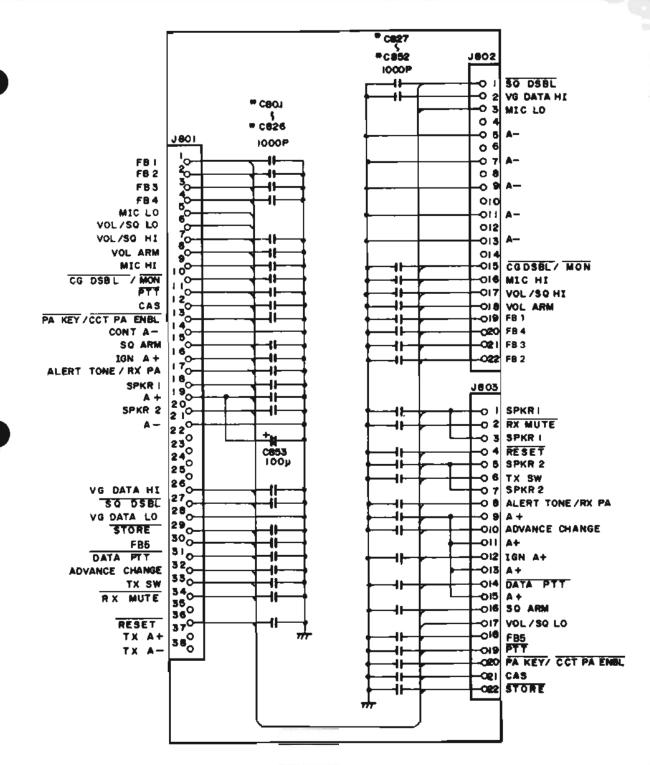
SCHEMATIC DIAGRAM 403 MHz - 512 MHz POWER AMPLIFIRE DD00 - CAH - 256H

FH3-45-1-25 OSA (G)

*CIO13 +

A COMPONENT IDENTIFICATION CHART

	CAH-256AH	САН-256ВН	CAH-256CH
PART	403 ∿ 440MHz (100W)	440 ∿ 470MHz (100W)	470 ∿ 512MHz (80W)
# C1	10p	10P	8P
# C6	47P	39P	30P
# C7	47P	39P	30P
# C14	15P	15P	10P
# C15	15P	_	
# C16	12P	13P	10P
C19	3P	3P	
# C21	10P	10P	8P
# C25	47P	39P	36P
# C26	479	39P	36P
# C33	15P	_	
# C34	15P	_	
# C35	12P	10P	10P
# C41	109	1 O P	8P
# C45	479	39P	36P
# C46	479	39P	36P
# C53	15P	_	_
# C54	15₽	-	-
# C55	12P	10P	10P
# ¢60	3P	2 P	2 P
# C61	3P	112	2P
# C62	6P	4P	2 P
# C63	2P		0.58
# C65	2P	10	19
# C67	3P	2.5P	2.5P
# C63	3P	1P	2 P
# C78	1000P	1000P	-
# C79	0.0lp	0.01µ	_
R34	4.7Ω,1W	1,50,1W	1.50,1W
R35	4.79,1W	1.5Ω,1W	1.5Ω,1W
BC1	M57704M-37	M57704H-37	M57704SH-37



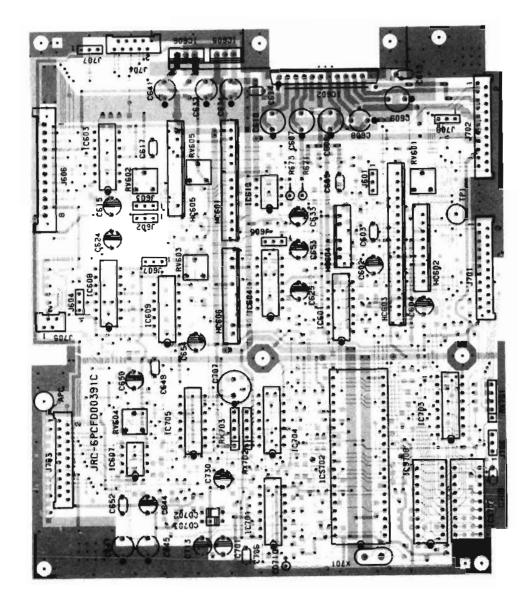
INTERFACE SCHEMATIC DIAGRAM DD00-CPQ-2223

1/1

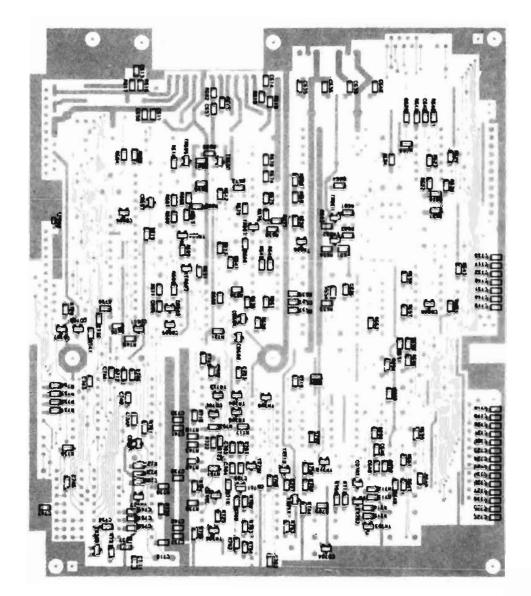
RUNS ON SOLDER SIDE

RUNS ON BOTH SIDES

RUNS ON COMMPONENT SIDE



SYSTEM CONTROL BOARD



LEAD IDENTIFICATION FOR TRANSISTOR

(JOE ATEM)

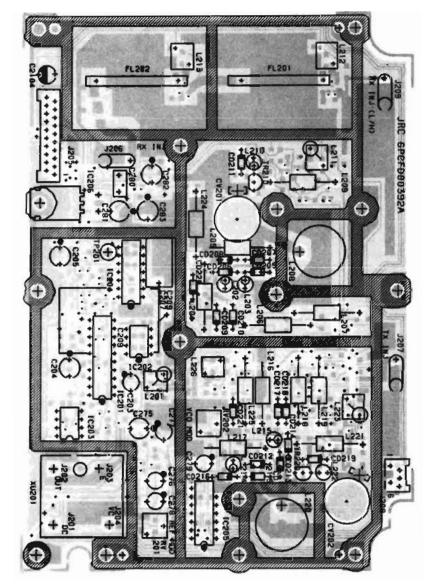
LEAD EDENTEFICATION

(106- A16M)

SYSTEM CONTROL BOARD

RUNS ON SOLDER SIDE

- RUNS ON COMPONENT SIDE



LEAD IDENTIFICATION FOR TR210, TR220 (TOP VIEW)



O G S

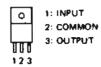
LEAD IDENTIFICATION FOR DIODES (TOP VIEW)



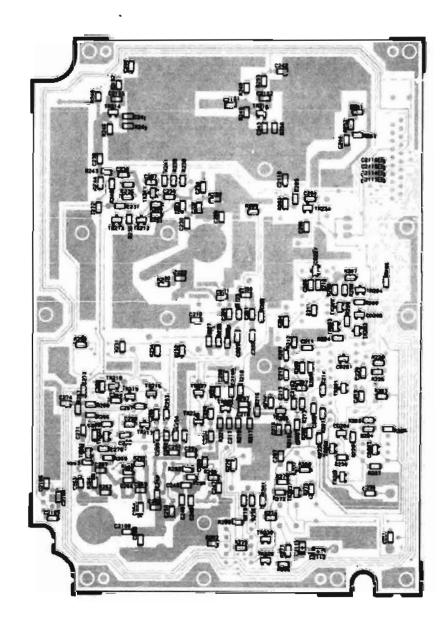
LEAD IDENTIFICATION FOR RV201, RV202 (TOP VIEW)



LEAD IDENTIFICATION FOR (C206 ITOP VIEW)



FREQUENCY SYNTHESIZER BOARD



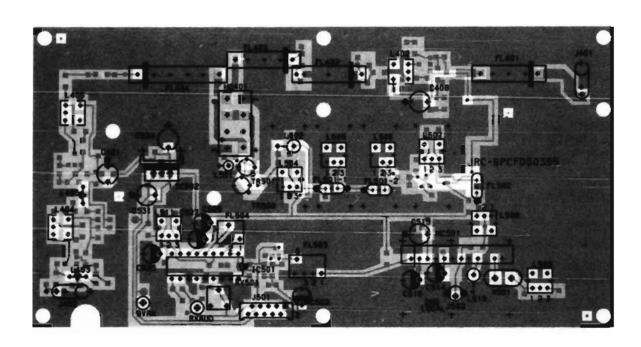
LEAD IDENTIFICATION FOR DIODES (TOP VIEW)



LEAD IDENTIFICATION FOR TRANSISTORS (TOP VIEW)



FREQUENCY SYNTHESIZER

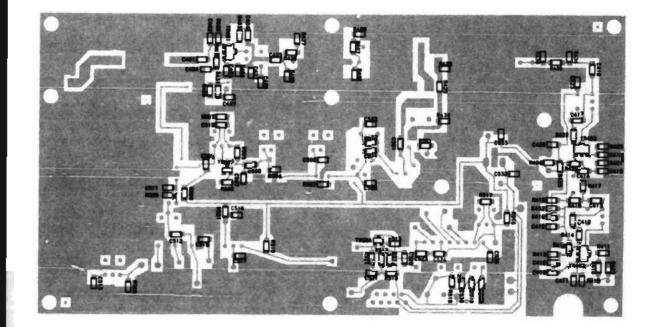


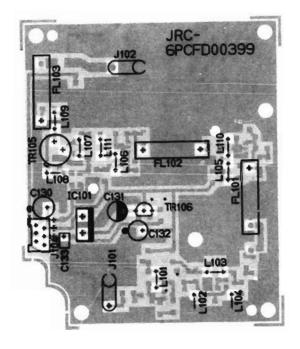
RECEIVER BOARD

LEAD IDENTIFICATION
FOR RV 501
(TOP VIEW)



RUNS ON SOLDER SIDE
RUNS ON BOTH SIDES
RUNS ON COMMPONENT SIDE





LEAD IDENTIFICATION FOR TR108 (TOP VIEW)



1: EMITTER 2: COLLECTOR

1 2 3 3: BASE

LEAD IDENTIFICATION FOR TR106 (TOP VIEW)



1: EMITTER 2: BASE

3: COLLECTOR

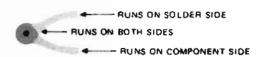
LEAD IDENTIFICATION FOR IC101 (TOP VIEW)

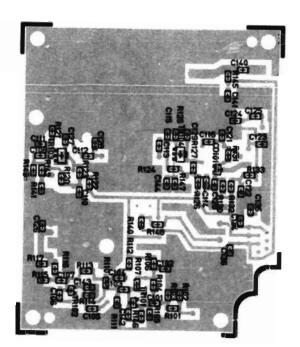


1: INPUT

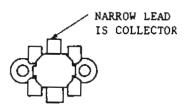
2; COMMON 3: OUTPUT

TRANSMIT EXCITER BOARD

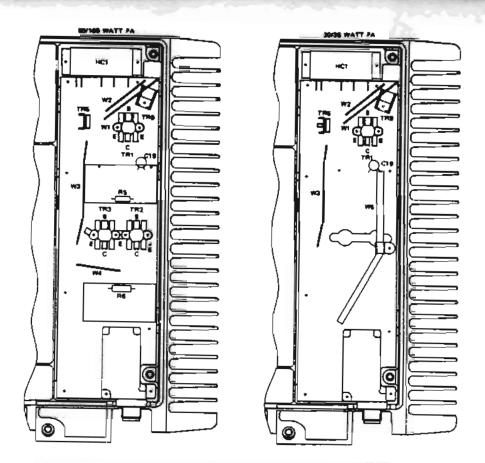


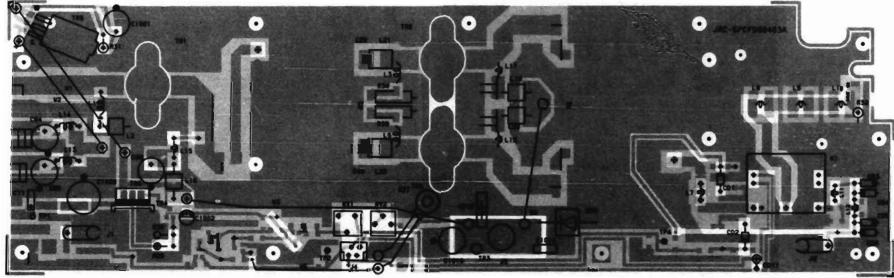


TRANSMIT EXCITER BOARD



TYP LEAD TRIMMING FOR TR 1 TO TR 3





LEAD IDENTIFICATION FOR TRE AND TRE



1: BASE 2: COLLECTOR

3: EMITTER

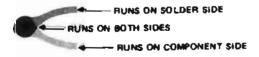


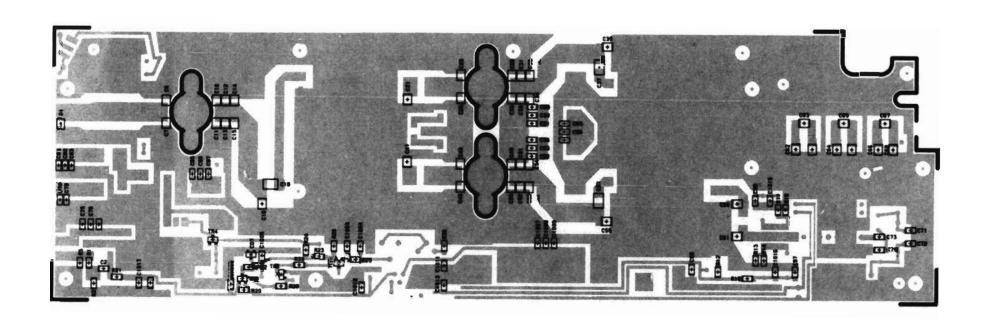
LEAD IDENTIFICATION FOR RV1 AND RV2 (TOP VIEW)

RV2

LEAD IDENTIFICATION FOR DIODES (TOP VIEW)





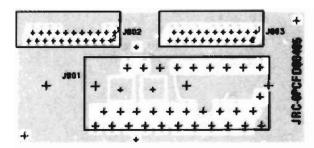


POWER AMPLIFIER BOARD

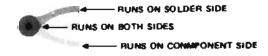
LEAD IDENTIFICATION FOR CD1, CD8, CD13, CD14 and CD15 (TOP VIEW)

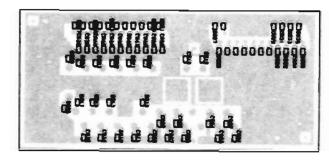
;**____**י

LEAD IDENTIFICATION FOR TRANSISTORS (TOP VIEW)



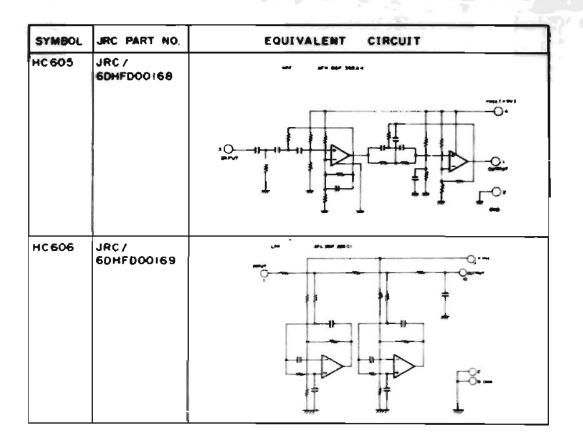
INTERFACE BOARD





INTERFACE BOARD

SYMBOL	JRC PART NO	EQUIVALENT CIRCUIT
HC 60+	JRC/ 6DHFD00160	
HC 602	JRC/ 6DHFD00165	
HC 603	JRC/ 6DHFD00164	
HC 604	JRC / 6DHFD00167	DE-EMPASSS ONLY ONLY



PARTS LIST

-	CE PART NO.	DESCRIPTION
819/0	M-25ML: LOW P	PA BOARD
	2540H: HIGH 2540L: LOW P 2540B: HIGH 254CL: LOW P 254CN: RIGH	POMER (150%) POMER (150%) POMER (100%) OURS (30%)
C1	819/30M80109	CAPACITORS
cı	RI 9/ 50% MRT (7)	(Used in CAN-256 AL, AM, BL and BM), 3 Mices: BpF +0.5pF, 500VDCV,
04 27	319/5CMAB01250	(Used in CAF-25e Ct. and CH). Wica: 47pF +5X, 500VECF. (Used to CAF-25e At. and AF).
06 #14 07	319/3CMA30:430	Nica: 19pF +5t, 300FbCr. (Used in CAN-256 M. and MI).
C6	B19/50MB01464	Micar 30pF +SE, 500TpCu. (Used in CAP-23e CL and CH).
CIO CI3	B19/50M801155	Nice: 27pF +5%, 500YDCsr.
C14	319/504401351	Mica: 15pF +52, 500TDCM, (Used in CAF-25e AL, AR, St and BR).
C14	919/5CMAR01091	
CIS	\$19/30MB01351	Hica: 15pF +5%, 500VDCP; (Gaed in CAN-256 AL and AM).
C14	B19/50MB01443	Mica: 12pF +5E, 500VDCU. (Used in CAN-236AL and all).
C16	819/5CM301495	Wice: 13pF +0.5pF, 500VDCF, (Word in CAN-256 M. and MD).
C16	819/5CHAR01091	Mica: 10pF +0.5pF, SOUVDCH, (Used in CAR-256 CL and CR).
10	819/5CH4801471	Miles 150pF ±51, 500VDCH,
:19	B19/5CAABGG843	Geramic: 3pF +0.25pF, 500VBCW, (Used 1s CAR-256 AR, AL, BL and BM).
20	B19/5C4AH00015	MSCa: 100pF +5%, 100VBCH. (Wased to CAN-256 AM, BM and CN).
21	B19/5CM(801091	Mica: 10pf =0.5pF, 500VDCW. (Dend in GAN-256 AN and BH).
n	B19/3CM801173	Hica: SpF +0.3pF, 500vpcv. (Omed im CAS-256 CR).
25 ad 26	#19/3CHAB01252	Mica: 47pF +SX, SOUMDON, (Used is CAR-256 AN).
23 Md 26	629/50MAR01430	High: 39pF +5%, 500VnCV. (Uned in CAL-236 BH).
25	19/5CHAR01466	Hica: 30pF +31, 300Vpcr, (Teed in CMF-256 CR),
2	119/5CM1001155	Rice: 27pF +5%, 300VBCF. (Used in CAE-256 AM, NF and CE),

STYMEON	CE MART NO.	BESCRIFT 10H
C33 and C34	B19/5CMAR01351	Hich: 15pF -5%, 500VaCu (Bood in CAN-236 AB),
cx	819/5CHAB01351	Hica: 159F +5%, 500VMCH, (Used in CAN-256 MI),
cx	919/5CMA01091	Hice: 10pF =0.5pF, 500VpCs, (Veed in CAR-256 CB),
C35	R19/50W301443	Hicar 12pF +51, 500PHCH. (Used in CAR-256 AR).
c35	819/50W#01091	Mico: 10pP +0.5pF, 5009ECH. (Used in CAIF256 BR and CE),
C 37	B19/50MAB01471	Wica: 150pF =52, 500VBCH. (Used in CAS-256 AR, MI wad CR),
C40	B19/3CAAR00015	Hice: 100pF +51, 100VBCV, (Tood in CAN-234 aN, NR and CK),
CAL	B19/5CHAR01091	Hice: 10pF +0.5pF, 500VBCH, (Used in CAN-256 AM and BM).
C41	819/5CMAR01173	Https: 8pF +0.5pF, 500VBCM, (Deed in CAR-256 CR),
C45 and C46	B19/5CNAB01252	Micar 47pF +51, 500WhCu, (Bunf in GAN-256 AN),
C45 and C46	B19/5CHLB01430	Nick: 39pf +5%, SOUNDOW, (Bood in CAR-256 pm),
C45 and C46	R19/50%801466	Nica: 30pF +51, 50099CH, (Used in CAN-236 CH).
C53	B19/5CHABOL155	Hica: 27pF +SE, 500VHCh, (Weed in CAF-256 AH, MH and CH),
CS3 cs4	819/50MJ01351	HECA: 15pF +5%, 500FMCH, (Wood to CAM-256 aN),
cs)	B19/5CHAB01351	Micai 15pF +SE, 300Fpcm, fBeed in CAF-256 pm),
cs3	B19/50M801091	Hica: 1897 =0.5pF, 30079CF. (Wood in CAN-236 CN).
255	B19/5CHAB01443	Hica: 12pf =0.5pf, 500VBCH, (Use4 in CAS-256 AN),
255		Micas 10pF e0.5pF, 500VpCu. (Goed in CAN-256 NN and CR).
:57	B19/3CMLB01471	Hica: 150pf -52, 500VpCH, (Wood in CAN-256 AN, NH and CN),
560 md 561	B19/5CMAR01124	Micar 3pF +0.25pF, 500FpCr. (Gnet tu CAB-256 AZ end AN).
100	819/5CHAR01170	Hica: 2pF 40.25pF, 500VBCH, (Heed In Call-256 BL),
40	E19/5CHAM2 397	Micus 4pF +0.25pF, 500mpcs. (Veet in Call-214 3H).
41	15/3CM301169	West lef of 25pt, 300vects. West in CAE-256 H. and (H),
1		

-	OR PART III).	MATTER STATE
C00	819/5CHA901179	Most by 40.25pt, 1000pm. (Book to QUI-126 QL and QL).
6		(field is QUI-196 QL and QI).
C62	PT-04-20070-01730	Mices: 6pt +6,5pt, 500MCH. (Tool in COM-236 al. and all),
C6Z	819/9CHABOL397	Hicks 4pF +0.25pF, 500Mpcs. (Youd to CAR-256 M. and SR).
CEZ	\$2 5 /50(\$400).70	MARE 3pF +0.23pF, \$6000CH. (Basé 1s Call-236 CL and CH).
ເພ	11430#1671 #	Micro 2pr +0.25pr, 30000Cr. (Next in Call-256 at and AR).
C#3	MIN SCHOOL SEZ	Micros: 0.3pF =0.23pF, 300VpCr. (Vocal in CAN-236 M., MR, CL and CR).
CSA	919/5QM401320	Mica: 797 g0.5pr, 5000p0v.
cas	819/509a61179	Mices: 3pf +0.25pF, 500mgcs. (Need in Cill-256 al. and all),
043	N19/5GM281109	Mices: 1pf +0.25pf, 500mpCH. (Wood to Call-256 Mt., Mt, Ct. and CH),
C66	325/5CHAR1336	Rices our at. Syr., 30079CH.
C#67	ELS/509A0EL124	Mint 3pf -0.25pf, 300mCr.
13		(Wood in CHE-256 M. and AN).
O67	81W3crus01473	MScot 2.5pr +0.25pr, 50000CL. (Marri to CAR-256 NL, NL, CL and CR),
CMB	815/5cma#1109	Mice: 1pr e4.25pr, 369mack. (Need to CAP-236 M. and MD.
CH4	\$15V5CH4801170	Micro 2pf +4.25pf, 3990cr. (Book to Cil-256 CL and Cit).
ст	B15/3CAA900709	Cormite: 2pf +0.25pf, SPREE, composed 9 +00pm.
cn.	215/3CAN(007%	Cormics 3pf +0.25pf, 200001,tmp coef 0 +10pm.
පා	30.5/30AM00780	Commite: 100pf -SE, 107pcE, tony cool 0 -100pps.
C75	815/3C4480076	Curude: 1008pf +10E, 1079CV, temp carf +330 -100pps.
C76	\$15/3CAA\$6009	Cornelle: 0.01m7 -150, severe, temp each -160.
c77	115/3CH490364	Counter 4.47mf -168, 30mgcr.
CTIL.	MP/XMMM	Communic: 1600pf +101, 100mCH, coop- cand +250 -1000 pps. (Need in Con-256 al., at., pl. and 303.
c79	NO SOLUTION	Consider 8.066 - 10K, 5000CK, trap- cost +10K. (Mind in Col-226 at., at., at. and 30).
ctes	-	Martinlytic: Dyr. 1881, 1880.
cats .	MANAGEMENTS)	Committee: MilyF -W., Sirince, Lang conf 8 -Milyon.
a	115/30L010001	Computer 1000pf +100, MINER, Date and +200 -1000 pps.
	103/3Chination)	Company B. Shipf 1985, 709031, 1989 and 1985.
CBA	Mary State S	Electrolytics 43e plin, 19mm.
cas	H5/3246FD	Country 1984 - 18, Mester, may med 0 - 1984.
3		

-	CE PART ID.	MANUAL PERSON
CRE	103/3C440000	Corcarie: 1000at +100, Strace, Lane
	1	Coronic: 1000pf -100, Mercu, Lang- cond +350 -1000pps.
cato	B11/SC24000700	Consider B. Staff glott, Street, component glott,
CBB	BUNSCHAPTERS	Beetrobnites Our gint, 1980s.
C89	811/3Ch4300700	Committee: 100pt etc., 500ptcs, 500p conf 0
CAR	2Viculatos	Cormic: 1600pr +160, 50mcs, (asp cost +350 +1600pg. (fee to CSF-256 all, all and CD).
CPI	N/SOME	Coronale: 2300pt off., 500mm, comp conf +350 -1000pm. (Good to CMI-255 AM, MI and CS).
C#S	B114/3C4460700	Coronder 19849 592, SWEET, Long- conf 48840. (Seed in City-256 all, 38 and CO).
Cag	811//SQUIGHB70	Corpusion 1000gF alls, 200009, bread over +250 -1000ggs. (Good to CMI-256 AM, SM and CM).
C9A	B19/304869792	Corunte: 2500pr +55, 500000, pany coof +350 -1000pm. (Sood in Ciji-256 Mt, MI and CID.
cts	819/3/2A000078	Corunder 1998pf -186, 3998CM, tapp coef +230 -1998pgs. (Seed in Call-236 AR., III and CR).
C%	\$2\$V9C348887\$9	Cercular 4.65, 1961, 5000CV, casp cost +100, (Gand to COS-256 Mt, M and CO).
68 68	E15/3/24/00700	Country 1986 of S. March, temporal Colleges.
C99	SEN/SCHAMOUR	Commics 1000pF +18E, 7000CH, two-
C1001	\$19/3CBM#1844	Klackinkytler 220aF +200. 220000.
C)002	\$15V3C3MC8F794	Tencelone by spin, limper.
C1003 chru C1006	\$15V5C34400070	Counte: 1000pf +10%, 3000CH, comp coef +330 -1000pps.
C1007	\$19/70MH#780	Counter 18647 eSt, SPRES, teap conf Sellage.
CZÁROS	125/3Cad000076	Coronder 1884/ +165, SPECE, COSP Corf 4250 -1886pin.
	117/7cames/17	Curanies S.Mar - Mills, Strack, some conf - Mills.
0498	HWYCHARDS	(Necessiyties 2004 alif., 2004),
CHEE CHEE CHEE	\$19/3Capping#6	Serinder 1996/ 4161, SSSCK, bully COST +250 +360 pp.
CORTA	NAME AND ADDRESS OF	Committee Andrews and Publishers.
colisi end colisi	HINTOLOGETS	County 100kg olds, 100kGr, name COST +350 -100kgr.
C)III7	1047/Capping 10	Companies 1984 (1988, 1989), 1984 Cont. 1988 - 1984 Cont. 1988 - 1984
Ca(120)	medicanion?	Microspiles Old gall, Marc.
		À

STREET	GE PAGET NO.	DESCRIPTION
	0	
CD2	BEST TEAMORE	Silicon. (Schurtky Barrier): Sis to NEC 18697 (2).
818	B19/ 5TTAM00051	SELECTOR, foot recovery, (RF Switch): ofm to Hitmobiaki HEAD?,
COM	B19/97E4800051	Silicon, fast receivery, (RF Siricch): also to Micambishi Mi407.
CB7	B19/97XAA09402	Zemer: 6.87, 200mH, atm to MSC R36.800-T1.
CDF9	B19/3/E400019	Silicon: Full current 3A, 200PSV: min to NUTCHDLA NUTS).
CB 10	819/9TXA400104	Commic Varietor: Limit veltage 30 to 135V, sto to Sanken 500-2200310.
Ori	BE9/ 3034400001	Silicon: 2007 LA, ofm to Souhen Delz.
		WATER CONCESSOR
MC1	827/380AB00249	MP Power Amprilier: aim to Mitsmbishs MS77944-37 (Wood in Chi-2564L and AM),
mC1	819/3004800247	RF Power Amprifier: wim to Mitsublobs MS7704H-37 (Wood in CAS-256 ML and MH).
ec i	519/300AB00248	RF Power Amplifier: sin to Hitmbinbi NSY704SH-37 (Used in CAR-256 CL and CB).
		consectors
13 peeq TI	B19/3JMCL00045	Connector, W.
13	919/53AAG90060	Co-sulal connector H type
	B19/5JW8609176	Connector, RF1 6 plu.
13	B19/5JTCH00060	terreteat.
		RILAY
ET	339/SELAH00657	Belay: 1097.
		ons
ы	315/6LAF001247	Ge11, 1F.
LZ	819/6LAF961129	Call, Ef.
13	919/6LAF991248	Cot1, RF. (Doed in CAS-254 AR. 30 and (E)
U	B19/66,MF001250	Co11. 17.
LB	E19/6LAF901251	Cotl, RF.
1.9	pa 9/6LAF901 251	Ce41, AF.
L10	B19/4LA/001251	teti, V.
LIE	319/46AF941254	Cod), RF.
L12	B19/6LAF001254	Codl, RF.
LUS	E19/61/2012/07	Coll, M.
	-	

STHEEL	GE PART NO.	1
L34	319/6LAPS012A7	Cell, 17.
113	919/6LA7901256	Gell, RP.
LJ6	319/6[47001139	Call, U.
นา	BIWGLAPOST260	Got), RF: (Quet in CaS-256 AH, SM sed CH).
1.1.0	h19/6LL7901129	Coll, 197 (Sund in CMS-256 AS, SS and CSD.
L19	\$19/6LAP801260	Cot1, RF: (Seed to CdS-254 AS, ER and CE).
L20	11% QLF101125	Cot1, RF1 (Bond to CMS-256 AM, EM and CM).
121	h19/GLA7901261	Cutt, RF: (Bood to CAB-256 AK, III and CR).
L233	h19/66AF001261	Coil, 17: (Seed in CAS-256 AM, 20 and CE).
		eggistens
R1	B19/SRZAC00995	Hetal film: 5.6 olms +5K, 20079CH, 1/6K.
F3	31975REAC00636	Herel file: 820 shee ±5%, 2009900, 1780.
ស	\$19/3E2A000014	Hets) film: 100 olms +55, 330VpCU, 24. (Bood to CAM-256 4E, SS and CR).
R6	819/SEEAG00470	Hetal film: 2000kms +5%, 3500kGH, 30. (Bood in CAS-256 Al, MK and CH),
N)O	819/SREAG08584	Hetal film: 100-hum ±51, 20079CF, 1/6V.
NJ Z	\$19/SEMG00596	Hetal file: LSK olong +5%, 2009BCU, 1/8U, (Good in Cul-236 AL, M. and CL)
113	819/SRENGO0581	Heral file: 22K plan +5E, 2009(CE, 1/Br (Bood to CAS-256 AB, 3E and CE).
113	119/SEEAG00586	Notal f(las 47 elem ±5%, 2000900), 1/Sr.
R15	819/SREA008572	Note: 1 file: 1K ohns -5K, 20079CH, 1/8r.
R20	B19/3REAG80571	Hesal film: IE show ±5K, 2007BCE, 1/8v.
R25	B19/ SRZAC00573	Netal Films 4.7K sham (SI, 20079CH, 1/84.
122	819/3EE4008397	Nece1 951ms 230 chan _55x, 20070CF, 1/Dr.
123	819/3HEAD00575	Sects 7(1m2 2.2% phase +5%, 20000CF, 1/80 (Speed to CAS-256 AE, St. and CL).
123		Negal Filter 1.5% plan +55, 2009NCF, 1/Bir Chard fo Cull-254 all, 80 and Cir),
1,74	B19/3MEACB0574	Notal fills 18K shan 95K, 20078CH, 1/8K,
125	311/Skgsc00994	Netal Film: 228 shae \$52, 20079CH, 1/6H,
E26	\$1.W383600575	Notal filler 2.2% shan 55%, 2000007, 1/20.
147	N/1/2022-000020	Portstar (Next in CAS-256 AS, SK and CA).
	l,	

- 1	-	The Charles	
	School	OR HART WE.	beschrift.
	120	#14/36/C005E1	Marcol (1714) 225 along 456, 2004000, 1/46,(Speed to CES-256 &c., 66 and CR).
	127	211/3034/071541	Carbon Piller 470 abon 691, Marson, 1740.
	H200	\$\$1/SHILARE\$43	Carties Filler: 220 chas ±51, 307907, 1740,
	1139	14.5/3004,401.576	Cortes filter 10 chas c51, 300vsCr.
	B.32	Maria Maria	Cortica (Eller 1/1 etc58, 2009)CV.
	833	NW Named His	West files 300 days +51, 3000pm; 1/80 (Gard in Cap-254 48, 88 and GD).
	12A 404 125	103/3mmole412	Special Filling 4,7 show, TV. (Vend in Cin-236 all),
	13A 135	IQW SHELDWOOD	Notes fries 1.5 days, 18. Filled to Cill-256 St and City,
	136	119/3034c00590	Natial filler 0 ohn 1/84.
	107 1,	919/SEMABRE77	Bertinkler IX oten "Mit, 6.19.
	E#2	#19/30000033	Vertablet bit den gert, 0.20.
	That	ELS/TICA/ORDE	Silicia, Mir Power Amplifier, 600 (Simila, 12.30) ata to Microbiaki 200382.
	73.2 73.3	HEA/HEMOSORE	Hilliam, Mit Power ampliffer, 60m (Simmi, 12.37) one to Membelski 1923/00 (Noof fa Cal-256 AB, M. and CA).
	784	815/3[Baji00054	\$11 Econ. Wit: who to MC 250791-71.
	TRJS	825V 92148000043	Sijikem, FW: ein to Recombite Stocklie.
)15/72had0054	\$1150ms, 1889 of to 186 28098-11 (Next to Call-256 all, 18 and CR).
	1007 I	81W/778480054	9125com, 1880 etg to SEC 200998-71.
	7340	31W 3734440055	\$1150m, RD1 sån tu HC 258434-T1.
	78.0	1154.200 Marie 12	Stilligen, Williams of the to Madamakita 2001.2700.
	_	M3/0L4/909290	
	-		
		M5/4/A/901299	Ware.
		ht IV GLACING SHIP	Man.
	-	iggi/(Rappin.34s	Vites. Chart in COS-254 AV., TO and CO.).
	25	in Westplates	Sential mates Sent to CE-255 AL, R and CL).
	_		
		NINCH-256 NINCH-256 SINCH-256	MCDER HAND
		National Control of the Control of t	Committee halffy staff, Staffin, somp conf 4350 -1896pp.

Section.	CE PART 10.	MODEL PROPERTY.
C103	\$11V5C4200117	Coronalet 17yd of Spr., Million, comp could 4500 -18665 (Speed in Call-1864).
cies	Nas/Scaumoris	Corondor 1550 gSL, 500000, temp soul addges. (Specific COP-2560).
CIES	N1/SQUARES	Consule: 1647 gH, William, comp conf (Maga: (Small to GU-SMc).
C	\$19/5CM#88076	Create: 1000pr oldt, Strate, temp coef +350 -1000pps.
CISS	ET WSCAADORNIE	Consider 1807 518, 507000, comp conf findings. (most fa COT-2564).
cles	E15/3CAMBRIDE	Consider 1500 500, Wester, being conf Consider. Classif & Carl-2001.
G85	\$19/5CM8007(4	Consuler 12pr eld, Smell, sing over distance. (Next In Car-Stoc).
CIÑ	it-V7CMadeeid	Consule: 200 pH, March, casp and Street, Clare to Car-25th).
ពល់	1257303486666	Creed() lay off, MINCH, same most findings. (Same to COP-2768).
C167	\$29/5Cha00705	Cornell's 10pp yt.Spr 100001, temp Cord 6000000. Open In Car-20001.
C)66	159/304888389	Germate: 188pF uSt, 588pOil, temp
CIL	MY TOWNSON	Grander 1000pf +16K, 2000CF, temp Out +256 +1600ppi.
cni	NW MANAGEMENT	Gurande: 2pf =0.25pf, 2000CU, nonp Shad B =000ppm. Shard in CAF-250q),
ខាង	STW YOMER PRO	Germale: 1889F gM., 5009CR, topp
വാ	NI VYCAMONIA	Security Opt of St. 1980s, page
CUÉ	нужнее	Carrier Miller yell, Siller, seas Carr Spillers.
CIN.	CONTRACTOR TO	4-161 184 18, 3303, 144 14 1244
a.	WWW.	Complete State Sta
CL ^{jij}	HIV YOMEN STATE	Control (Service of)
O.A.	WW.	Can bress, 200,
Œ12	Marian Principal	
œn.		المسابعة والمساوات
CC.	Marian Pa	242.
a 25	-	

STHE	OL CE PART NO.	DESCRIPTION
-		
C12		coef 0-60ppm. 9 Cornect 6pf -0.5pf, SOTDCE, Lamp coef 0-60ppm.
cizi	B19/5CAAB0079	CONNET TO CAP-256 A and B), 6 Curinter 2pf of 25pf, 30YDCH, cump coef 0+40pps. CUsed To CAP-256 c).
CIM	B19/5C4AB0000	
C1.30	819/ SCRAADLOAS	
ตห	B19/3054000323	
CI 33	B15/5Chag0141)	Ceremics 0.127 +80%, -20%, SOVECH, temp coef +30 -80%,
CL42	R19/5CAAB00792	Ceramic: 2200pF +52, 50VDCV, temp cost +330 -1000ppm, (Seed in CAF-254 A and B),
C144	319/5CAAB00780	Cornetc: 100yF +5t, 50VDCr, temp cosf 0+60ppm.
CD-101	E19/STEAD00291	Stilcon, fust recovery (2 diades in series): win to Toekibe isSTBA.
7 L101	319/54RAT00016	EF B.F.F.: Tame bond 403-440 sqrz. (Based in CAF-254A).
FL101	919/58LAT00023	RF B.F.F.: Pans band 440-470 Mtz. (Used in CAF-2548).
FL101	B19/58KAT0002A	RP 3.P.F.: Pass band 470-51200z. (Used in CAP-256C).
FL102	819/500AT00022	RF S.P.F.: Pann band 403-440pm; (Good in CAP-256A).
PL102	019/56/LATG0023	RF S.F.F.: Page band 640-670gg; (Deed in CAP-2568),
PT. 1.02	B)9/30GAT00024	RF H.F.F.: Pass bank 470-5120ffx. (Osed in CAF-256C).
PL103	819/3HAT04022	RF B.F.7.: Pass bond 403-440-Ez. (Good im CAF-256A).
PL 103	#19/SHLATORE21	RF B.P.F.1 Page hand 440-47000z. (Wood to CAF-256E),
7L103	BEW SHEATOODZA	RF B.P.F.: Page band 470-51298x, (Used im CAF-256C),
IC161	B19/500A680021	Lisser, Posttive Volcage Regulator: sta to Nationalita APGS41.
(101 mdi (102)	819/3.NCL00843	Communication of the Communica
184	819/3JW0000176	Commecter, 6 pin.

	GE MET NO.	DESCRIPTION
	12	ФП3 ——
£101	919/6LAF801263	Cotl, EF.
F303	815/6CAF801264	Coll, EF.
LIO	B19/MAP901265	Coi1, EF.
L105 thru L106	B19/6LAPB01265	Coll, EF.
L109	839/6LAP801264	Coll, EF.
1.111	\$19/6LAFB01263	Cot1, EF,
	No.	MESTSTORS
#10f	B19/58JMG00419	Hetal film: 22 abou +5%, 200vacu, 1/8s,
#102 ##d #103	819/5REAG00422	Mercal film: 270ohum ±5E, 200Vacus, 1/8M.
R104	319/SKEAG00574	Writel film: 1.5K olumn ±5K, 200VECH, 1/8H,
R105 and R106	E19/SREA000397	Heren' fflux 330 ohns ±5%, 2007ECV, 1/Dr.
R107	B19/58EAC00579	Herel film: 670 ohem ±5%, 20099CH, 1/8r,
X110	\$19/5REAC00574	Metal film: 1.5K ohum +5X, 200VSCH, 1/3H,
mı		Metal /films 330 ohom ±5%, 2007pcw, 1/9e.
N)12		Metal Film: 270whee +5%, 20079CM, 1/DV.
R113		Notel Film: 330ohem ±5%, 20009000, 1/Br.
R114 and R116	819/5REAG081/90	Necal filles 0 show, 1/8st,
K1.20		Notal film: 2.7K whom ±5%, 20079CB, 1/dm.
nin		Notal files: 330 ehem ±58, 20099CH, 1/8F.
N1.22		treat films (4 when -51, 20070cs),
ยย		decal filler 330 shar ±5%, 2007ECH, //BH,
B124	819/988AC00623	httal films 2.7% olos <u>+</u> 5%, 2000pcs, /De.
RIZS	K19/38ENG90622 N	intel film: 270-has -52, 2000pcm, /8e.
nM:		heral film: ZZuhan -SE, 2000mcs, /SML
etta	019/502600996 0	istal films 220 shan -52, 2000acu,
-130	119/30344C00574	HEAR Filter 1.5K when 45K, 2007ACH, Filtr.

_	CE THE NO.	PERCEIPTOR
un	319/383400094	Hetal films 220mins 451, 200min, 1/80.
132	119/Stmc00615	A Secretary of the second of the Second
1133	319/586A000572	mount films IX show 450, 20079CF.
n4	91.9/3mts4000302	1/00. Noted Filler 1.0K since +5K, 100VpCm 1/00.
1141	825V782MG80634	
1142	115/3KEM200595	instal fille: 5.6 shoe -100, 1007907. 1/84.
ш	B29/9863600636	Hatal film: \$20 olms ±5%, 20079CH, 1/90.
£145	819/38/2009573	Notes: #55ms 4.7% alum ±55m 20070cm. 1/8r.
E146	E19/3E84400597	Noted files 330 show -52, 3000000, 1/8r. (Seed in CAP-255 A and 8).
ша	819/3E2400619	Histal fills: 22 show +5t, 20049Cu, 1/8t.
1146	115V 3004C00597	Notal file: 330 shee ±52, 200*8CF, 1/00.
	SENTROLINGS:5	Silione, Mile win to Mil 29(2779.
TR. 142	12.5/7/Capterion	SELECON, MPH: sin to MIC INCLUSE.
12103	\$19/3YG4998787	Silicon, MM: ele to Tenhile 2003357.
TERM	\$15/3FCAPORNET	Silicon, MW: eig to Tankibs 2903357.
TR.205	F14/34CF140361	Silien, 1981 atp to MC 1912762.
	A THE REAL PROPERTY AND ADDRESS.	and the second s
	M2/30/00003	2541636-7.
with	B15V7EA660093 B15VCHD-13761 B15VCHD-13761	25AM2N-Y. STREETSLIGHT BANGES 603-640min
wife cin	159/CHQ-1304; 815/CHQ-1304; 815/CHQ-130C;	STANDS-T. STANDS-T. STANDS-TIME MARIN 649-47000 CP-112000 CRACTIONS Consider 0.8474f e.MC, 270001, tamp
can	159/CHQ-1304; 815/CHQ-1304; 815/CHQ-130C;	25ANOS-T. STREET, MARCH
cin cin	HINGS-130: 11900-120: HINGS-130: HINGS-130:	STRUMENT DIAGO STRUMENT DIAGO SES-ALADAM SES-ALADAM SES-ALADAM SES-ALADAM SES-ALADAM SES-ALADAM SES-ALADAM CONTRACTORS CONTRA
cals	HIS/CHO-1370; HIS/CHO-1370; HIS/CHO-1370; HIS/SCAMBILTE HIS/SCAMBILTE HIS/SCAMBILTE	25ANOS-T. STREET, MARCH
	NA SCHOOL SELECTION OF THE PROPERTY OF THE PRO	25AMENT. STREET, MARCH
	EFF/CHD-1370; EFF/CHD-1370; EFF/SCAMELLYI EFF/SCAMERLYI EFF/SCAMERLYI EFF/SCAMERLYI	Symmetrical Districtions 603-640min 640-670min 640-670
	HIS/CHO-13DAI HIS/CHO-13DC: HIS/CHO-13DC: HIS/SCHARRILL'H HIS/SCHARRILL'H HIS/SCHARRILL'H HIS/SCHARRILL'H HIS/SCHARRILL'H	STANDAY. STANDAY IN THE STANDAY OF
	###/CHE-1376; ###/CHE-1376; ###/CHE-1376; ###/CHE-1376; ###/CHE##### ###/CHE##### ###/CHE##### ###/CHE##### ###/CHE#### ###/CHE####	Symmetrical Districtions 603-640min 640-670min 640-670
	ESSYCHOLOGICAL SELECTION OF THE STATE OF THE	STANDAY. STANDAY. STANDAY. STANDAY. SAN-CASAN. 649-CASAN. 649-CASAN. CANACITORS Connades 0.407-d .10%, 270001, tany and .21%. Dennades 0.407-d .10%, 270001, tany and .21%. Linetrolyster 22%-F .28%, 100001. Chemites 0.607-d .10%, 270002, tany and .25%. Subgranyforms 1sd .2%, 270002, tany and .25%. Connades 0.607-d .10%, 270002, tany and .25%.

STREET	CE BURT NO.	New York
cms	\$19/50mm1131	Coronder 4,04745 glob, 250000, tomp
മാ	B15/3CAAB40680	And the state of t
C 11)	319/3CAA#80977	Coronto: 747 pt.547, 388000, comp conf bade par (form To COE-1381).
chia chia chia	315/3CAA80076	Coronic: 1800pf 6185, 1899CH, Comp- coof 4350 -1800pm.
CE15	823/3GA400070	Correction 150pp of E. 1000CH, compound Ogsfoppe.
C220	HW30480676	Cornele: 1000pr +165, SPECH, composed +330 -1800pps.
CZL	11.9/3CM/00069	Cornate: 22pt offi, Mentry, temp conf Distinger (Band To CHO-12ht),
C221	819/SCIA880794	Consider Mar (SR; Merch, time conf (Merch, (Real to CO-1229).
c221	13 W3CAMBOTTS	Counter 27pf est, SPACE, comp and Goldens. (Seed in CHC-128c).
C222	\$25V 3CIAMIO 795	Cornector Dipl (SM, 1970CH, comp cont Science, (Classic To CHE-LINA).
CRES	£19/3CM#01290	Consider 1867 538, Marcy, tamp gast 4790 41305555 (Bast in CC-1286,C).
C223	Resources	Creminder 12pf gill, 1979cm, trap cond Configura. Change To Cop-125cf.
czzs	STOP SCHOOLSPES	The facility of the control of the c
COED	101/1-14000EZ	Connect for St. Ser. Series, com-
CT. ¹⁴	MI-1704400-276	Charles & S.Dyr., 1980s, con-
CZ IS	119/7CM#86799	The Edwards
CTE I	10V3C4480195	tension by gluby, sweet, any new police. Sand is section.
cas	RYNOMINI	County (Mile) (SEC, SMICK, CO.) and (SEC.
coss	ad/Rangings)	Control of State (State)
	HANNE THE	
•	Professional	Charles and States, States, and Charles an
cm)	TENTANTIAN	Sanday (19 years), States, and

STHEOL	GE PART NO.	DESCRIPTION
C228	B19/3CAAD00783	Germaici 4700pF +10%, SOTECV, temp
C228	1	coef 4101.
C230	\$19/5CAA001303	Countic: 27pF +5%, SOVECH, temp coef -750 +120ppm.
C231 ==4 C232	B19/3CAAD00070	Ceramic: 1000pF ±10%, 50VDCF, camp coef +350 -1000ppm.
C233	B19/3CAAD01303	Ceremic: 27pF ±51, 50TDCH, temp conf =750 ±120 ppm. (Qued in CRG-132A, 9).
c233	B19/5CAAD01306	Cernaic: 22pF +51, 50VpCH, temp coef -750 +130ppm. (Used in CHG-139C).
C234	B19/5CAAD01306	Geranic: 22pF +51, 50VDCR, temp coef -750 +120 ppm (Uned in CRC-132A, B)
C234	919/3CAAD01298	Coranic: 18pF +5X, 50VDCV, temp coef -750 +120ppm (Used in CRC-132C).
C233	319/5GAAD00796	Gerunic: 3pF+0.25pF, 50VDCM, temp coef 0+40ppm. (Used In CHG-132A)
C235	B19/5CAAD00600	Cermic: SpF \pm 0,25pF, 50VDCH, tempcoef 0+60ppm (Used In CHG-132B),
C235	319/5CAAD00795	Ceromic: 1pF +0.25pF, SGVDCH, temp coef D+6Oppm (Used In CHG-132C).
C236 and C137	319/5GAADD0678	Ceramic: 1000pF ±10%, SOYDCW, temp coef +350 -1000ppm.
C236	\$19/5CAAD00049	Ceremic: 22pF ±5%, 50VDCH, temp codf 0=60ppm.
CZ39 thru CZ44	B19/SCAAD00878	Gerumic: 1000pF +10%, 30YECM, temp coef +350 -1000ppm.
C245	819/5CAA800787	Ceranic: 15eP +5%, 50VDCW, temp coef 0+60ppm.
C246	B19/5CAAD00795	Cerimics 1pf +0.25pF, 50VDCN, temp- coef 0+40ppm.
C248	B39/3CAAD00878	coef +350 -1000ppm.
C249	B19/5CAABOORE	Ceramic: 189F +5X, 50VDCW, temp coef 0+60ppm. (Used In CHG-132A).
C249	B19/5CAAD00869	Ceramic: 22pF +5%, 50VDCU, temp Caef 0+60ppm. (Used im CHG-132B, C).
C250	\$19/5CAAB01306	Ceranic: 22pF ±5%, 50V9CV, Lonp coef -750 +120ppm. (Used in CHG-132A).
C250	B19/5CAAB01299	Ceramic: 15pP ±5%, 50VECF, bemp coef ~750 +120pps. (Qued im CRG-1328).
c250	B19/3GAAB01296	Ceramic: 18pf ±51, 50VECF, temp couf =750 ±120ppm. (Need in CRC=132C).
Cası	B19/5CAAB00000	Corrector SpF e0.25eF, SOTECH, temp- coef 0x60ppm. (Used In CRE-152A).
	1	

		DESCRIPTION
STHEOL	GE PART NO.	DESCRIPTION .
C251	319/5CAA800022	Ceramic: SpF +0.5pF, SOVECH, tamp coef 0+40ppm. (Used In CHG-1328).
C2 51	#19/5CAAD00785	Ceremic: 10pF +0.5pF, 50FDCH, temp coef 0+60pps. (Used In CHC-132C).
C252	919/3CALD00795	Ceramic: 1pF ±0.25pF, 50FDCW, temp coef 0+40ppm. (Used In CHG-132A).
C252	B19/5CAA000977	Cerumic: 7pF ±0.5pF, 50VDCs, comp conf 0+50ppm. (Wood In CHO-1328).
C252	319/3CAAB00822	Ceramic: 8pf +0.5pf, 50VECM, temp coef 0+40pps. (Used Ta CNG-132C).
c253	319/SCAAD00783	Ceramic: 4700pF ±10%, 50VDCF, temp coef ±10%.
C254	919/5CAA300794	Caranie: 3pf +0.25pF, 50VECM, tamp coef 0+60pps. (Used In CHG-13ZA).
C234	319/5CAAD00810	Ceramic: 4pr +0.23pr, 50TECH, tomp conf 0+60ppm. (Used In CHG-132B).
c234	819/5CAAD00600	Ceranic: 5pf ±0.25pF, 50VECF, temp: coef 0+60ppm. (Used Tn CHG-132C).
G333	319/SCAAD00795	Ceramic: lpf +0.25pF, 50fDCM, temp- coef 0+40pps. (Uned in CHC-132A).
C255	B19/3CAAB00798	Cerusic: 2pF +0.25pF, 50FECH, tump coef 0+60pps. (Used Ta CHG-132m).
C235	B19/5CAAB000001	Cerusic: 49F +0.25pF, 5079CW, temp coef 0+40ppm. (Used %m CHG-132C).
C254	B19/5C4AB00783	Cernmic: 4700pF +181, 50VBCF, temp coef +101.
C257 thru C266	919/5CAADOO876	Cermite: 1000pF +10%, 50VECH, temp coef +350 -1000ppm.
C262	\$19/5CAAD01291	Ceramic: 33pF ±5%, 50FECV, temp coef -750 ±120ppm.
CZ 6.3 and CZ 6.3	319/3CAAD00678	Ceramic: 1000pr +10E, 5078CF, temp- coef +150 - 1000ppm.
C265	919/5GAA001304	Coronic: 229F ±5%, 3090CH, tump coef -750 ±120pps.
C2 6 4	319/5CAAB01298	Ceremie: 10pf +5%, 50VBCM, temp coef -750 +120ppm.
C267	319/3CAA300000	Ceremic: SpF =0.25pF, 30VBCH, temp coef 0=60pps.
C2148	819/5CAAB01131	coef elff.
(269 and C170	B19/5CAAH00878	conf +330 -1000ypm.
ໄໝາ	819/3CAAR00069	Countie: 229F ±58, 50FBCH, temp coef 0:50ppm.

	GE PART NO.	DESCRIPTION
C272	819/5CAA000795	Corante: 1pf +0.25pr, 50VBCH, temp coef 0+60ppm.
C273	B19/5CAA000795	Geranic: 1pF +0.25pF, 30V9CV, temp coef 0+60ppm.
C274	B19/SCAABOOR78	Caranic: 1000pF +103, 50VDCH, temp conf +350 -1000ppm.
C276	\$19/5CEAA01962	Electrolytic: 47m -20%, 1679CW.
C279	319/5CEAA01826	Electrolytic: 10mf +20E, 1690CH.
C280	B19/3CRAA00576	Metallized Plantic: 0.1uF +52, 507900.
czel thre czel	\$19/5CRA401827	Electrolytic: 100,09 ±20%, 1475CS.
CZSA thru CZSA	10.9/5CAAB00878	Ceramic: 1000pp +10X, 50VpCw, coef +350 -1000ppm.
C287	919/5GAA901131	Corante: 0.047,7 +105, 2579CV, ten coef +105.
C289	319/SCAAB00796	Corante: 3pf +0.25pF, 3099CH, temp coef 0+40ppm. (Used In CHG-132h).
C290	B19/5C14800001	Corandet 4pF +0.25pF, 50VDCH, temp coef 0+60ppm. (Bood To CHS-132A).
C290	119/SCAAB00796	Corunic: 5pF +0.25pF, 50TECV, temp conf 0+60pps. (Ound In CHD-132b),
C250	819/3CAA800790	Ceronie: 2pF +0.25pF, 30FECV, temp coef 0+60pps. (Weed To CHS-LIEC).
CIN	B15/5CAABGG795	Cerander 1pF +0.25pF, 50VECH, time- cent 0+60pps. (Wand In CHS-132A, C).
C291	319/3048007%	Corande: 3pF +0.25pF, 50VECH, two- coef 0+60ppm. (Wood To CoE-132p).
C292	h19/5044800783	Ceremier 4700pr +201, 10VICE, temp coof +105.
C293	219/3CM200796	Corander 3pf +0.25pf, 50VECH, tomp conf 0+60pps. (Deed In CHS-L32A, C).
C253	E15/5CA200790	Geranics 2pf =0.25pf, 5099CF, temp conf 6-66ppm (Good in CHC-1328).
C294	B15/3CA4800795	Coronic: lpf +0.25pf, 3070CV, composed 0-60ppm (Seed in CHC-133A).
C254	BLW SCAABGETTS	Coronales 2pf +0.25pf, 500pCr, tempoted 0.50ppm (Book in CHD-132 S, C)
C295	815/7CM600763	Committee 4700pf -100, 300pcV, time coof -100.
C256	\$19/3CAMPEPER	Corneles (1667 455, 1949CV, Lute cost felfiges.
C298	11.9/3CAL000076	Certaidet 1600pf +161, 500pcr, trop conf +330 -1600pps.

C2100 B19 C2100	#/SCAABOORF8 #/SCAABOORF4 #/SCAABOORF9 #/SCA	Corunic: 1000pF +10pF, 50FECH, temp coef +350 -1000ppm. Ceramic: 47pF +5%, 30FECH, temp coef 0+60ppm. (Used In CHC-132A). Ceramic: 33pF +5%, 50FECH, temp coef 0+60pm (Used in CHC-132B, C) Tantalum: 1uF +20%, 35FECH, temp coef 0+60ppm. Ceramic: 1000pF +5%, 50FECH, temp coef 0+60ppm. Ceramic: 27pF +5%, 50FECH, temp coef 0+60ppm. Ceramic: 27pF +5%, 50FECH, temp coef 0+60ppm (Used in CHC-132A). Ceramic: 27pF +5%, 50FECH, temp coef 0+60ppm (Used in CHC-132A). Ceramic: 22pF +3%, 50FECH, temp coef 0+60ppm. (Used In CHC-132B,C). Ceramic: 1000pF +10%, 30FECH, temp coef +350 -1000ppm. Tantalum: 1uF +20%, 16FECH. Tantalum: 1uF +20%, 16FECH. Tantalum: 1uF +20%, 16FECH. Silicon, feat receivery (2 41edex in serion): sig to Teshiba 195224.
C2104 B19 C2104 B19 C2107 C2107 C2106 B19 C2109 B19 C2109 B19 C2110 B19 C2111 B19 C2111 B19 C2112 B19 C2100 B19 C2100 B19 C2100 B19 C2100 B19 C2100 B19	0/50A800794 0/50A800780 0/50A800780 0/50A800793 0/50A800878 0/50BA80078 0/50BA80078	coef 0-60pps. (Osed In CHE-132A). Ceranic: 35pf e5x, 50vDCW, temp coef 0-60mm (Osed in CHE-132B, C) Tantalum: 1sF e20x, 35vDCW, temp ceef 0-60pps. Ceranic: 100pF e5x, 50vDCW, temp ceef 0-60pps. Ceranic: 27pF e5x, 50vDCW, temp ceef 0-60pps (Gsed in CHE-132A). Ceranic: 22pF e5x, 50vDCW, temp ceef 0-60pps (Gsed in CHE-132A). Ceranic: 22pF e5x, 50vDCW, temp ceef 0-60pps (Gsed in CHE-132A). Ceranic: 100pF e10x, 50vDCW, temp ceef 0-60pps. (Used In CHE-132B,C). Ceranic: 100pF e10x, 50vDCW, temp ceef e330 -1000pps. Tantalum: 0.47pF e20x, 10vDCW. Tantalum: 1sf e20x, 16vDCW. Variable: max 10pF. Silicon, fest recovery (2 41edus in
C2104 B19 C2105 B19 C2107 C2106 B19 C2109 B19 C2109 B19 C2110 B19 C2111 B19 C2112 B19	0/5C3A000982 1/5C3A000780 1/5C3A000876 1/5C3A000869 1/5C3A000869 1/5C3A002249 1/5C3A002249 1/5C3A002249	coef 0400m (Good in CHC-1328, C) Tantalun: 10F 20E, 35VDCW, Cornaic: 100pF 45E, 50VDCW, temp coef 040ppm. Cornaic: 27pF 45E, 50VDCW, temp coef 0440ppm (Good in CHC-132A). Cornaic: 27pF 45E, 50VDCW, temp coef 0440ppm (Good in CHC-132A). Cornaic: 22pF 45E, 50VDCW, temp coef 0440ppm. (Hood Ta CHC-132B,C). Covenic: 1000pF +10E, 50VDCW, temp coef 4330 -1000ppm. Tantalun: 0.47pF +20E, 16VBCW. Variable: max 10pF. S1100ES S111com, fast recovery (2 41edus in
C2205 pli c2107 c2108 min c2109 min c2109 min c2109 min c2110 min c2111 min c2211 min	1/5CAA800780 1/5CAA800676 1/5CAA800679 1/5CAA800649 1/5CAA800678 1/5CBAA02249 1/5CBAA02249 1/5CBAA02249	Coronic: 100pF =5%, 50VDCW, temp coef 0=60ppm. Coronic: 1000pF =10H, 50VDCW, temp coef +350 =1000ppm. Coronic: 27pF +5%, 50VDCW, temp coef 0=60ppm (Uood in CHG-LVZA). Coronic: 22pF +3%, 50VDCW, temp coef 0=60ppm. (Uood To CHG-132b,C). Coronic: 1000pF +10%, 30VDCW, temp coef +350 =1000ppm. Tantalum: 0.47pF +20%, 10VBCW. Variable: max 10pF. BIOSES Silicon, fast recovery (2 41edus in
C2107 C2106 B19 C2109 B19 C2109 B19 C2110 B19 C2111 B19 C2111 B19 C2112 B19 C2112 B19 C2102 B19 C2102 C3003 C3004 B19 C3009 B19 C3009 B19	I/SCIABOO793 I/SCIABOO793 I/SCIABOO679 I/SCIABOO78 I/SCIABOO78 I/SCIABOO145	coef 0:40pps. Cornuic: 1000pr ±10E, SOVECY, temp coef +350 -1000pps. Cornuic: 27pr +SE, SOVECY, temp coef 0:40pps (Good in CGC-132a). Cornuic: 22pr +SE, SOVECY, temp coef 0:40pps (Good in CGC-132a). Covanic: 1000pr +10E, SOVECY, temp coef 0:40pps. Covanic: 1000pr +10E, SOVECY, temp coef +350 -1040pps. Tantaluar 0.47pF +20E, 16VECY. Tantaluar 1pf +20E, 16VECY. Variable: max 10pf. BIOSES Silicon, fast recovery (2 41edus in
C2109 315 C2109 315 C2110 315 C2111 315 C2112 515 C2112 515 c400 315 C2000 315	1/5CAAB00793 N/5CAAB00869 N/5CAAB00876 N/5CBAA02249 N/5CBAA02249 N/5CBAA02249	Corunte: 27pF +5E, 50FECH, temp coef 0+60ppm (Used In CHG-LIZA). Corunte: 22pF +5E, 50FECH, temp coef 0+60ppm. (Used To CHG-1329,C). Corunte: 1000pF +10E, 50FECH, temp coef +350 -1000ppm. Tantaluar 0.47pF +20E, 10FECH. Tantaluar 1upf +20E, 10FECH. Variable: max 10pF. Silicon, fast recovery (2 41edus in
C2109 315 C2110 815 C2111 815 C2112 815 C2211 815 C7202 C9201 815 C9203 815 C9204 815 C9205 815 C9206 815	N/SCAABOOR/S N/SCAABOOR/S N/SCBAAD224S N/SCBAAD2249 N/SCBAAD2249	coef 0440pm (God in CHD-132a). Coranie: 22pF +5E, 50vcCV, temp coef 0440pm. (Used To CHD-132B,C). Covenie: 1080pF +10E, 50vpCV, temp coef +530 -1080pm. Tantalum: 0.47pF +20E, 16VECV. Tantalum: 1mF +20E, 16VECV. Variable: max 10pF. Silicon, feat recovery (2 41edus in
C2110 815 C2111 815 C2112 815 C2112 815 C7201 815 C7202 C8203 815 C8204 815 C8205 815 C8206 815 C8206 815)/3CAAB\$0876)/3CBAA02248)/3CBAA02249)/3CTAB00145	COST D-600pm. (Nood To CNG-1328,C). Covenie: 1000pF +10X, 90VPCM, temp cosf +350 -1000pm. Tantaluar 0.47pF +20X, 10VPCM. Tantaluar 1uf +20X, 10VPCM. Variable: max 10pF. Silicon, fost recovery (2 41edus 10
C2111 915 C2112 815 C7201 815 C7202	//SCEAM02248 //SCEAM02249 //SCEAM00145	Tentalus: 8.47pF +20%, 16FECH. Tentalus: 1sF +20%, 16FECH. Variable: eax 10pF. BIOSES Silicon, feat receivery (2 diedes in
C22112 815 C7201 815 and C7202 C8203 815 C8204 815 C8205 815 C8206 815 C8206 815	//SCEAMOZZA9 //SCEAMOO145	Tantalum: 1pf +20%, 1600CU. Variable: eax 10pf. BIOSS Silicon, feat recovery (2 diedes to
C9201 819 C9202 819 C9202 819 C9204 819 C9204 819 C9204 819 C9204 819	1/5CTAN0014S	Furtable: max 10pF. BIOSS Silicon, fast receivery (2 diedus in
CH261 B19 CH264 B19 CH264 B19 CH265 B19 CH266 B19 CH2669 B19 SH4		Silicon, fast receivery (2 diedus in
ca204 815 Ca204 815 Ca205 815 thru Ca206 815	/ 313410032 0	Silicen, fast requesty (2 41edes in
Ciddo Big thru Ciddo Ciddo Big		
CROSS BLS	/31XAM0356	Silices, feet recovery (2 diedes with made retine): els to Tookibe 188182.
	V-72XA4001.70	Silicum, Variable Capacitance Plotus wim to Hitmoid 18768.
C94710	/503M004230	Silican, fast recovery (aritching): sie to Hitachi LELIO.
com no	/500m40324	Siliem (Schottley Barrier): als to MC 15957.
cm212 st4 thre cm216	/7mm/0120	Siliem, Briable Constitues Medes on to Ritarit 1996.
CHECK B115	PSTOCHHOLS)	Silican, fast recovery (artiching); sin to Hitachi 138116.
GG 1	/300mm326	Slifeon (Schotthy Burrier): win to
COEDS 11.0	/ 2010/16/2 3)	Silion, fort recovery (artiching): sin to bitseld 19816.
G005 125	/30mmin;79	Silicon, Byrishin Capacitance Makes sin to Mineld 1976. (Seed to CO-LTA)

\$1100	E GE PART NO.	DESCRIPTION		
CD22	7 B39/STXAB00320	Silicon, fast recovery (2 diodes in series): eis to Toshiba 188226,		
1		FILTUS		
71.20	1 B19/3HLAT00051			
P1.20	1 819/5WLAT00050			
FL20	1 819/SWIATOO014	RF filter BFF 384-430MHz		
FL20	819/3WLAT00051	(Used in CHG-132C). RP filter SPF 320-35898s		
FL202	219/5KLAT00050			
FL202	819/3NLAT00014	(Used in CHC-132B). RF filter RFF 384-430HRg		
		(Used in CMC-1J2C).		
[C20]	B19/50AAJ00328			
10207		Synthesizer: CHOS serial input. Prescater: sim to Pufftum NRSOLP.		
IC203		Duel Comparator: atm to MJRC NJR29030.		
IC204	319/SBAAJ00359	Digital, Bilateral switch: sim to Notorola HC14066,		
ntid IC205		Notorola NC14066,		
IC\$06	B19/SDAAR00021	Positive Voltage Regulator: sim to Hartenshita AMSAL.		
		JACTS		
J201 thru J204	B19/5ZJTL00001	Crystal Socket.		
J205	819/5JVM500173	Connector, 20 pins.		
J 204	819/5/NCL00045	Connector, MF.		
J207 J206	B19/5.7W9900174			
J206	\$137.33E\$3KC174	Connector, 6 pine.		
		coits		
L201 L202	B19/5LAAC00052	Coli, Ry.		
		Choke coil: 0.68 uE ±10% (Used in CMC-132A),		
1.202	B19/3LCAB00012	Choke ceil: lull +10%. (Used in CMC-1378).		
1.203	819/SLCAC00174	Chake coll: 0.47 mH ±10% (Used in CHC-132C),		
L203	B19/SLCAC00174	Clocks coils 0.66 pH +16X (Qued in CHE-132A).		
L203	B19/SLCAB00012	Chake cut1: 1 at +10% (Seed to CMS-132s).		
L203	#19/SLCAC00176	Choice coil: 0.47 µH ±18% (Good in CHG-132C).		
	1			
	-			
	ľ			

SYMBOL	GE PART NO.	DESCRIPTION
L204 and L205	B19/5LCAC00174	Choke coll: 0.6848 +181
L206 ead L207	B19/SLCM000134	Choke coil: 1.5d8 *10% (Based in CMC-132A, 3).
L204 and L207	B19/5LCAC00174	Choke coll: 0.60mm alox (Good to CMG-132C).
1,208	319/5LAAC00065	Coll, RF (Doed In CHG-132A).
1.208	819/SLAAC00047	Coll, RF (Good in CMG-1328, C).
L209	B19/SLCA000156	Choke coil: 1.5em +10%. Coast in CHG-132A, B).
1.209	819/SLCAC00173	Choke coil: laff +10%. (Seed in CHC-132C).
L210	819/5LCAB00012	Choke coil: luff +10%
L211	B19/SLAAC00051	Cotl. RF.
1212	B19/SLAAC00052	Coll, RF (Uncel 1st CMG-132A, 2),
1212	B19/5LAAC00050	Coll, RF (Seed in CMC-132C),
L213	B19/SLAAC00052	Gest, mr.
LŽIA	\$19/5LCAB00176	Choke coil: 0.47mH =10%. (Used in CHG-13ZA)
1.214	B19/SLCAB00012	Cheke coll: tul +10% (Deed in CHG-1328)
L214	B19/52/Ch/000247	Choke coil: 0.33uH ±100 (Deed in CMC-L32C)
L215	919/SLCAC00176	Choke coil: 0.47µB ±10% (Beed in CHG-13ZA)
1213	B19/3ECAB00012	Choke cell: Lul +18% (Need to CMC-1328)
นาง	B19/SLCAC00247	Cheke ceil: 0.33pH ±16% (Beed in CHE-LERC)
Line	B19/SLCAC80176	Chake coil: 0.4748 +101 (Bood in CHG-1.32A, C)
*214	B19/3LCAC00174	Cheke cet1: 0.60uH ±10% (Wood in CHS-132C).
un7	B19/SLCac00176	Chake cost: 0.47ml A10E (Bood in CHS-13ZA, CT,
Ln?	B19/5LCAC00174	Cheke coil: 0.50at -10% (Dood to CMS-1328).
LPIS	819/SLCA000176	Chaine cotl: 0.60ml =10E Chood im CHG-132b, b)
C21#	819/3LCAC00176	Claims coil 0.47uH oldE Claud to COC-138C).
LITS	819/3LCac90174	Chalce cot1 5.48aH =16K (Bood in CHG-13Ma, B).
un•		Chile cett 8.47st =16% Cloud in CHS-132C).
		Cell, OF (Wood to CHO-LINA).
- 1		Coll, 87 (Seed to CHG-1328).
1210	819/FLANCH0063	Coll, RF Client in CHG-13803.
- 1		

STHEOL.	GE PART NO.	BRECK EPTS COM
133:	\$19/3LCAC00173	Chake cail: 1.8 all +182 (Wood in CHO-132a, N).
133 31	812/2FCHC00120	Cheke cotiz 1.5 of ±10% (Wood in CHG-LIEC).
1.322	BLSV SECAMOROLI	Chuke codi: las ±10%,
1.223	B19/3LAAC86851	Coil, W.
L224	B15/3E/DE00136	Chake coll: h.5uf +162. (Send in CHO-132a, E).
L224	119/R01090174	Choke call: 5.66pH +16R (Yead in CHO-133C).
LZZS	819/3LCaC80174	Chuke unil: 0.48aH +18E. (Seed in CHC-132A, p)
L225	109/SLGA000126	Chain coil 8.47 at +165 (Seed in COS-133C)
L224	H19/3LAACH00\$2	60, W.
R2071	H25/9804000574	Nical film: 16K abox 55k, 16690cm, 1/6s.
N/ANN	113/70mc00519	Named Pillar 22 when ±50, 2000pcsr, 1760.
1200	#C003mm#CV234	Secal files 230 chan -25, 2000pcs, 1/8s.
	825/7886000576	Noted files 10K etc. 15K, 100mcs, 178c.
135	M WHENDROOMS	Noted 23304 A.7K elen <u>-</u> 7K, 200400K, 1/86.
1007	(ISV Status (PALIS	Hetali Exisc 22 etus <u>e</u> 91., 3000cm, 1/80.
1209	129/34acm313	Simil Other O'R aim off, 1889aca, 1880.
1216	101/74mcH1786	Viscal Piller 13K oben 25K, 2000pcs, 178c.
1211	11,5/70mm100577	Microb Ciliar - 6.8K atom ySt., 2000;CD., 1/8K.
4313	165/700mp005/5	Signal Philos Like ober 1981, mensena 1982.
ndx3	149/7 1111/1111/11	March Piller 100 atom (SR, 2000ch, 1986)
2234	-	Middle Miles 339 olds gill, 300000, 1986.
121.5	-	Marie Cities and even you, security,
12D.7	162/2000D1	Named Attorn Sall often you, Millery,
uinë	-	Noted Color 330 stem o'SC, 2009001, 1/80. (Dank to Oth-Cife.)
eler#	MATERIAL PROPERTY.	ment Clin SH day (St., 1984).
	-	Stand Other 136 along St., Miller, 1886.
- 1		Stelet filler. L.S. etc. 481, 200424,

STITUL	CE PART NO.	MENCKEPYZON
H222	MAJMPONENT	Noted files 230K oles 45K, 30078CH, 1/8s.
R223	15V300c00392	Noted file: 33K class +5K, 20079CF, 178F.
R234	129/303ac00594	Notal film: 15% ohno +5%, 2000pcm, 1/8r. (Good to CH2-13%A).
R234	115/300000573	Mercal filter 4,7% elem +5%, 20049CF, 1/8F. (Good to CH2-1325).
B224	H29/3000000576	Motal films 16K olum +5K, 2007pCF, 1/6F. (Seed in CHS-12Et).
B225	(1,9/7mgsq1454)	Single (Viles MIX when +5%, 2007QCH, 1/80.
2224	\$19/3mgap88574	Single filter 1.72 shanges, 160mgcr, 1/80,
B227	\$19/7mmoF690)	Botal filter 250 stan 550, moreon, LPBN.
U226	MY2000000	Notes: (1734) 1892 older -52, 2004;ES.
1270	le:Vingelitik	Sheaf Pilms 16E when ySt., 18049034, 1/8r.
B231	NeV3mandMS72	Noted filled H. shan SE., Marrier., 1980.
1232	NeW/Insuphisis	Noted filter lift sheet office annual, lifts.
E230	229/20pa00572	Noted Other M shee M., seconds, 1880.
2274	NPV/IngupleS/G	Michael Pitches Mill whom - 500, provinces, 1/80.
R225	Name and Persons	NAME AND THE PERSON, ASSESSED,
H236	teWhyadt572	Nicol Files & sheet oft, 2000cr.
1274	New Yorks (New York)	State Clark III olan 1984, Mersen, 1886.
6239	NeWholastic	Frank Filips 3.4t along \$10, 3000pcs, 1780.
1946	NEW/20060005	Name (NSac 1.25 one off, Miller, 1986)
2	309/30aur00043	Name 150 about 250, personal, 1/50,
EMB		Steel Piller. 30 other 1971, 201923.
1914	#*************************************	Mand (150s 120 etc. 250, 2000).
4345	-	Marie Cine 2.5t and 3t, 200pm,
1000	-	100 Miles 18 July 18, 1990.
-	1579	100 Mar 20 au 50, 3000.

STREEOL	GE PART NO.	DESCRIPTION
#248 and #249	819/58EAG00575	Heta1 fflm: 2,2% ohma ±5%, 200070%, 1/8%,
#250 ##6 #251	819/SREAG00594	Metal film: 220 ohme ±5%, 200VDCF, 1/BW.
R252	B19/5REAG00620	Hetal file: 33 obma ±5%, 200 VBCW, 1/8w.
R253	B19/SREAG00594	Metal file: 220 ohes ±51, 200VBCN, 1/8w.
R254	#19/5RZAG005#1	Metal film: 22% ohms ±5%, 2009DCH, 1/8W.
R253	B19/SREAC00376	Mrcal film: 10K ohou ±5%, 200VDCH, 1/8H.
1,260	819/ SREAG00596	Metal film: 15K ohns ±5%, 200VDCW, 1/8W.
R262	B19/ SR.RAC00621	Hetal film: 68 ohma ±5%, 200VDCW, 1/8w.
R243	B19/ SREAG00625	Hetal film: 5.6K ohme +5t, 200VDCN, 1/8W.
R264	819/SRZAG00574	Netel fils: 1.5K ohms ±5%, 200VDCM, 1/6W.
R265	819/5REAG00583	Netal film: 150 ohms ±5%, 200VBCW, 1/8W.
3.266	819/5REAG00792	Hetal film: 82 ohms ±5%, 200VDCW, 1/8M.
R 267	B19/5REAC00586	Met#) (flm: 100 ohus ±5%, 200VDCM, L/BM.
R260	B19/5REAG00792	Metal film: 82 ohmu ±5%, 200VDCW, 1/8W.
1274	B19/50ZAG00591	Metel file: 680 ohms ±5%, 200VDCW, 1/8W.
2275	B19/5RZAG00581	Hetal film: 22K obse +5%, 200VDCW, 1/8W. (Used to CHO-13ZA, B)
R275	B19/SREAG00576	Setal film: 10K ohms +5K, 200VDCW, 1/8W. (Used in CMO-132C)
R276	B19/5REAG00576	Metal film: 10K obss +5%, 200VDCW, i/8W. (Used to CMG-13ZA)
R276	B19/58.EAC00577	Hetal film: 6.8K ohmm +5%, 200VDCW, 1/8W. (Used to CMC-132%). Hetal film: 4.7K ohmm +5%, 200VDCW.
A277	B19/5REAG00372	1/8W. (Used in CHC-132E)
R276	B19/3REAG00596	1/84.
	as or smallered 270	Hetal film: ISK ohms
£279	B19/5REAC00578	Metal film: 47% ohma +5%, 200VDCW, 1/8W,
R280	B19/5REAG00573	Setal Etlm: 4.7K ohma ±5%, 200VDCV, 1/8W.
1283	B19/5RZAG00597	Metal film: 330 ohma ±5%, 200VDCW, 1/8W,
1		

STOROL	CE PART NO.	RESCRIPTION
R205 and R206	319/5REACOUS72	Metal film: IX ohms e5%, 200VpChr, 1/8r.
B267	319/5REAG00619	Metal film: 22 ohmo +5%, 200VECM, U-8W.
R288 and R289	B19/SREAG00574	Metal film: 1GK ohms ±5%, 2009BCW, 1/8W.
R293	B19/5REAG00586	Hetal fflm: 100 ohms ±5%, 20095CW, 1/8W,
R294	819/SREAG00618	Notal Ellm: 15 ohns ±5%, 2007DCW, 1/8W,
3.2%	B19/SREAG00381	Metal [film: 22K ohmm +5%, 200VDCM, 1/8m, (Used in CMC-132A)
12%	B19/SREAC00592	Hetal film: 33 K ohma ±51, 200VDCW, 1/8W, (Owed in CMC-132B).
R296	819/SRZAG00596	Netal film: 15K ohma ±5E, 2DOVDCV, 1/Bu, (Umed in CHG-132C).
R297	819/5REAG00597	Hetal film: 330 ohmo ±5%, 200VDCW, 1/8W.
1.298	B19/5RDAA01179	Carbon film: 47 ohms +51, 300VDCW, 1/4W. (Used in CMG-)3ZA).
A2100	B19/5RDAA01179	Carbon film: 47 shme +5%, 3009DCW, 1/4W. (Used in CMG-13ZA).
R2102	B19/5REAC00594	Metal film: 220 ohma ±5%, 200VDCW, 1/8W.
RV201 and RV202	B19/5RVAB00279	Variable: 10K ohma ±30%, 0,1w,
		TRANSISTORS
TR201 and TR202	B19/5TBAB00055	Silicon, PNP: aim to MEC 253624.
TRZ03 and TRZ04	B) 9/5TBAB00054	Silicos, NPF: sim to MEC 250596,
TR205	B19/5TBAB00055	Silicon, PMP: alm to NEC 253624.
TR206 and TR207	\$19/5TCAG00047	Silicom, MPW: mim to Mataumhita 2803110.
TR208 and YR209	819/5TCAZ00011	Silicon, NPM: #[# to Sanyo 25C3398.
TA210	B19/5TKAH00002	M-channel, field effect. (Junction Single Gate): sim to Sony 25K125.
TR211	B19/5TCAG00047	Silicon, NPN: sim to Matsushita 25C3)10.
TR2L2 and TR2L3	B19/3TCAZ00011	Silicon, NFN: aim to Sanyo 25C3398,
TR214 and TR215	B29/5TCAG00047	Silicon, MPN: sim to Mataushita 28C3110,

SYNGOL	GE PART NO.	DESCRIPTION
TRZIÓ thru TRZI9	B19/STCA200011	Silicon, MPM: mim to Samyo 25C339S.
TR220	B19/5TKAN00002	N-channel, [is]& effect (Junction Single Gate): aim to Sony 28K125.
TR221	819/5TCAG00047	Silicon, APH: sim to Matauchita 28C31t0.
TR222	B19/5TCAZ00011	Silicon, NPM: sim to Sanyo 25C3398.
TR724	B19/5T0AB00054	Silicon, KPK: alm to MEC 250596.
TR227 Lhru TR230	819/5TCA200011	Silicon, MPM: sim to Sanyo 2SC3)98.
		CRYSTALS
XU201	819/6XXF000012	Reference Oscillator unit. (Standard Sppm U)
¥0781	919/6XMFD00010	Reference Osciliator unit. (Option Zppm U/800)
	819/CHA-239A 819/CHA-239B 819/CHA-239C 819/CHA-239E 819/CHA-239E 819/CHA-239G 819/CHA-239G 819/CHA-239H	BECEIVER BOARD
		CAPACITORS
CADI	\$19/5CAAB00797	Commic: 470pF ±51, 50VDCM, temp comf ±101.
C402	B19/5CAA000796	Ceramic: 3pF =0.25pF, 50VDCM, temp coef 0=60ppm.
C403	B19/5CAAD00929	Ceramic: 68pf +51, SOVDCW, remp conf 0+60ppm.
C404 Ehru C407	\$19/5GAAD00789	Ceramic: 0.01uF -101, 50VDCW, cemp- coef -101.
C408	\$29/5CEAA01816	Blectrolytic: 47uF ±201, 25VPOF.
£409	B19/3CAAD00789	Ceramic: 0.01uF ±10%, 50VDCW, comp coef ±10%,
C+10	#19/3GAAD0080L	Coramic: 4pf +9.25pf, 30VOCM, temp coef 8+60ppm.
CALT	819/3CAAD00794	Ceramic. 33pF ±5%, 50VDCW, cemp coef 0±60ppm.
CA1Z thru CA14	819/5CAAD00789	Ceramic: 0.01uF -101, 50VDCW, temp- coef -101.
C415	E19/5CAAD00801	Ceremic: 4pF =0.25pF, SOVDCM, temp- coef 0=60ppm.
C416	819/SCAAD00794	Ceramic: 33pF -5%, 50VDCV, temp coef 0-60ppm.
C417 thru C420	B19/5CAAD00789	Ceramic: 0.01uF ±101, 50Y0CF, temp- coef ±101,
C421	819/5CEAA01816	Electrolytic: 47oF ±201, 75Vocw.
C422	819/3CEAAD00803	Ceramic. Apr 40.75pF, 50VDCW, temp coef 0460ppm.
C501	B19/5CAAD00769	Cermic: 0.010F =10%, 50VDCM, temp coef =10%.

SYMBOL	GE PART NO.	DESCRIPTION
C503 and C504	119/SCAAD00789	Ceramic: 0.01uF -101, 50VDCM, temp
C505	819/5CAA000798	Geranic: 2pF =0.25pF, 50VBCM, temp coef 0=60ppm.
C506	B L9/SCAADOGGO	Ceramic: 4pF =0.75pr, 5070cM comp coef 0=60ppm.
¢307	819/3CAAD00977	Coranic: 7pf ±0.5pf, 1970CV, temp coef 0±60ppm.
C508	B19/SCAADOOGOO	Ceramic: 5pF =0.25pF, 50VDOr, temp coef 0=60ppm.
C\$09	EL9/5CAAD00878	Ceramic: 1000pF +10T, SOVDCW, twop- coef +350 -1000ppm.
C510 and C511	19/3CAAD00401	Geramic: 4pf =0.25pF, SOVDGW, temp coef 0=60ppm.
6512	819/3CAADOON78	Ceramic: 1000pf +101, 50VDCF, temp coef +350 -1000 pps.
C313	#19/5CAAD00787	Ceramic: 15pf ±51, 50VDCH, temp coef 0+60ppm.
C514	\$19/5CEACO0946	Tantalum: 0.72uF -20X, 3590CW.
CSIS	\$19/3CAAD00878	Geramic: 1000pF ±10%, 50VDCF, temp- coef +350 -1000 ppm.
C316	819/3CSAC00988	Tentalum: 0,72uF ±201, 15VpCw.
C517 end C518	B19/3CAAD00878	Geranic: 1000pF +102, 50VDCM, temp coef +350 -1000 pps.
C519	\$19/5CEAA01#16	Blectrolytic: 47uF ±20%, 25vpcw.
¢\$70	\$19/5CAAD00789	Ceramic: 0.01uF -t0t, 50VBCV, temp- coef -101.
C321	B19/5CAAD00678	Geramic: 000pF ± 101, SOVECH, compcor + 350 ~1000ppm.
C522	B19/5C8AC00982	Tentalum: 1uF +20%, 35VDOF,
C323 and C324	\$19/3CAAD0/378	Ceramic: 1000pF 410%, 50VDCH, temp coef +350 -1000 ppm.
C\$25	\$19/3C\$AC00930	Tentalum: LOur +201, 25VBCW.
C526	819/3CAAD00844	Cramic: 47pF +5%, 50VDCH, remp coef 0+60ppm.
C527 and C578	819/3C\$AC01068	Tentalum. 0, jur -101, 35VDCM.
C530	B1973CAADOU678	Geranic: 1000pF -10%, 50VDCW, temp- coef +350 -1000 ppm.
CSJL	819/5CEAA01816	Electrolytics 47uP -201, 25VbCu.
C537 and C533	819/5CAADQ0878	Ceramic: 1000pV =101, 50VDCV, temp coef +350 -1000 ppm.
C534	819/3CKAA01816	Electrolytic: 4747 +101, 15Vocv.
C535	B19/3CEAAGO789	Ceramid: 0.01 F -103, 50VDOF, temp coef -108.
		1

51	DEOL	CIL	PART	ж.	PESCR177108
Г					70.004
'	1401	B19/34	MATO0	034	RF filter: BFF 603-42396s (Used in CHA-239A).
"	1401	B19/50	CATOO	035	RF filters RPF 410-430sHz (Used in CMA-2398);
r	1401	BL9/58	LATOO	937	RF filter: BPF 420-440mmz (Used in CKA-239C).
n	401	819/50	LATOO(149	RF (11ter: 3FF 440-460NMz (Used in OM-239D).
r	A01	B19/3#	LATOOC		RF filter: RPF 450-470Mtz (Umed in CMA-239E),
n.	401	019/5#C	LATO00		RF filter: BPF 470-48886tm (Used in CMA-239F).
n.	401	BL9/SMT	AT000		RF filter: BFF 482-500991x (Used in CNA-2390).
n	104	919/5WZ	AT000)		RF filter: 3PF 488-512MHz (Osed in CMS-239H),
PLA	-02	B19/5mi	BEO000		EF filter: MPF 403-423eHz Used In CMA-239A).
PLA	1	19/5WL		1	U ftlter: \$PF 410-430992 Uned in CMA-23983,
n.	02 1	119/5R12	ATO O O 3	8 (Ffilter: BPF 420-440Mfz Used in CMA-239C),
TLA	02	19/5KL	170004		Filter: NPF 440-460mHz Used in CMA-239D).
PLA		19/5NLA	10003		f filter: BPF 450-470Mig Deed in CMA-239E),
PL40	2 0	19/5#LA	10004		Filter: SPF 670-488881z Jack in CNA-239F),
PL40	2 8	9/SHLA	100044		filter: BPF 482-500eNz deed in CNA-239G),
71.40		19/ SHLA		(n	filter: BPF 488-5129Hz med in CMA-239K),
		9/3WLA1		(0	filter: BPF 603-623MHz med im CMA-239A),
PLA 0.3	3 81	9/SKLAT	00033	K.F (U	filter: SPF 410-43000tz sed in CMA-2398),
TLA 0.3	31	9/SKLAT	00037	₹.F (U.	filter: BPF 420-440MHz and is CNA-239C).
1403		9/3WLAT	00049	(B	filter: BPF 440-460mHz and in CMA-239D).
LA03	B19	/SWLAT	00039	Ř7 (0∎	filter: BFF 450-470MHz ed 1m CNA-239E),
		/SWLATO		RF (Oa	filter: BPF 470-488Miz ed in CMA-239F),
403	\$19	/ SMLATO	0043	RF : (Ve	filter: RFF 482-500MKm ed in CMA-239C).
		/XLATO		RF (filter: \$PF 486-5)2Mix ed in CMA-239(),
404	819/	SDHARO	0007	RF (11ter: RPF 320-358MHz d im CMA-239A, B and C).
404	819/	SNLATO(RF (11ter: 8PP 357-388681z d in CNA-239D and E).
			1		

572	OOL	GE PART IN).	DESCRIPTION
n	A04	B19/30LAT000	M3	
n	501	B19/5XMAA000	10 1	1
PL	502	319/5XHAA008		7,000
n	503	319/5HRAADQ0	*	1
PL	504	319/SWAA000	41	
1	- 1			
яся		\$19/30HAT000		Friends Circuits
HC3	- 1	\$19/60H200014		Double Balanced Mixer,
~~	~	#17/ BUILDOO/18	-	Dimear, 2'nd Mixer: alm to JRC DRD0186.
	-1			
ıcs	اره	\$19/500AS0007	ا ،	ENTECRATED CIRCUITS
				Linear, IF Amplifier & Detector: sim to Motorola MC3359P.
103	02	319/5DAAR0002	1	Linear, Positive foliage Regulators six to Matsushita AMSSA1.
1	1		1	TO MERCHANICA AND MI.
			1	CONNECTORS
J401 and		19/5JMCL0004:	5	Connector, RF.
J402	1			
J301				Connector, 10pins.
1502	1	119/3./WCL00047	1	Connector, RP.
1				corks
L402	1	19/6LAF001135	1	Co11, RF.
1403		19/61AFD01156	6	Coll, RF,
£404		19/6 LAFD 01135	0	Co11, T.
1,405		19/6 LAPD 01156	c	Coil, RF.
L406	b	19/6LAFD01135	c	Co11, RF.
£50)		19/3LCAC00391	C	Theke coil: 0.1µH ±10%,
1.502	1	19/3LCAC00160	0	Thoke coil: 3.3uM +10%,
1.504	1	9/6LAFD01318		Thoke coil: 3.3µM ±101, coil, N.F.
L305	1	9/6LAD000553	1	oci, ar.
L508				
L509	81	9/6LADD00554	Co	o1), MF.
L510	83	9/3LCAC00165		hoke roll: 0.22µP +20%,
LSII	1	9/6LAF000877		
		İ		
R401		9/5RDAC02154	_	RESISTORS —
K+01	"	77 JRDAU02134	1/	stal film: 5.6K ohmu ±5X, 200VDCW, (BW.
R402	819	7/5RDAC02132		etal film: IK ohma ±SE, 200VDCV.
R403	B) 9	/5RDAC02140		
	.,			tal film: 330 ohea +5%, 200VDCW, EV.
- 1				
- 1				

STHEOL	CE PART NO.	L		DESIGNI PYTON
R404	\$19/5R0aC02141	Notal 1/80.	film	10 ohma +5%, 2009BCW,
E403	319/58DAC02137	Notal 1/86.	file:	100 ohms ±5%, 2007BCV,
R407	B19/50DAC02300	Netal	film	O ohem
R409	B19/SRDAC02140	Netal 1/8/	film	330 ohus ±51, 2009/DCF,
R410	\$15/50DAC02144	Hetal L/Br.	film	18 obms ±5%, 2009DCM,
R417	B19/582MC02140	Hetal 1/84.	film	330 ohma <u>+</u> 5%, 2004DCM,
R412	819/3RADAC02154	Hetal L/Br.	films	5.6K ohma <u>+</u> 5%, 200VDCW,
EALJ	B19/5RABAC02132	Hetal 1/84.	ftlms	1X olum <u>+</u> 5%, 200VDCV,
R414	B19/5RDAC02153	Hetal 1/84.	ftimi	470 ohma ±5%, 200VBCM,
E415	B19/SEADAC02141	Netal 1/84.	ftlai	10 okme <u>+</u> 5%, 200VBCW,
R416	819/5RADAC02137	Hetal L/Se.	f(lm:	100 ohms <u>+</u> 5%, 200VBCF
R417	819/582AC02140	Hetal 1/84.	filmi	330 ohma <u>+</u> 5%, 2009/DCM,
R418	B19/5RDAC02146	Hetal 1/04.	filmi	16 ohmo <u>+</u> 5%, 200VDCV,
R419	819/3RDAC02140	Hetal 1/84.	film:	330 ohma ±5%, 2009BCW,
E420	819/5RDAC02154	Notel 1/6M.	ftlmi	5.6K ohma <u>+</u> 5%, 2007DCV,
E421	919/SRD6C02132	Netal L/#W.	film	1X ohms ±5%, 200VBCW,
R422	119/5RDAC02133	Metal 1/8/.	filer	470 ołma ±5%, 200VBCW,
E423	319/5RDAC02141	Hetal 1/W/.	film	10 ekms +51, 200VECW,
R424	#19/SKBAC02137	Metal 1/84.	ftlar	100 ohmu ±51, 200VDCH,
8425	919/SRBAC02257	Hetal 1/80.	film	470 ohma <u>+</u> 51, 2004/DCM,
R426	819/SRBAC02141	Hetal 1/8W.	film	10 ohme ±5%, 200VDCW,
R427	119/5RDAC02257	Metal 1/84.	film	470 ohmo <u>+</u> 5%, 200YDCH,
R429 and R435	B19/5RDAC02380	Metal	fils:	0 ohma
£50t	B19/5RDAC02135	Hetal 1/04.	filmı	150 ohma ±5%, 200VDCW.
IL502	B19/5RDAC02120	Metal 1/80.	filet	2.7% ohma <u>+</u> 5%, 2009/00/v.
E304	B19/3RDAC02156	Metal 1/8W.	filor	8.2% ohms <u>+</u> 5%, 200VDCW,

		The same of
STREET.	GE PART NO.	DESCRIPTION
1.505	319/50pac02129	Hetel filmt 150% shap 25%, 200vacu, 1/80;
R504	B19/5RBAC02127	Here's Films 40 elem #St, 2007504, 1/84,
8507 and 8508	B19/5RADAC02150	News Filter 8.2K ohma ±5%, 20079CH, L/DM.
R509	B19/5RBAC02124	Metal film: 2,2% ohms ±5%, 20090CM, 1/86;
R510	B19/5R0AC02133	Hetel film: 1.5K ohms +5K, 200FECH, 1/6W.
R511	B19/5RBAC02124	Hetel film: 2.2K obse ±51, 2009DCV, 1/8W.
R512	B19/5RBAC02125	Netel film: 10% obme +5%, 2007ECF, 1/8%.
R513	819/5RDAC02159	Hetal film: 220 ohme ±5%, 2009DCW, L/BM.
R514	B19/SEBAC02147	Metal film: 3.3K ohmo ±5%, 200FDCN, 1/6W.
R515	319/5RBAC02152	Hetal film: 4,7% ohms ±5%, 200*PCW, 1/8W.
2516	319/5RDAC02153	Hetal film: 470 okes +5%, 200VDCW, 1/8M.
R517	319/5RDAC02134	Hetal film: 47% ohme ±5%, 200¥pCW, 1/8M.
R518 and R519	919/5RDAC02152	Hetel f(lm) #.7K obss +5%, 200VDCM, 1/8M.
R520	919/5R0AC02159	Notal film: 220 obms +5t, 2009pcw, 1/8W.
R\$21	\$19/5RDAC02137	Metal film: 100 ohms +5T, 20079CW, 1/8W.
RV501	a)9/3KVAB00275	Variable: max 2% ohms.
		TRANSISTORS
TR401 thru TR403	B19/5TCAB00287	Silicon, MPN: sim to MEC 2903357
TR.501 and TR.502	819/3TRAG00007	M-channel, field effect: sim to Silicon 9310.
TR.503	B19/57CAB0023B	Silicon, MPM: wim to MEG 29C2223,
TR304	B19/5TDAB00054	\$115com, MPM: wim to MBC 230596.
		CRYSTAL
X50)	819/5XNAA00002	Quarta crystal: 82,6550Mg
ı		CRYSTAL SOCKETS
XS501- A and X9501-	B19/32/DP000 ³⁰ 1	Erystal Socket,
1		
ļ		
		Ī

Emilo:	GE PART NO.	DESCRIPTION
	819/CHC343C	SYSTEM CONTROL BOARD
		CAPACITORS
CeOL	B19/5CAAB01737	Cermic: 0.1 oF =10%, 2VBOW, temp coef =15%.
C402	B19/508A000939	Tentalum: 22 uF -201, 1640CW.
C603	819/5CRAM00585	Polyester: 1000pF =52, 5000CV.
C404	B19/5CSAC01069	Tentalum: 2,7eF ±201, 35VDOW.
C605	B19/5CAAD01237	Germanic - O. LuF -101, 25VDCM, temp- coet -151.
ceds and ceo?	819/5CEAA01627	Electrolytic: 100 of 201, 16VDCw.
C608	B19/5CEAA01987	Electrolytic: 47 ur - 102, (4VDCW.
0609 and C610	B19/5GEAA01827	Electrolytic: 100 of -201, 16VDCM.
C611	819/3CAADO1237	Geramic: 0.1 uF +102, 25V0CM, temp- coef +15%.
cell and Cell	B19/5CRAADO576	Folyester: O.l of _51, SOVDOW.
6413	B19/5C\$AC01065	Tantalum: 0.47 uF 420%, 35VDOM.
C616	S14/3CAAD00797	Ceramic: 47pF ±5%, SOVECH, temp coef 0=60ppm.
C617	\$19/5CBAA00597	Polyester: 0.068 oF _5%, 50VDCW.
C624	819/5CSAC00987	Tentalum: LoF -202,)5VDOV.
C625	819/5CSAC00939	Tentalum: 22 uf -20%, L6VBCM.
C626 and C627	819/3CAAD01237	Ceramic: 0.1 uF ±102, 25VDCM, cemp coef ±152.
C633	B19/5CSAC00912	Tantalus: 10 oF ±20%, 35VDCV.
C634	B19/5CEAA01816	Electrolytic: 47 uF _201, 25VDOW.
c635 med c636	B19/5CAAD01237	Deramic: 0.t uF ±10%, 25VDCW, temp- coef ±15%.
C637	B19/SCEAAOISI6	Electrolytic 47 of 270%, 25VOCW.
C640	B19/3CAAD01237	Geramic: 0.1 uF +102, 25VDCW, temp
		coef <u>*</u> 15%.
C641	B19/SCEAADIB16	Electrolytic: 47 uF ±20%, 25VDCM.
C943	\$19/5CAAD01737	Cormaic: 0.1 oF -101, 25VDCW, temp coef -151.
C+44	B19/3CBAC00939	Tentalum: 22 oF • 201, 16VDCH.
Cb45	B19/5CEAA01982	Electrolyt(c: 47 mf 270%, 16990m.
CAA6	7.	Cormic: 0.0) of -10%, 50VDCN, temp coef -10%.
C647	119/5CEAA01182	Himserralytic: 47 oF -70%, 16VDCW.

SYNCHOL	CE PART HO.	DESCRIPTION
C649	B19/55CRAA00417	Polyester: 0.1 mF -52, 50FDCW.
C650	B19/5CEAC00912	Tantalum: 10 uF ±20%, 3599CW.
C651	B19/SCAAD00789	Ceramic: 0.0) oF ±10%, SOVDCM, tomp
0652	\$19/5CRAA00585	Polyester: 1000pF ±SE, 50VBCV.
C653 mod C454	319/5CSAC00919	Tantelum: 22 wF 201, teVDOV.
C655	B19/5CRAA00576	Polyester: 0.1 uF _SZ, 50VDCM.
C456	B19/5CAAD00789	Ceramic: 0.01 oF -102, 30VDCN, temp coef -102.
C657	819/3CAAD01237	Oeramic: 0.1 of ±10%, 259000, temp. coef ±15%.
C658	B19/5CAAD01237	Geranic: O.t of -10%, 25VOCM, temp
		coe! -15%.
C701	819/5CEAC00982	Tentalum: uF ±20%, 35VDCM.
C702 and C703	319/3CAAD00878	Ceramic: 1000pF +101, 50VMCW, comp- conf +350 -1000ppm.
C704	819/3CAAD00789	Geamic: 0.01 of ±10%, 50VDCW, temp.
C705	\$19/5CAA000878	Cermic: 1000pF ±102, 30VDCW, temp coef +350 ~1000ppm.
C706	B19/5CRAA00597	Polyester: 0.068 aF =53, 50VDCW.
C707	#19/5CEAA01320	Electrolytic. 220 uF .201, 2549CM.
C708	819/3CAAD0078)	Ceramic: 4700pF ±10%, 50VDCW, temp. coef ±10%.
C707	#19/5CRAA00597	Polyester: 0,068 uF ±5%, 50VDCW.
¢110	819/5CAADG0785	Cermic: 10pF ±5%, 50VDCV, cemp coef 0±60ppm.
C711	819/3CAAD00787	Coramic: 15pF _5X, SOVDCM, temp coef 0=60ppm.
C712	B19/5GAAD01204	Ceramic: 0.047 uF _LOZ, 25VDOW, tem coef _15%.
C711	#19/3CSAC01063	Tentalum: 0.47 oF -201, 35VDCV.
C714 thru C729	819/3CAAD00782	Deramic: 1000pf ±51, 50VDCW, temp sout 0±60ppm.
C730	B) 9/1C8AC00982	Tantalum: LuF :201, 35VDCV.
	B19/3CAA000789	Ceremic: 0.01 of +101, 50VDCW, temp
and C733		coef -101.
C734	\$19/3CAAD00782	Curanic: 1000pr -51, 50VDCW, temp couf 0 -60ppm.
c735	B19/3CAAD00782	Commic: 1000pF -St, 50VDCU, Long coef 0-80ppm.
C736	319/5CAAD01201	Serawic: 0.066 uF -102, 2570CF, ter
C7)) and C739	B19/5CAADOL237	Ceremic: 0.1 wF ±10%, 25VpCW, temp coef ±15%.
C740 and C741	B39/5CAAD00789	Geranic: 0.01 uF ±10%, 50VDCM, temp coef 0 ±30ppm.
	83 9/SCAAB00834	Ceramic: 47pF _5%, 50VBCM, tamp cod_ _00,5%.

STHEOL	SE PART NO.	DESCRIPTION
		Accessance pioets
CD401	B19/STXAD00320	Silicon, fast recovery (2 diodes in series); also to Toubibe 155220.
CPGS- 4M4 CDS05	#19/5TRAD00290	Silicon, fast recovery (2 diodes in cathoda common); sim to Tockibe 168184;
CD606	B19/>THARGO320	Silicon, fast recovery (2 diodes in series); sim to Tophiba 133226.
C0607	819/5TXAD00290	Silicon, fast recovery (2 diodes in cathode common); sim to Toshiba 155186.
CD408	#19/5TXA000290	Silicon, fast recovery (2 diode in cathode common, bim to Tomhiba 158184.
CD7UL	819/5TRAD00320	Silicon, fast recovery (2 diodes in series); sim to Toubiba 138226.
C9792	\$19/5TKAE00257	Zeneri 500mir, 6.5V, sim to Mitachi HE7A2.
CD703	\$19/5TXAE00199	Zener: 500mir, 1.8V, sim to Hicachi
CD703	\$19/5TRAD00290	Silicon, fast recovery (2 diodes in cathode common); sim to Toshiba 188184,
CB796 and CB797	#19/5TXAD00329	dilicom, fast recovery (2 diodes is series); sim to Tochiba 135226.
CD 708 and CD 709	319/9TXAD00290	Silicon, fust recovery (2 diodes in cathode common); sim to Toshibe 168166.
CD710	819/5T2AD00020	Diode, optoriscreate: red; sim to
QB911	\$19/5TXAD60290	#llicon, fast recovery (2 diodes in cathode common); sim to Toshiba 1851#A.
		HYBRED CERCULTS
HC6-01	\$19/6DH7900160	Squelch; sim to JRC (MFD160.
MC60Z	B19/60HF000165	Switch, sim to JAC DEFDISS.
HC40)	319/60KFD00164	Filter; wim to JRC BMFD164.
MC604	919/60MF000167	Filter; sim to MURATA DRUFD167.
нсьоз	\$19/60HF000168	Filter; aim to MURATA EMPDIGE,
MC606	\$19/40MFD00169	Filter; sim to MURATA DMFD109.
		INTEGRATED CIRCUITS
(C#01	\$19/30AAJQ0359	
10603	939/5DAAA00233	Linear, Audio Amplifier; min to MEC
[C603 and [C604	#19/30AAH00004	
10403	819/5BAAD00082	Linear, Positive Voltage Regulator; Sim to Tombiba TA78005AP.
10006	839/30AAR00021	12
10407	(\$4.9/30AAF00027	Linear, Dual OF AMP; aim to 455M Sypn.

TOBOL	GE PART NO.	BESCRIPTION
ICAO)	\$19/504a300359	Digital, Stiateral switch, ask to Matorole Mildook.
15010	B19/50AAL00/53	Linear, Weltage Detector, Sie to \$4 ts.7700.
10701	B19/50AAB00140	Licear, Timer; sin to Mitsubishi
16703	319/68LF300002	Hacrocomputer, M-684.F000007
10704	817/30AAJ00354	Digital, New Homeisverting 3-atota Buffer; sie to Notorola Milital.
10764	\$19/SDAAFOUSIS	Digatal, Men Lauerter Buffes/Briver;
16705	619/300A800209	Digital, Ouel Botype Plip Flop; sim to Micasbishi MAGI),
10706	@19/5000Y0002&	Digital, EEPRON; sim to Elect 22312AP.
		#3000#000#00# \$000#\$\$ ********************
1C\$702	B19/52JAB00029	15 Sockese, 40 pin.
IC\$706	#19/52JA#00030	IC Socheta. 18 pin.
1902 THEN 1901	819/SJTCA00137	Sontact, electrical.
Je06	#19/5JDAG00152	Commercer, Metering, 12 plas.
J607	h)9/SJTGA00137	Contact, electricat.
1101	819/5JW#\$00179	Connector, 22 pins.
J702	\$19.'SJM\$8001.79	Connector, 22 plus,
1703	#19/5JW#500173	Connector, 20 plan
3704	619/5JM8500138	Connector, 10 pins.
3705	619/5JW8500174	Connector, & pins.
J706 thru J708	819/SJTCA0013)	Commet, steatrical,
P601 chru 2605	#19/5JDAH00912	Seceptacts: 2 position, shorting, rated at 1 emp; aim to Hoods DIC-5257.
1607	#19/5J0AM00012	Recapetale: 2 position, shorting,
P/06	B19/3J0AH00617	Receptacle: 2 position, shorting,
P708	g , 20 00 00 00 00 00 00 00 00 00 00 00 00	resed at 1000; aim to Honda DSC-5212.
R60e R60e	#19/3REAG00575	Metal 11lm: 10K ohma 151, 2009/DCM, 1/8W,
R607	111/SEEACO0573	Pertal film: 4,7K obma 25%, 2009000, 1/64,
1004	819/SREACO05/5	Metal film: 10% ohme 25%, 2009DCH, 1/86.
2609	919/50EAG00581	Hetal film: 22K obms ±52, 2009DCH,

STUBOL	GE PART NO.	PESCALPTION
R630	919/SREAG00578	1/64.
R611	B19/SREAG00586	Hetal film: 100 ohme +5%, 200VBCF, 1/8s.
R612	919/SREAD00431	Metal film: 220K ohna ±5%, 2009DCW, 1/8W.
2613	B19/ SREACO0 581	Netal film: 22K ohma +SE, 200VDCW, 1/8W.
R614	B14/5REAG00376	Notel film: 10K ohms ±51, 200VDCW, 1/8W.
A615	B19/SREAG00583	Hetal film: 150 ohmm ±5%, 200VDCW, 1/8W.
Réié thre Béif	B19/SRDAC02223	Metal film: 2.2 obset ±5%, 200 BOW, 1/8M.
R620	919/588AG00590	Metal film: 0 ohse
R622	819/58.EAG00897	Metal film: 180K ohms ±51, 200YDCM. 1/6W.
1623	B19/5REAG00584	Hetal film: 8,2% ohms ±5%, 200YDCW, 1/8W.
H634	919/SREAG00572	Metal film: 1K ohms -5%, 200VBCW, 1/9W,
R627	83.9/5KEAC00897	Metal film: 80K ohma +5%, 200YBCF, 1/86.
R620	319/5REAC00575	Netal film: 2.2% ohms ±5%, 2009DCH, 1/0r.
R629	819/58ZAG00879	Netal film: 82K ohma ±5%, 200VDCV, 1/Pu.
R630	019/5REAC00631	Hetal film: 220K ohne ±5%, 2007DCM. 1/8W.
863 f	B) 9/ SREAG00576	Metsi file: 10K ohes ±5%, 200VDCM, 1/8M.
R632	B19/58EAC00573	Metal film: 4.7K ohme ±5K, 200V9CW, 1/8W.
R633	B19/5REAG00580	Netm1 film: 47 ohma ±5%, 200VDCW, 1/8W.
R634	B19/58RAG00623	Metal file: 2.7K obms ±5%, 200VDCW, 1/8W.
2635	319/SREAG00582	Hetal film: 1.8% ohma ±5%, 200V0Cw. 1/8W.
4636	B19/SREACO0682	Netel file: 18K ohms ±5%, 200VDCW, 1/8W.
8637	B19/5REAG00576	Metal film: IOK ohms +5%, 2004DCM, 1/8M.
R638	B19/5RBAG00626	Metai film: 27K ohmm ±5K, 200VDCW, 1/8W.
R639	83.9/ SREAC00372	Hetal file: 1K obse ±5%, 200VDCV. 1/8w.
R640	\$19/5REAG00579	Hetal film: 470 ohme ±5%, 2009DCV, 1/8V.
241	B19/SREAG00576	Hetel film: 10K obms ±5K, 200VDCW, 1/8W.
1642	319/5REACOO879	Heral film: 82K ohms ±5%, 2009DCW, 1/8W.

		DESCRIPTION
STHEOL	GE PART NO.	
R\$43 thru R\$45	B19/5REAG00574	Matel film: 10K ohen ±5%, 2009'SCW, 1/8W.
R644	B19/5REAG00572	Metal film: 1K ohom ±5%, 20099CW, 1/6W.
R647	819/SREAG00591	Metal film: 680 show ±5%, 200VECM, 1/8M.
R648	B19/5REAG00586	Matel film: 100 shop +5%, 200YBCW, 1/8W.
R649	319/SREAGO0591	Metal film: 680 ohme ±5%, 200VBCV, 1/8W.
1650	B19/SREACO0574	Hetal film: 1.5K ohmm ±5%, 2009DCV, 1/8W.
R651	319/5EEAG00596	Hetal film: 15K ohme ±51, 200VBCH, 1/8H,
R652	819/5RBAG00632	Metal filer 330K ohms ±5%, 200VDCM, 1/6W.
R653	919/SREAG00585	Netal film: 1.2% obse ±5%, 20079CV, 1/8V.
R654	B19/58,EAG00572	Metal film: 1K ohma ±5%, 200VDCW, 1/8V.
£635	B19/5REAG00576	Netal film: 10% ohes ±5%, 20VDCV, 1/8V.
R656	B19/5REAG00482	Netal fflm: 18K ohno +5K, 200VDCW, 1/8W.
R657	B19/SREAG00576	Nets f(ls: 10K ohms +5%, 2009ECW, 1/8W.
R658	B19/3REAC00379	Hets) film: 470 ohmms +5%, 2009DCN, 1/8M.
R659	819/SREAG00626	Note: film: 27K ohma ±5K, 200VDCV, 1/8V.
#640 ##6 #661	B19/SREAC00576	Metal film: 10% obpo ±5%, 200VDCW, i/9W.
R662	B19/SREAG00578	Hetal film: 47% ohms ±5%, 200996W, 1/8W.
R664	B19/3REAG00577	Metal film: 6.8K ohem +5%, 200VDCV, 1/8W.
R665	B19/5REAG00625	1/64.
R666	\$19/SRZAG00572	1/8w.
R667	B19/SREAG00589	1/84.
1648	B19/5REAG00574	1/8w.
R669	B19/SRZAC00384	Hetal film: 8.2K ohms ±5%, 2004DCW, 1/8M.
#671	B19/5REAG02737	1/84.
#672		1/64.
R673	B19/5REAA02533) Metal f(lm: 2.21% ohma ±1%, 250VBCN, 1/8W.

STOROL.	GE PART NO.		DESCRIPTION
1674	319/38EA000574	Metal film: 1/80.	10E ohim -5E, 200VBCH,
2675	919/58EAC00879	Metal film:	62% ohne <u>+</u> 52, 20070CV.
R676	B19/5REAG00573	Metal films 1/00.	4.7E atms ±51, 2009DCM,
R677 thru R680	B19/SREAG00576	Mecal file: 1/04.	10E obma <u>•</u> 5I, 200VDCM,
1661	\$19/56EA0007?2	Metal film: 1/W.	Di ohma _SI, 200VDCH,
R682	B19/5REAG00576	Matal film: 1/80,	10K ohna _551, 200VDCW.
2483	819/5REAG00587	Metal film: 1/80.	100K ołma <u>+</u> SX, 200∀DCW,
2664 and R665	319/SREAG00376	Metal film: 1/80.	10K ohma ±51, 200VBCH,
£701	319/5REAGO0586	Metal films 1/00.	100 ohma ±5%, 200∀9C⊌,
£702	B19/3REA000541	Mecal film: 1/8/.	ZZK ohmo ±5%, 200VDCW,
£703	939/SEE4G00387	Metal film: 1/80,	100E ohno ±51, 200VDCV.
1.704 and 1.705	B19/5REAG00572	Metal film: 1/Br.	LK olus ±5%, 200VDCH,
£704	B19/3REAG00379	Metal film: 1/8W.	670 okma <u>+</u> 51, 200V0CW,
£767	B19/3REAC00576	Metal fllm: 1/04.	10K ohma ±5%, 200VDCM,
E706	B19/5REAG00569	Metal film: 1/80.	3.3K obme ±51, 200VDCW,
R709	319/SEEAC00572	Metal film: 1/8r.	LK ohma _5%, 200VDCU,
M710	E19/3REAG00623	Metal film: 1/64.	2.7K ohmo ±5%, 200VDCM,
B711	919/38EAG00576	Metal film. 1/04.	10K ohno _51, 20VDCV,
R712 and R713	819/5REAC00541	Metal film: 1/80.	22K ohms <u>+</u> 5%, 700V9CW,
R7 L4	919/58EAG00879	Metal film: 1/8W.	52K ohms <u>+</u> 5%, 200VBCV,
#715	\$19/5REAG00576	Metal film:	19K obses ±51, 20042004,
£716	B19/SREAG00423	Notal filu: 1/8M.	8.7E ohmo ±5E, 200VDCM,
R717	819/5RRA000581	Metal film: 3/mr.	22K ohma _5X, 200VDCW,
R718	#19/SEEAG00576	Metal film: 1/80.	LOK ohms ±3%, 200VDCF,
#7L9	B39/SREA000585	Metal film: 1/8s.	1.2K ohmu ±51, 200978CM,
m720	B19/5REAG00584	Hotal film:	200 ohna <u>+</u> 5%, 200VDCH,

	OR PART ID.	DESCRIPTION .
8723 and 8722	\$19/58EAG00376	Marcal Silm: 10K obma #53, 20079504, 1700.
R723	\$19/38EAG00564	Metal film: 100 ohns ±5%, 20099CH, L/SM.
8724	819/3REA000378	Metal film: 47K ohma -52, 200VBCH, 1/86.
R725	B19/3884000399	Metal film: LSK ohme ±5%, 2009'0CW,
R726	\$19/38EAG09375	Recal file: 470 obse ±5%, 2009DCH, 1/8P,
R727	\$19/38EAG00576	Metal film: 10K ohms ±5%, 20095CF, 1/8F.
E728	\$19/5REAG00578	Metal film: 47K ohms _5X, 2009DCM, 1/Mr.
R729	B19/58EAC00546	Metal film: 100 ohms ±5%, 200990W, 1/8W.
8730 thru 8735	#19/5REAC0037a	Metal film: 10% ohmo ±52, 200VDCM, 1/8M.
E,736	\$19/5REAG00579	Metal film: 470 obma ±5%, 20099GW, 1/8w.
E737	919/5REA000578	Metal file: 47K ohms 55%, 20099CW, 1/8K.
R738 chru R740	B19/5REAGO0576	Maral film: 10K ohmo ±5%, 20099CH, 1/8W.
R741	819/SREAG00386	Metal Film: 100 ohna -5%, 200VDCW, 1/BW.
8742 and 8743	\$19/5EEA000576	Metal film: IOK ohms ±5%, 200VDCW, 1/8W.
R744	#19/SREAG00544	Hetal film: 8.7% ohms ±5%, 2009DOW, L/SW,
R743	#19/SHEAG0050?	Metal film: 100K elms ±5%, 200VbCH, L/SH,
E746	019/SREA000431	Hetal film: 220K ohma _5%, 200VDCF, 1/8F,
£747	#19/5REAGGG-16	Netal (ilm: 27K ohms ±51, 200VDCH, 1/8H.
R748 end R749	\$19/5HEAG00576	Metal film: 10K ohma ±5%, 200VBCW, 1/8W.
R750	319/3REA000616	Mertal film: 27K ohma ±5E, 200VBCW, 3/BW.
#751 mmd #752	#19/5REAG00576	Metal Film: 10K ohmo ±5%, 200VDCH, 1/8M.
R753	#19/5REACCOS#4	Metal film: \$.2% obma ±5%, 200VDCM, 1/8d.
E754	#19/5mmaG00623	Metal film: 270 ohna ±52, 2007DCW, 1/8m.
A753	\$19/5REAG00583	Netal film: 22% ohma 45%, 20099CH, 1/8H.
	\$19/58VABO0279	Warishle: 10K olms 230%, 0.1M.

STHEOL	GE PART NO.	DESCRIPTION
37602	B19/387AB00276	Vertable: 100K ohms +30%, 0.1W.
RV603 ==4 RV604	B19/5RVAB00279	Variable: 10K obma ≥30%, 0.1%.
X7603	B19/SRVAB00277	Variable: 5K ohma ±30K, 0.1W.
23701 thru 23703	\$3.9/SRZABOG133	Quad Resistor array; 10K chase ±5%, 1/8W.
TREO1 thru TREOS	B19/3TBAB00034	Silicoe, MPN; sim to MEC 280596 (DV3).
TE701 thru TR707	B19/97DAB00054	Silicon, MFM; sim to MEC 2SD596 (DF3).
TR706	B19/5TBAB00055	Silicon, PMP; sim to MEC 258624 (DV3).
TR709 thru TR713	B19/5TBAB00054	\$111com, XPW; 85m to MEC 250596 (DW3).
X701	B19/5XHAA00778	Quartz crystal: 600s,
1701-A and 1701-B	B19/5ZJB#00001	Crystal Socket.
	B19/CPQ~2223	INTERPACE BOARD
CB01 thru CB52	319/3CAAD00838	CAPACITORS ————————————————————————————————————
C853	B19/5CEAA01813	Blectrolytic: 100uF 4201, 25VDCW.
		JACKS
J 60 1	319/5JCAP00006	Connector; aim to SMX CSC05333-0301R.
J802 and J803	319/5Jun900175	Connector, 22 pins.
	B19/J10451835A	INTERCONNECTION CANLE
X6-01	B19/3XBAA00776	Crystel kit
20601 and 20602	B19/5200L00025	Flexible cable:
2C403	m19/5z0CL00024	Flexible cable:
		Flexible cable:
- 1		Fierible cable:
- · [B19/52001.00029	Flexible cable:
	B19/6JJFD00054	Co-egial cable:
ZC608 1	19/6JJP800063	Co-arial cable:

	A= 0.00	
STIGOL	GE PART 10.	DESCRIPTION
		Co-axial cable: Co-axial cable:
		Co-axial cable:
	319/6ZCP000145	
20613	319/62CF900144	
		————— Y(I \$CTZ,LAMBOUS ———
	B19/HP1H01167	Radio kay
	319/10/33/14964	Radio Hounting Plate
	B19/HFXP01744	Bardware Kit (Radio Hounting)
		Bottom Cover (Complete Assembly)
		Top Cover (Complete Assembly)
	19A704978P1	Reylock Assembly
	319/CMC-132-X	2 PMC Kit
	19821602163	Tx Puse, 20A-low power
	19821602166	Tx Puse, 30A-high power